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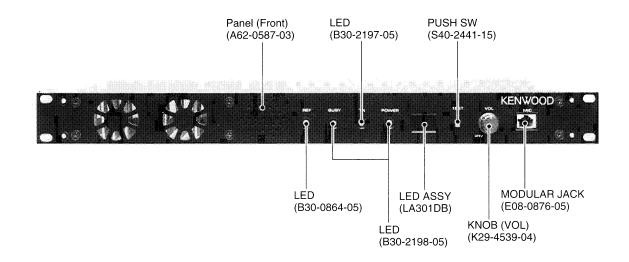
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TKR-830 SERVICE MANUAL

KENWOOD

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GENERAL

INTRODUCTION SCOPE OF THIS MANUAL

This manual is intended for use by experienced technicians familiar with similar types of commercial grade communications equipment. It contains all required service information for the equipment and is current as of the publication data. Changes which may occur after publication are covered by either Service Bulletins or Manual Revisions. These are issued as required.

ORDERING REPLACEMENT PARTS

When ordering replacement parts of equipment information, the full part identification number should be included. This applies to all parts : components, kits, or chassis. If the part number is not known, include the chassis or kit number of which it is a part, and a sufficient description of the required component for proper identification.

PERSONNEL SAFETY

The following precautions are recommended for personnel safety :

- DO NOT transmit until you verify that all RF connectors are secure and any open connectors are properly terminated.
- SHUT OFF and DO NOT operate this equipment near electrical blasting caps or in an explosive atmosphere.
- This equipment should be serviced by a qualified technician only.

SERVICE

This radio is designed for easy servicing. Refer to the schematic diagrams, printed circuit board views, and alignment procedures contained within.

NOTE

WE CANNOT guarantee oscillator stability when using channel element manufactured by companies other then KENWOOD or its authorized agents.

1. Overview

The TKR-830 is a 400-MHz-band trunking repeater system radio unit.

2. Main Features

- (1) Dimensions Width : 19 inches, Height : 1.75 inches, Depth : 12 inches
- (2) Aluminum die-cast uni-body frame.
- (3) Number of Channels : 1CH (This channel is selected by using either Dip switch or a Control line from 32 preset channels.)
- (4) This radio has PC tuning as below:
 - PC tuning RX : Squelch sensibility sensitivity, RA output level, RD output level
 - TX: RF output power, Maximum deviation, TA deviation, TD deviation, TD balance,

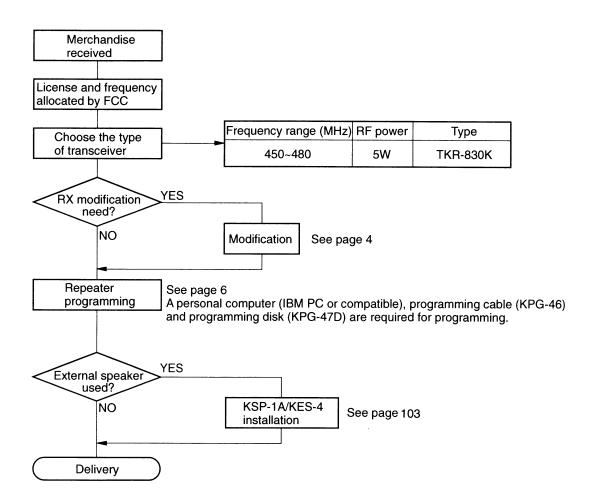
Manual tuning RX : Helical frequency bandwidth, MCF wave from, Quad coil

TX: MIC sensitivity

- (5) Software is stored in flash memory and can be rewritten without opening the cover.
- (6) The following can be monitored on a PC : RX : VCO lock voltage, RF input level / TX : VCO lock voltage, RF output power.

- (7) Multi-mode (Wide : 25kHz / Narrow : 12.5kHz)
- (8) RF output power is adjustable from between 2 to 5 watts. It is 100% duty cycle.
- (9) This radio has an interface port for external equipment such as a Repeater controller.
- (10) This radio has grant of Type Approval for ETS and CE, FCC, and IC certification.
- (11) The Front panel has LED indicators for Power, TX, Busy, and REF. It also has two 7-segment displays, a Mic jack, a speaker, a Local AF volume control, and a TX test switch.
- (12) The Rear panel has a BNC connector for the RX input and the TX output. There is also an External Reference input, a DC supply connector, a 25 pin D-sub connector, a Fuse box, and a 15 pin Test I/O connector.
- (13) This radio requires an external 13.8V DC supply.
- (14) You can increase the RF output power of this radio to 25W by changing the final output device.
- (15) This radio has an External Reference input (10MHz) .

SYSTEM SET-UP



3

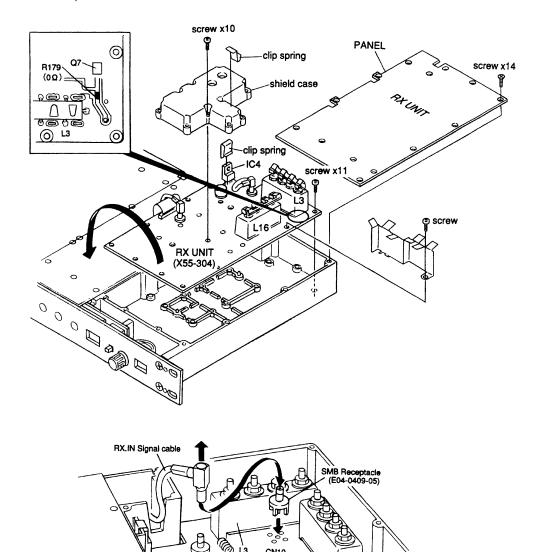
INSTALLATION

RX MODIFICATION

When you modify the receiver system by using a narrow duplexer between the RX circuit and RX antenna, you don't need to use the L3 filter.

- ① Remove the RX cover panel.
- 2 Remove the clip spring from IC4 and L16.
- ③ Remove the 12 screws from the RX unit and the 10 screws from the shield case.
- ④ Remove the jumper (R179) from the reverse side of the RX unit (X55-304).
- ⑤ Insert on SMB receptacle (E04-0409-05) at CN10. Solder the 5 leads in place.

- 6 Replace the screws on the RX unit and shield case, and the clip springs on IC4 and L16.
- $\ensuremath{\textcircled{O}}$ Move the RX. IN signal cable (from the back panel) from CN1 to CN10.
- (8) Attach a tacking generator signal to RX.IN, them use a spectrum analyzer to read the output at CN2 while adjusting L16 for the proper attenuation.
- 9 Next, adjust IF, squelch, and RSSI.
- 10 Replace the RX cover panel.



6

CN1

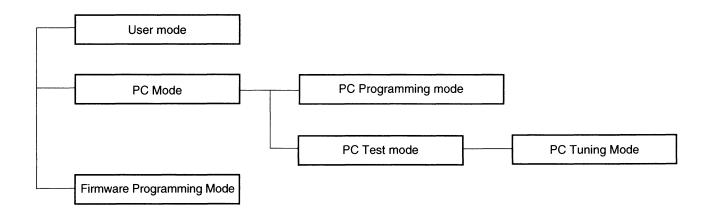
CN10

L16

 \bigcirc CN2 1

REALIGNMENT

1. Modes



Mode	Function			
User Mode	Use this mode for normal operation.			
PC Mode	Use this mode to make various settings by means of the FPU through the RS-232C port.			
PC Programming Mode	Use to read and write frequency data and other features to and from the Repeater.			
PC Test Mode	Use to check the Repeater using the PC.			
	This feature is included in the FPU.			
Firmware Programming Mode	Use when changing the Firmware program of the flash memory.			

2. How to Enter Each Mode

Mode	Operation
User Mode	Power ON.
PC Mode	Received commands from PC.
Firmware Programming Mode	Voltage is stored while you press the Test Switch. Press and hold the switch for 1 second so that all of the segments of the 7-segment display flash one time. Release the switch, and then press and hold it again within 1 second. "P.B" will appear after holding the switch for 1 second. Firmware Programming Mode is active.

REALIGNMENT

3. PC Mode

3-1. Preface

The TKR-830 repeater is programmed by using a personal computer, programming interface

The program software can be used with an IBM PC or compatible. Figure 1 shows the setup of an IBM PC for programming.

3-2. Connection procedure

- 1. Connect the TKR-830 to the personal computer with the interface cable.
- When the power ON, user mode can be entered immediately. When PC sends command the repeater enter PC mode, and "PC" is displayed on the 7-segment LED. When data transmitting from repeater, the TX LED is blinking.

When data receiving from repeater, the BUSY LED is blinking.

Notes:

- The data stored in the personal computer must match model type, when it is written into the flash memory.
- Change the TKR-830 to PC mode, then attach the interface cable.

3-3. KPG-46 description (PC programming interface cable : Option)

The KPG-46 is required to interface the TKR-830 to the computer. It has a circuit in its D-subconnector (25-pin) case that converts the RS-232C logic level to the TTL level. The KPG-46 connects the universal connector of the TKR-830 to the computers RS-232C serial port.

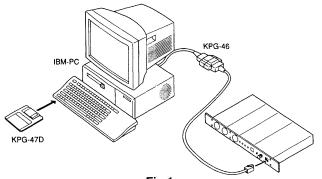
3-4. Programming software description

The KPG-47D programming disk is supplied in 3-1/2" disk format. The software on the disk allows a user to program TKR-830 repeaters via programming interface cable (KPG-46).

3-5. Programming with IBM PC

Data can be programmed into the flash memory in RS-232C format via the universal connector.

KPG-47D instruction manual parts No. : B62-1008-00



4. Firmware Programming Mode

4-1. Preface

Flash memory is mounted on the TKR-830. This allows the TKR-830 to be upgraded when new features are released in the feature. (For details on how to obtain the firmware, contact Customer Service.)

4-2. Connection procedure

Connect the TKR-830 to the personal computer (IBM PC or compatible) with the interface cable (KPG-46).(Connection is the same as in the PC Mode.)

Notes:

You can only program firmware from the 8-pin microphone connector on the front panel. Using the 25-pin logic interface on the rear panel will not work.

4-3. Programming

- 3. Start up the programming software (KPG-47D), select "firmware program" in the "Program" item, and press the Return key on the personal computer. This starts up the firmware programmer.
- 4. The top screen is displayed. Press any key to advance to the next screen.
- 5. Set the communications speed (normally, 38400 bps) and communications port in the Setup item.
- 6. Set the firmware to be updated by File select (=F1)
- 7. Voltage is stored while you press the Test Switch. Press and hold the switch for 1 second so that all of the segments of the 7-segment display flash one time. Release the switch, and then press and hold it again within 1 second. "P.B" will appear after holding the switch for 1 second. Main Programing Mode is active.
- 8. Check the connection between the TKR-830 and the personal computer, and make sure that the TKR-830 is in the Program Mode.
- 9. Press F10 on the personal computer. A window opens on the display to indicate progress of writing.
- 10. If writing ends successfully, the TX LED on the TKR-830 lights.
- 11. If you want to continue programming other TKR-830s, repeat steps 5 to 8.

Notes:

- To start the Firmware Programmer from KPG-47D, the Fpro path must be set up by KPG-47D Setup.
- This mode cannot entered if the Firmware Program mode is set to Disable in the Programming software (KPG-47D).

4-4. Function

If you press the [TEST] switch (front panel), the right hand decimal point on the 7-segment display will light. The writing speed is 19200 bps (low-speed mode). If you press the [TEST] switch again, both decimal points will light. The writing speed is 38400bps (high-speed mode).

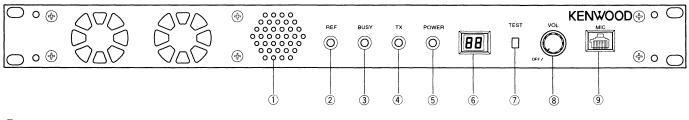
Notes:

Normally, write in the high-speed mode.

OPERATING FEATURES

CONTROLS AND FUNCTIONS

Front Panel



1) Speaker

② REF (reference) indicator

Lights red when using an external reference frequency. Lights green when using the internal reference frequency.

3 BUSY indicator

Lights green when the channel is in use.

④ TX (transmit) indicator Lights red while transmitting.

5 POWER indicator

Lights green when the power is turned ON.

6 Display

Tow, 7-segment digits display the channel number or status.

TKR-830

⑦ TEST switch

Press to transmit an unmodulated signal with on external microphone connected.

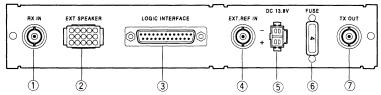
8 VOL (volume) control

Turn clockwise until a click sounds, to switch the power ON. Rotate to adjust the volume. Turn counterclockwise fully to switch the power OFF.

9 MIC (microphone) jack

Connect a microphone to this 8-pin modular jack.

Pear Panel



1 RX IN jack

Connect a RX antenna to this BNC receptacle.

② EXT.SPEAKER jack

Test input/output jack. Connect an external speaker to this jack.

③ LOGIC INTERFACE jack

Connect an external programming device to this DB-25 interface.

④ EXT, REF IN jack Connect an external reference frequent

Connect an external reference frequency (10MHz) to this BNC receptacle.

5 DC 13.8V jack

Connect a 13.8V DC power supply to this jack.

6 FUSE

Insert a 4A blade fuse into this fuse holder.

⑦ TX OUT jack

Connect a TX antenna to this BNC receptacle.

OPERATING FEATURES

Logic interface (25pin) (D-SUB Connector) Back Panel

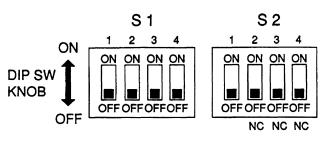
	23 14					
No.	Terminal name & Description					
1	NC					
2	RXD2 (PC serial data to radio)					
3	TXD2 (PC serial data from radio)					
4	NA (AUX1:IC9 Q5)					
5	NA (AUX2:IC9 Q6)					
6	NA (AUX3:IC9 Q7)					
7	DG (Digital Ground)					
8	TD (TX signal input)					
9	TA (TX audio input)					
10	RD (RX detector output)					
11	RA (RX audio output)					
12	RXG (RX Ground)					
13	SPM (Speaker Mute)					
14	NC					
15	MON (Monitor SW)					
16	PTT (Same test SW)					
17	SC (SQ Control output)					
18	NC (reserved for key)					
19	TXG (TX Ground)					
20	IN/EX SW (INT./EXT channel control select)					
21	EC1 (EXT, Cannel bit select 1)					
22	EC2 (EXT, Cannel bit select 2)					
23	EC3 (EXT, Cannel bit select 3)					
24	EC4 (EXT, Cannel bit select 4)					
25	EC5 (EXT, Cannel bit select 5)					

EXT. Speaker (15pin) (TEST I/O Connector) Back Panel

		<u> </u>				
Π	13 14 15	(10)	0	4	$\mathbf{\hat{0}}$	Π
	14	(1)	8	5	2	
		12	9	6	3	

No.	Terminal name & Description
1	+B (AUX)
2	+B (AUX)
3	NC
4	GND
5	GND
6	SPG (Speaker Ground)
7	RD
8	RSSI
9	SPI (Internal Speaker Input)
10	TXCV
11	RXCV
12	SPO (Output for external Speaker $4W/4\Omega$)
13	VC (Voltage Check only)
14	FWD
15	EXT REF

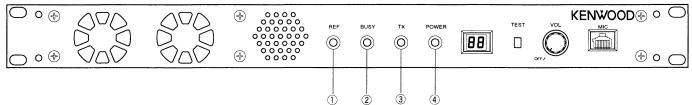
Internal channel setup switch (control unit) Method of setting up the channel using the DIP switches (S1 and S2)



0 : ON 1 : OFF	:					
	S1					S2
СН	1	2	3	4	1	2 3 4
1	1	1	1	1	1	NC
2	0	1	1	1	1	NC
3	1	0	1	1	1	NC
4	0	0	1	1	1	NC
5	1	1	0	1	1	NC
6	0	1	0	1	1	NC
7	1	0	0	1	1	NC
8	0	0	0	1	1	NC
9	1	1	1	0	 1	NC
10	0	1	1	0	 1	NC
11	1	0	1	0	1	NC
12	0	0	1	0	1	NC
13	1	1	0	0	1	NC
14	0	1	0	0	 1	NC
15	1	0	0	0	1	NC
16	0	0	0	0	1	NC
17	1	1	1	1	0	NC
18	0	1	1	1	0	NC
19	1	0	1	1	 0	NC
20	0	0	1	1	0	NC
21	1	1	0	1	 0	NC
22	0	1	0	1	0	NC
23	1	0	0	1	0	NC
24	0	0	0	1	0	NC
25	1	1	1	0	0	NC
26	0	1	1	0	 0	NC
27	1	0	1	0	0	NC
28	0	0	1	0	0	NC
29	1	1	0	0	 0	NC
30	0	1	0	0	0	NC
31	1	0	0	0	 0	NC
32	0	0	0	0	 0	NC

OPERATING FEATURES

Display



① REF (Reference) LED

The LED is green when using the internal reference frequency and red when using an external reference.

② BUSY LED

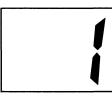
④ POWER LED

Lights green when receiving. Flashes when receiving data from the KPG-47D or when the receiving PLL is unlocked.

③TX LED

Lights red when transmitting. Flashes when transmitting data from the KPG-47D or when the transmit PLL is unlocked.

7-segment LED Displays





• Channel display (1~32): while operating normally in User Mode



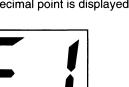
• "PC" display : while in PC Mode





- "PG" display : while in Firmware Programming Mode 2 decimal points are displayed : 38.400 bps
 - 1 decimal point is displayed : 19.200 bps







Lights green when the power is ON.



• "E2" display : when the channel data is not written.



• "E3" display : when PLL is unlocked When receive PLL is unlocked : BUSY LED flashes. When transmit PLL is unlocked : TX LED flashes. When the standard 19.2MHz is unlocked : the 7-segment display decimal point flashes.



• "E4" display : when you try to transmit on a channel that dose not have a frequency set up.

• "E1" display : when FPU data is not written.

CIRCUIT DESCRIPTION

Outline

The TKR-830 is a UHF-band relay radio unit for business radio applications. It is designed as a high-performance model with enhanced basic transmit/receive functions. The TKR-830 also has the PC tune and PC monitor functions and its circuits are configured to support future upgrading flexibly.

The TKR-830 has three PLL circuits in the transmitter unit and two PLL circuits in the receiver unit. All the PLL circuits are controlled with the same basic frequency, so the transmit and receive frequencies are very stable compared with the previous models. It uses a new circuit design to modulate the transmit reference PLL and the transmit main PLL at the same time during transmission. Therefore, it features flat modulation characteristics from a low-frequency range regardless of whether the external reference frequency or the internal TCXO is used.

(1) Internal/external reference circuit

The internal/external reference circuit switches between the internal +/-1.0ppm/20MHz TCXO X101 and the 10MHz external reference automatically. If there is no external reference input, the internal TCXO is used as the basic frequency for PLL circuits. When the external reference (10MHz/-10dBm or higher) is input to CN101, the external reference is used as the reference frequency for all PLL circuits. The circuits operate as follows.

When the external reference signal (10MHz) is input, its impedance is converted by an emitter follower (Q102). Then, harmonic components are generated by a double amplifier. Only the 20MHz component is taken by the MCF XF210 and sent to D101 and high-frequency amplifier Q205. The 20MHz signal amplified by Q205 is converted to a direct current voltage by the double-voltage detection circuit consisting of C265 and D205. The direct current voltage is compared with the reference voltage by comparator IC204. If the detected direct current voltage is higher than the reference voltage, the comparator output changes from "L" to "H".

The comparator output switches Q110, Q111, Q112, Q113,

Transmitter circuit

The transmitter unit (X56-303- A/3) consists of (1) internal/ external reference circuit, (2) transmit reference PLL circuit, (3) receive reference PLL circuit, (4) transmit main PLL circuit, (5) driver circuit, (6) modulation level adjustment circuit, and (7) other circuits.

and Q114 switching transistors. Q110 turns "OFF" and Q114 turns "ON". Switching diode D101 conducts (since Q110 is "OFF", D103 does not conduct). The 20MHz reference signal generated from the external reference signal is input to IC201 and IC202 and the external reference signal is used as the reference frequency.

When the comparator output turns Q206 "ON", the comparator reference voltage decreases by a certain level, and hysteresis characteristics are obtained. Even if the external reference level changes slightly, the comparator output does not change. If there is no external reference input, the double voltage detection circuit C265 and D205 does not output any signal, the comparator output is "L". Therefore, Q114 turns "OFF" and Q110 turns "ON". Power is supplied to the internal TCXO and D103, the internal TCXO 20MHz reference signal is input to IC201 and IC202, and the internal TCXO is used as the reference frequency. The TCXO frequency stability may be affected by the output load impedance. The TCXO output load impedance and its frequency.

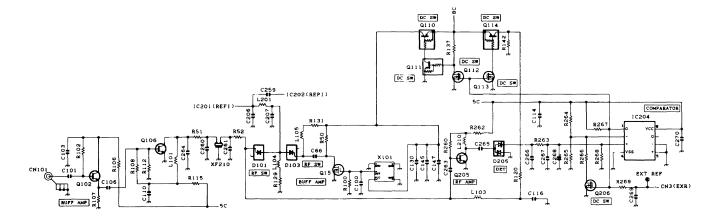


Fig.1 Internal/external reference circuit

CIRCUIT DESCRIPTION

TKR-830

(2) Transmit reference PLL circuit

The transmit reference PLL circuit generates the reference frequency signal (19.2MHz) for the transmit main PLL and consists of IC201, X201, Q201, and Q202.

The VCO has a no-adjustment type crystal oscillator circuit (based on a Colpitts circuit) consisting of Q201 and X201, varicap D203 for modulation, and varicap D201, D202 for changing the oscillator frequency by direct current voltage.

The signal generated by the VCO is fed to buffer amplifier Q202. The signal then goes to a "pi" type LPF to remove unwanted harmonic components. The resulting signal goes to the fractional N type single-chip PLL IC (IC201), and the phase of the divided frequency (200kHz) is compared with that of the reference frequency. The phase difference signal enters the internal charge pump, is converted to an analog signal (0 to 5 V) and output from the PHA pin. Then, the signal is converted to a direct current voltage by a laglead type loop filter. The capacity of D201 and D204 is varied by the direct current voltage to keep the VCO oscillator frequency 19.2MHz.

The stabilized 19.2MHz oscillator signal is taken from the LPF output, output to IC101 Xin pin, and used as the reference frequency signal for the transmit main PLL.

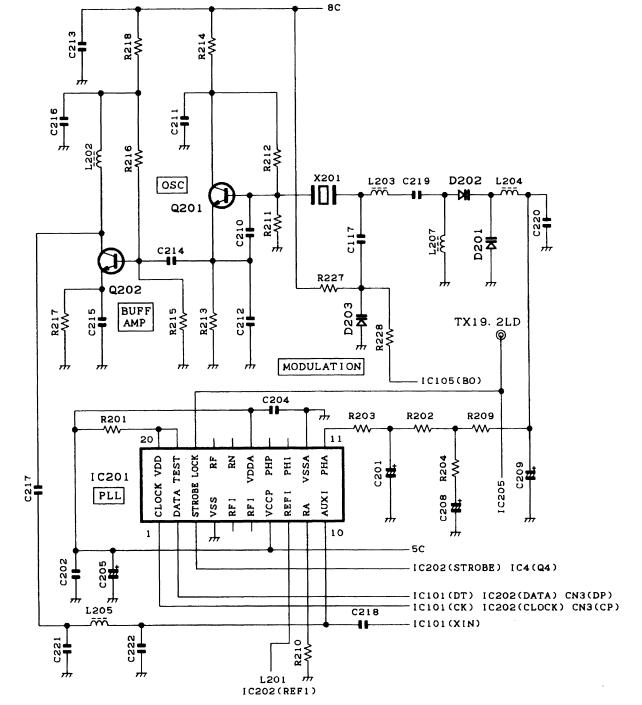


Fig.2 Transmit reference PLL circuit

CIRCUIT DESCRIPTION

(3) Receive reference PLL circuit

The receive reference PLL circuit produces the reference frequency signal (19.2MHz) for the receive PLL (first and second local oscillator), and consists of IC202, X202, Q204, and Q241.

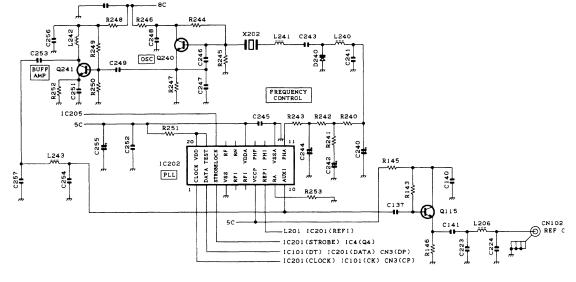
The VCO contains a no-adjustment type crystal oscillator circuit (based on a Colpitts circuit) consisting of Q240 and X202 and varicap D240 for changing the oscillator frequency by direct current voltage.

The signal generated by the VCO is fed to the buffer amplifier Q241. The signal then goes to a "pi" type LPF to remove unwanted harmonic components. The resulting signal goes to the fractional N type single-chip PLL IC (IC202), and the phase of the divided frequency (200kHz) is compared with that of the reference frequency. The phase difference signal enters the internal charge pump, is converted to an analog signal (0 to 5 V) and output from the PHA pin. Then, the signal is

converted to a direct current voltage by a laglead type loop filter. The capacity of D240 is varied by the direct current voltage to keep the VCO oscillator frequency 19.2MHz.

The stabilized 19.2MHz oscillator signal is taken from the LPF output, output to IC101 Xin pin, and used as the reference frequency signal for the receive PLL (first and second local oscillator). The impedance is converted by emitter follower amplifier Q115. The resulting signal passes through the "pi" type LPF and goes to the receive PLL reference output pin CN102.

The unlock signals for the transmit reference PLL circuit and receive reference PLL circuit are output from pin 18 (LOCK) of IC201 and IC202. The two unlock signals are ANDed, and the reference PLL unlock signal (LDS) is sent from CN3 to the control unit.



voltage.

Fig.3 Receive reference PLL circuit

(4) Transmit main PLL circuit

The transmit main PLL circuit generates the transmit frequency signal. This circuit consists of a clap type oscillator VCO consisting of Q1 and Q2 and single-chip PLL IC (IC101). When transmitting 450.0000 MHz to 464.995 MHz, the Q2 VCO oscillates and Q1 stops. The switching operation is performed by controlling switching transistors Q3, Q4, and Q5 using the output Q1from shift register IC4.

The signal generated by Q1 or Q2 is fed to buffer amplifier Q6. Q6 provides isolation, and the signal goes to the high frequency amplifiers Q9 and Q107. Q107 amplifies the signal to the level required for the internal prescaler in IC101. Unwanted harmonic waves are removed by the "pi" type two-step LPF, and the resulting signal is input to IC101 Fin pin. IC101 divides

the VCO oscillator signal input to Fin and the transmit PLL reference signal (19.2MHz) input to Xin by the divide ratio, and the phase is compared with the 12.5kHz comparison frequency. The phase difference signal detected by phase comparison enters the internal charge pump, is converted to an analog signal (0 to 5 V) and output from the Do pin. The analog signal output from the Do pin is converted to a direct current signal by the laglead type loop filter. The direct current signal is applied to varicap D1, D3, D2, D4 to lock the VCO oscillator frequency with the desired oscillator frequency. The direct current signal passes through the IC109 operational amplifier and buffer amplifier, and is output from CN3 as the voltage signal (CVT) for monitoring the transmit main PLL lock

CIRCUIT DESCRIPTION

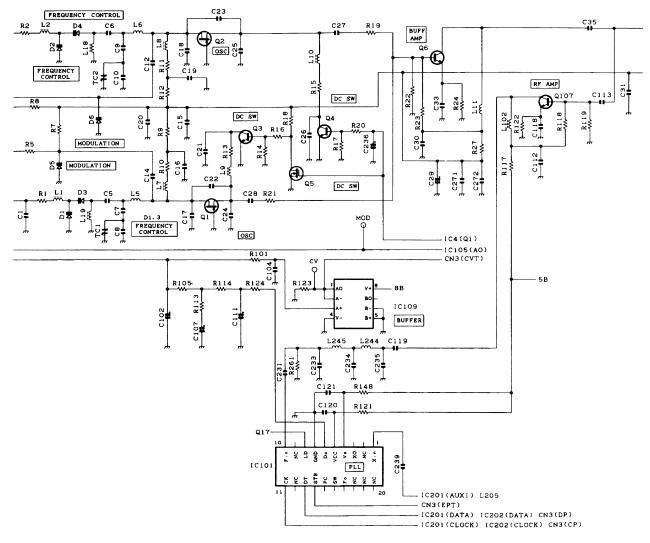


Fig.4 Transmit main PLL circuit

(5) Driver circuit

The driver circuit amplifies the transmit frequency signal generated by the transmit main PLL circuit to the level required for input to the final unit (X56-303 B/3). The driver circuit consists of high frequency amplifier Q9, high frequency switch D7, D10, high frequency amplifier Q13, high frequency amplifier Q14, direct current amplifier Q17, and switching elements Q18, Q203, Q8, Q16, Q10, Q12, and Q11.

When the transmit main PLL is locked, the IC101 LD pin goes "H", and the collector of Q17 goes "L". The collector of Q18 goes "H", the collector of Q203 goes "L", and the collector of Q8 goes "H". The logic is the opposite to the logic when the transmit main PLL is unlocked.

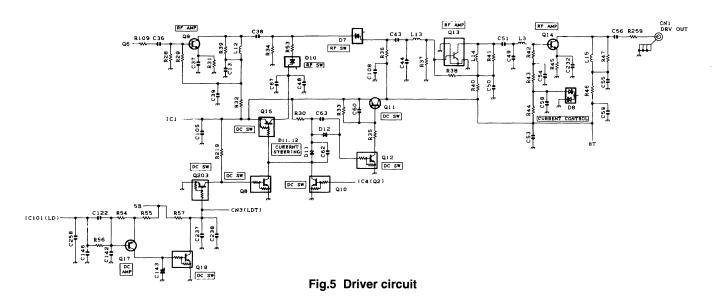
The transmit main PLL lock signal is output to CN3 as a signal "LDT" from the collector of Q18. This signal is used for the CPU in the control unit to monitor the lock state of the transmit main PLL. (See the control unit circuit description.)

When the collector of Q8 goes "L", Q16 turns "ON" and Q11 turns "OFF" regardless of whether the base voltage of Q10 is "H" or "L". Therefore, the power 8T for the drive is not provided. When the circuit is unlocked, it is protected to inhibit transmission.

The transmitter operation is controlled according to the data sent from the CPU in the control unit to shift register IC4. When IC4 pin 5 Q2 is "L" and the collector of Q8 is "H" (the transmit main PLL is locked), Q16 and D10 turn "OFF" and Q12 and Q11 turn "ON", 8T is supplied to the drive stage, D7 turns "ON", and the transmit signal is sent to Q13.

The transmit signal level input to Q13 is about 0 dBm. Q13 amplifies it by about 10 dB, and Q14 also amplifies it by about 10 dB. 20 dBm (about 100 mW) is output from drive output connector CN1.

CIRCUIT DESCRIPTION



(6) Modulation level adjustment circuit

The modulation level adjustment circuit adjusts the modulation signal level and provides specified modulation. It consists of IC105, IC3, IC100, and IC203.

IC3 is an electronic volume IC. The signalling frequency change adjustment, signalling modulation balance adjustment (transmit reference PLL and transmit main PLL are modulated at the same time to provide flat modulation characteristics), maximum sound frequency change, and the reference voltage setting for transmission power adjustment can be performed for each transmit frequency and for each channel using the FPU (KPG-47D) and a personal computer.

IC105 is a modulation signal summing amplifier (A/2) (sums the sound signal and the signalling signal whose balance is adjusted and modulates the transmit main PLL) and a signalling signal amplitude fine-adjustment amplifier (B/2).

IC203 is a DC amplifier that fine-adjusts the transmission power reference voltage generated by IC3. The "PC" signal is output to the final unit from connector CN.

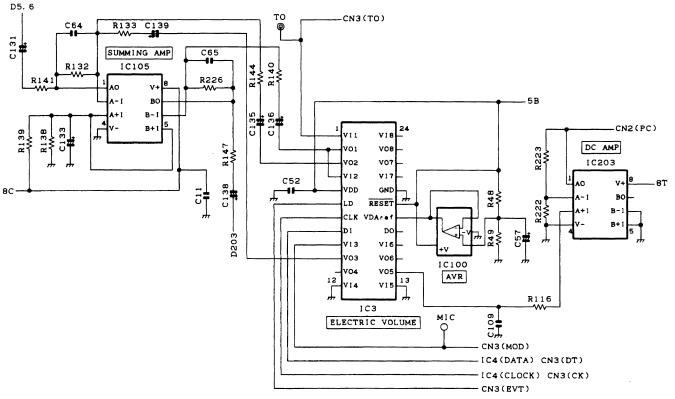


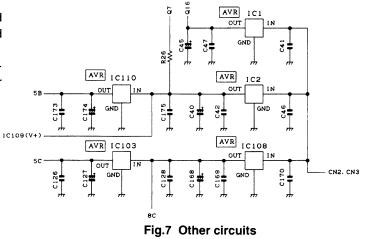
Fig.6 Modulation level adjustment circuit

CIRCUIT DESCRIPTION

(7) Other circuits

IC106 is an EEPROM. The transmit adjustment data adjusted for each unit is written into the EEPROM. If the unit is installed in another set, it is not necessary to adjust it again.

IC1, IC2, IC103, IC108, and IC110 are three-pin constantvoltage power supply ICs. Each circuit contains its own power IC to maintain isolation between circuits.

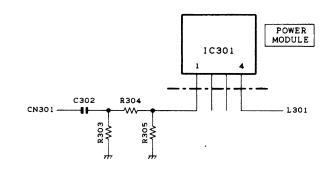


Filanl Unit

The final unit (X56-303 B/3) amplifies the transmission power to a specified level. This unit consists of (1) transmission power amplifier, (2) harmonic wave elimination circuit, (3) progressive wave power/reflected wave power detection circuit, (4) APC circuit, (5) abnormal temp. Detection circuit, and (6) common mode unwanted radiation prevention circuit.

(1) Transmission power amplifier

The transmission power amplifier IC301 uses a power module S-AU50M for portable transceivers to improve its efficiency. Driver output CN1 of the transmit unit is fed to CN301 of the final unit through a coaxial cable, and enters pin 1 of transmission power amplifier IC301 through a 5dB attenuator. The transmission power amplifier IC301 amplifies the power to the level corresponding to the voltage at the power control pin (pin 2) and outputs it from the output pin (pin 4).





(2) Harmonic wave elimination circuit

The harmonic wave elimination circuit is a three-stage "pi" type Chebyshev type LPF consisting of L301, L302, L303, C307, C312, C315, and C316. This circuit removes harmonic wave components from the transmission power amplified by the transmission power amplifier and sends the resulting signal to the progressive wave power/reflective wave power detection circuit.

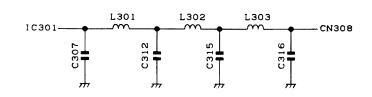


Fig.9 Harmonic wave elimination circuit

CIRCUIT DESCRIPTION

(3) Progressive wave power/reflected wave power detection circuit

The progressive wave power/reflective wave power detection circuit consists of a 1/4 λ CM coupling type detection circuit formed by a strip line and a direct current amplifier IC303. The CM coupling detection circuit detects a negative voltage corresponding to a square root of the power values of the progressive wave and reflective wave. (D306 detects progressive wave and D308 detects reflective wave.) The progressive wave voltage FWD is sent to the APC circuit and control unit in the next stage, and reflective wave voltage REV is sent to the control unit through CN302. Thirmistor TH301 corrects the thermal characteristics of the detection diode and keeps the APC function stable within the operation temperature range. Transmission power passes through the strip line and is output from CN308.

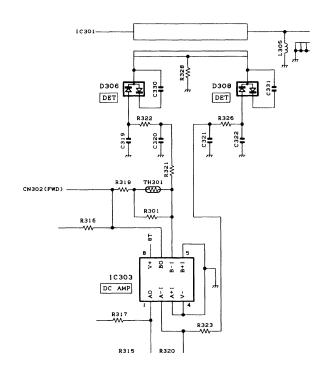


Fig.10 Progressive wave power/reflected wave power detection circuit

(4) APC circuit

The APC circuit consists of differential amplifier IC302 and direct current amplifier Q301. IC302 places the transmission power setting voltage PC and progressive wave detection voltage FWD from the transmit unit to + input and - input, and outputs voltage Vd amplified according to the difference between the voltages. (If PC > FWD, Vd increases, and if PC < FWD, Vd decreases.) The voltage Vd is applied to direct current amplifier Q301 in the next stage. The voltage is converted to output voltage Vg to control the power control pin (pin 2) of the transmission power amplifier IC301. At the power control pin, the transmission power increases when the voltage Vg increases, and decreases when Vg decreases. A loop is formed between transmission power, FWD, Vd, and Vg, and

the transmission power converges into the point where the transmission power setting voltage PC and progressive wave detection voltage FWD are equal. The transmission power can be controlled according to the transmission power setting voltage PC. The +B voltage is applied to the power pin (pin 3) of the transmission power amplifier IC301 even when the final unit is not in transmit mode. When the voltage Vg is applied to the power control pin, the current flows to the power pin of IC301. In this case, there may be some problems, such as no isolation of the input and output of IC301. To prevent this problem, the switching transistors Q304 and Q305 are switched by transmission power 8T input through CN302 and the Vd voltage is grounded when transmission is not made.

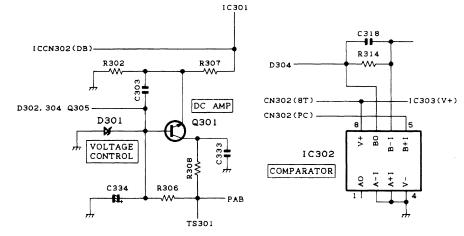


Fig.11 APC circuit

CIRCUIT DESCRIPTION

(5) Abnormal temp. detection circuit

The abnormal temp. Detection circuit consists of thermal switch TS301 and digital transistor Q302. This circuit reduces the transmission power amplifier function and prevents temp. Rise to protect the circuits when the final unit temp. Rises excessively and the circuits cannot be operated safely. This circuit rarely activate during normal use. When the thermal switch detects the operating temp., the internal switch of the thermal switch conducts. When the voltage is applied to the base of Q302, digital transistor Q302 turns "ON". The collector of digital transistor Q302 grounds the differential amplifier output voltage Vd of the APC circuit to reduce transmission power.

(6) Common mode unwanted radiation prevention circuit Common mode unwanted radiation prevention circuit. The TKR-830 has a filter L304 in the power line in the final unit to reduce unwanted radiation in common mode from the power cable.

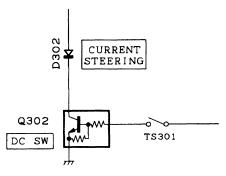


Fig.12 Abnormal temp. detection circuit

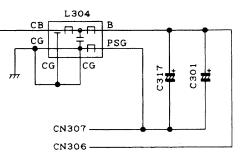


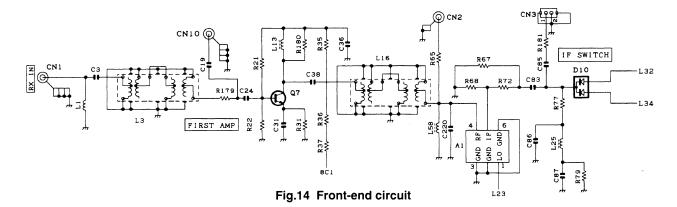
Fig.13 Common mode unwanted radiation prevention circuit

Receiver Circuit

The receiver unit (X55-304) consists of (1) front-end circuit, (2) narrow IF circuit, (3) wide IF circuit, (4) first oscillator PLL circuit, (5) second oscillator PLL circuit, (6) base band circuit, and (7) other circuits.

(1) Front-end circuit

The front-end circuit consists of helical BPF L3, high frequency amplifier Q7, helical BPF L16, mixer DBM A1, and IF switching circuit D10. The receive signal coming through CN1 goes to helical BFP L3. Unwanted signal components are damped and only the necessary band (about 5MHz) signal is sent to the high frequency amplifier Q7. The operating point of Q7 is set to maximize the gain and minimize distortion. The helical BPF L16 removes the unwanted out-of-band high frequency components produced by high frequency amplifier Q7 and unwanted components leaked from the previous circuits, and sends only the necessary signal to mixer DBM A1. The mixer DBM A1 mixes the first local oscillator signal generated by the first local oscillator PLL with the receive signal coming from the helical BPF L16 to produce a first IF signal (73.05MHz). The first IF signal is switched to the narrow or wide IF circuit by the switching diode D10.



CIRCUIT DESCRIPTION

(2) Narrow IF circuit

The narrow IF circuit consists of two-pole MCF XF2, four-pole MCF XF4, IF amplifier Q25, IF amplifier Q32, FM detection IC IC7, ceramic filter CF1, and CF3. The unwanted components of the first IF signal connected to the narrow IF circuit by the switching diode D10 are removed by the overtone type twopole MCF XF2. The resulting signal is amplified by IF amplifier Q25. Unwanted signal components are further eliminated by the overtone type four-pole MCF XF4 to maintain three-signal characteristics. The first IF signal output from XF4 is amplified by IF amplifier Q32 and input to pin 24 of FM detection IC IC7. The FM detection IC mixes the second PLL local oscillator signal with the first IF signal to generate a second IF signal (450kHz). Unwanted components of the second IF signal are removed by ceramic filter CF1. The resulting signal is amplified by the IF amplifier in IC7. Unwanted components of the amplified signal are further removed by ceramic filter CF3 to improve the two-signal characteristics of the IF stage. The signal then enters the quadrature detection circuit. The signal

with a phase shifted 90 degrees by phase shift coil L53 is compared with the original signal waveform to perform FM detection and generate the base band signal. The base band signal is output from pin 15 of IC7 and enters the low frequency amplifier IC11 (A/2 and B/2). The signal amplified by IC11 (A/ 2) goes to the Y0 input of multiplexer IC9 and the V2 input of electronic volume IC9. The level of the signal that enters V2 of the electronic volume IC is adjusted, the signal passes through the hysteresis circuit AF switch Q34. The signal goes to IC7 noise filter input (pin 17), and high frequency components are removed by a HPF. The signal is noise-detected and compared, and the noise squelch signal (N-DET) is fed to DC switch Q36. The voltage signal (RSSI) corresponding to the IF signal strength from the two second IF amplifiers in IC7 are compared with the reference voltage set by electronic volume V4 by the internal RSSI comparator, and the RSSI squelch signal (C-DET) is output from pin 20 of IC7. C-DET enters DC switch Q37 and is ANDed with N-DET by DC switch Q38. A squelch signal (SC) is output from connector CN6.

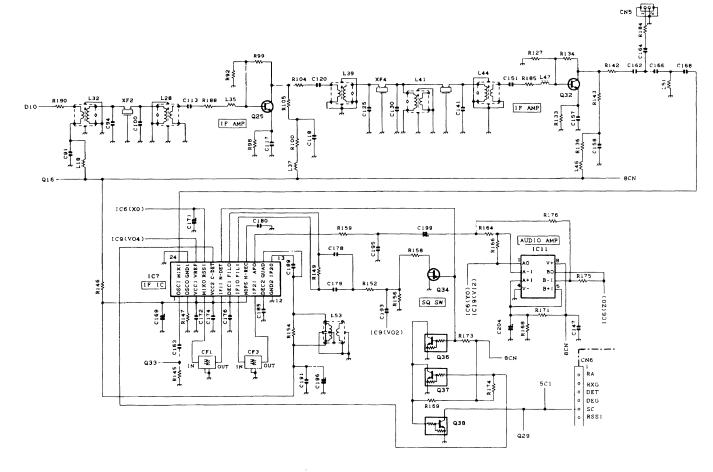


Fig.15 Narrow IF circuit

CIRCUIT DESCRIPTION

(3) Wide IF circuit

The wide IF circuit consists of two-pole MCF XF1, four-pole MCF XF3, IF amplifier Q24, IF amplifier Q31, FM detection IC IC8, ceramic filter CF2 and CF4. The unwanted components of the first IF signal connected to the wide IF circuit by the switching diode D10 are removed by the overtone type twopole MCF XF1. The resulting signal is amplified by IF amplifier Q24. Unwanted signal components are further eliminated by the overtone type four-pole MCF XF3 to maintain three-signal characteristics. The first IF signal output from XF3 is amplified by IF amplifier Q31 and input to pin 24 of FM detection IC IC8. The FM detection IC mixes the second PLL local oscillator signal with the first IF signal to generate a second IF signal (450kHz). Unwanted components of the second IF signal are removed by ceramic filter CF2. The resulting signal is amplified by the IF amplifier in IC8. Unwanted components of the amplified signal are further removed by ceramic filter CF4 to improve the two-signal characteristics of the IF stage. The signal then enters the quadruture detection circuit. The signal with a phase shifted 90 degrees by phase shift coil L52 is compared with the original signal waveform to perform FM detection is performed and generate the base band signal. The base band signal is output from pin 15 of IC8 and enters the low frequency amplifier IC12 (A/2 and B/2). The signal amplified by IC12 (A/2) goes to the Y1 input of multiplexer IC and the V1 input of electronic volume IC9. The level of the signal that enters V1 of the electronic volume IC is adjusted, and the signal passes through the AF switch Q35. The signal goes to IC8 noise filter input (pin 17), and high frequency components are removed by a HPF consisting of external CRs. The signal is noise-detected and compared, and the noise squelch signal (N-DET) is fed to DC switch Q36. The voltage signal (RSSI) corresponding to the IF signal strength from the two second IF amplifiers in IC8 are compared with the reference voltage set by electronic volume V3 by the internal RSSI comparator, and the RSSI squelch signal (C-DET) is output from pin 20 of IC8. C-DET enters DC switch Q37 and is ANDed with N-DET by DC switch Q38. A squelch signal (SC) is output from connector CN6. The C-DET signal and N-DET signal are the same for both the wide and narrow IF circuits. (The wide and narrow IF circuits do not operate at the same time.)

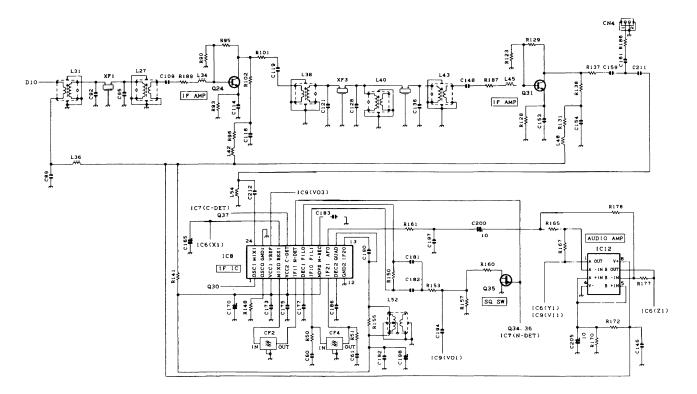


Fig.16 Wide IF circuit

CIRCUIT DESCRIPTION

(4) First oscillator PLL circuit

The first local oscillator PLL circuit consists of clap type VCO consisting of Q8 and Q9, fractional N type single-chip PLL IC IC1, buffer amplifier Q14, and high frequency amplifier Q3, Q1, Q5, and Q6. The first local oscillator is a lower heterodyne local oscillator with a receive frequency of 450.0000 to 480.0000 MHz. The VCO oscillator frequency is 376.95 to 406.95 MHz. One of the two VCOs, Q8, covers the range of 376.95 to 391.945 MHz, and Q9 covers the range of 391.95 to 406.95 MHz. One of the VCOs is selected by switching switching-transistors Q10, Q12, and Q13 by shift register IC3 output Q3.) The signal generated by Q8 or Q9 is fed to buffer amplifier Q14. The signal is isolated and is sent to high frequency amplifiers Q3 and Q23. The signal input to Q23 is amplified to the level required for IC1 prescaler input, harmonic

wave components are removed by a "pi" type two-step LPF, and the resulting signal goes to pin 5 of IC1. PLL IC IC1 divides the CN7 receive PLL reference signal 19.2MHz coming from the transmitter unit and the signal generated by the VCO and compares phases with a comparison frequency of 12.5 kHz. The detected phase difference signal is fed to the internal charge pump, converted to an analog signal (0 to 5 V), and output from the PHP pin. The analog signal output from the PHP pin is converted to a direct current voltage by a lag-lead type loop filter. The capacity of varicaps D2, D3, and D4 is varied by this direct current voltage to lock the VCO to the desired oscillator frequency. The signal input to Q3 is amplified to about 20 dBm by high frequency amplifier Q3, Q1, Q5, and fed to mixer DBM A1 as a first local oscillator signal.

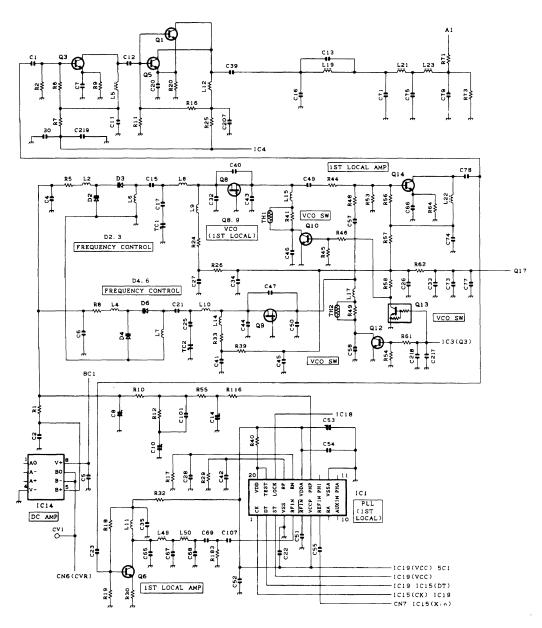


Fig.17 First oscillator PLL circuit

CIRCUIT DESCRIPTION

(5) Second oscillator PLL circuit

The second local oscillator PLL circuit consists of PLL IC IC15, crystal oscillator X1, oscillator FET Q21, buffer amplifier Q23, high frequency amplifier Q15, Q30, Q33, and emitter follower Q27. The VCO consists of no-adjustment type crystal oscillator circuit (Q21 and X1) (based on a Colpitts oscillator circuit) and varicap D9. The signal generated by the VCO is fed to buffer amplifier Q23. The signal is isolated by Q23 and fed to high frequency amplifier Q15 and emitter follower amplifier Q27. High frequency amplifier Q15 and emitter follower amplifier Q27. High frequency amplifier Q15 and emitter follower amplifier Q27. High frequency amplifier Q15 and emitter follower amplifier Q27. High frequency amplifier Q15 amplifies the signal to the level required for IC15 prescaler input, and outputs it to IC15 Fin (pin 20). IC15 divides the CN7 receive PLL reference signal 19.2MHz coming from the transmitter unit and the VCO-generated signal input to Fin and compares phases with a comparison frequency of 200 kHz. The detected phase

difference signal is converted to an analog signal (0 to 5 V) by the internal charge pump. The signal is output from the IC15 Do pin, and converted to a direct current voltage by a laglead type loop filter. The VCO varicap D9 is controlled by the direct current voltage to lock stably with the desired frequency 72.6 MHz. The signal input to emitter follower amplifier Q27 is isolated, and moved from the Q27 emitter to high frequency amplifier Q33, Q30. The signal is amplified to the level required for FM detection IC OSCI input, and output to the OSCI pin of each FM detection IC. The unlock detection signals from the two PLL circuits in the receiver unit are ANDed by IC18, and the resulting signal is sent to the CPU in the control unit from CN6 as receive PLL lock signal LDR.

TKR-830

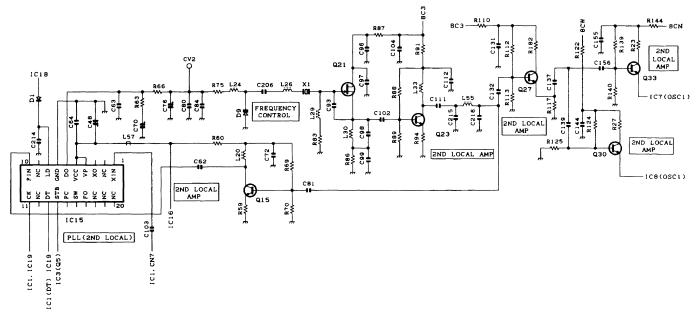


Fig.18 Second oscillator PLL circuit

(6) Base band circuit

The base band signal circuit consists of HPF Q26 and Q28, switching diode D11, and digital transistor Q29. The level of the base band signal detected by the narrow and wide FM detection circuits is adjusted by the amplifier (B/2) of IC11, IC12. The active detection output is selected by Z0 and Z1 of multiplexer IC6. The amplified base band signal is output to

CN6 from IC6 "Z" pin as the DET signal. The level is adjusted by the amplifier (A/2) of IC11, IC12 and the active detection output is selected by Y0 and Y1 of multiplexer IC6. The subaudio band components of the signal output from the "Y" pin are cut by the HPF of Q26 and Q28, the signal is switched by the squelch signal by D11 and Q29, and output from CN6 as the RA signal.

CIRCUIT DESCRIPTION

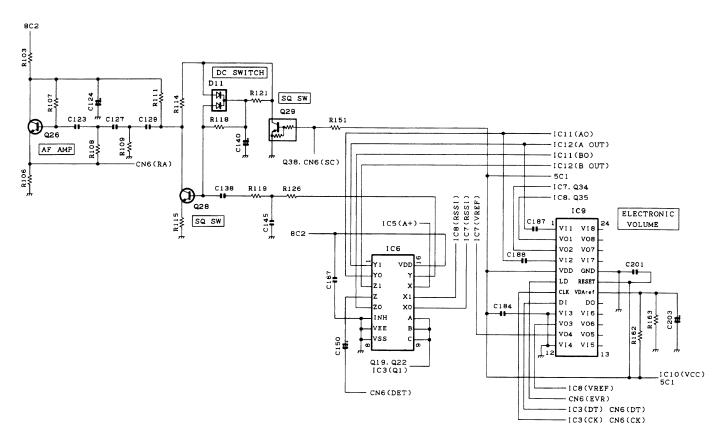


Fig.19 Base band circuit

(7) Other circuits

The receiver circuit contains an EEPROM (IC10) like the transmitter circuit. Adjustment data for each unit is written into the EEPROM when adjustment ends. Therefore, even if the unit is moved to another set, no adjustment is required. IC2, IC4, IC13, IC16, and IC17 form a three-pin constant voltage power supply IC. Each circuit contains a power supply to isolate circuits. Q17 is a ripple filter for the power supplied to the first local oscillator PLL VCO. The RSSI signal for the active wide or narrow FM detection IC is selected by "X1, X0, X" of the

multiplexer IC6. The signal is output from connector CN6 through the operational amplifier buffer amplifier IC (A/2). IC3 is a shift register. IC3 switches between the two IF circuit power supplies and between the second local oscillator PLL strobe data and the first local oscillator PLL VCO according to the data from the CPU. Q16, Q18, Q19, Q20, and Q22 compose a switching transistor. It controls power supplies 8CN and 8CW for the two IF circuits.

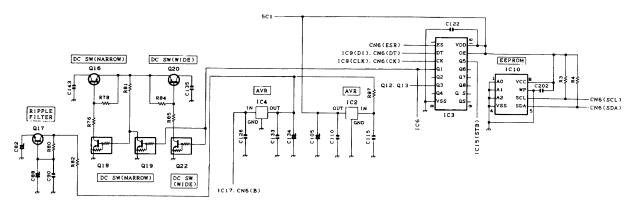


Fig.20 Other circuits

CIRCUIT DESCRIPTION

TKR-830

Control Circuit

The control unit (X53-381) consists of (1) CPU, (2) receive audio filter circuit, (3) LSD filter circuit, (4) AF PA circuit, (5) microphone amplifier circuit, (6) noise squelch circuit, (7) display circuit, (8) channel setting circuit, (9) RS-232C circuit, (10) external equipment connection circuit, and (11) other circuits.

(1) CPU

The CPU (IC10) is a single-chip microcomputer containing a 1Mbit flash ROM (128k x 8). The firmware can be modified easily. The CPU controls the transmitter unit, the receiver unit,

the control unit, and the display circuit and transfers data to or from external devices.

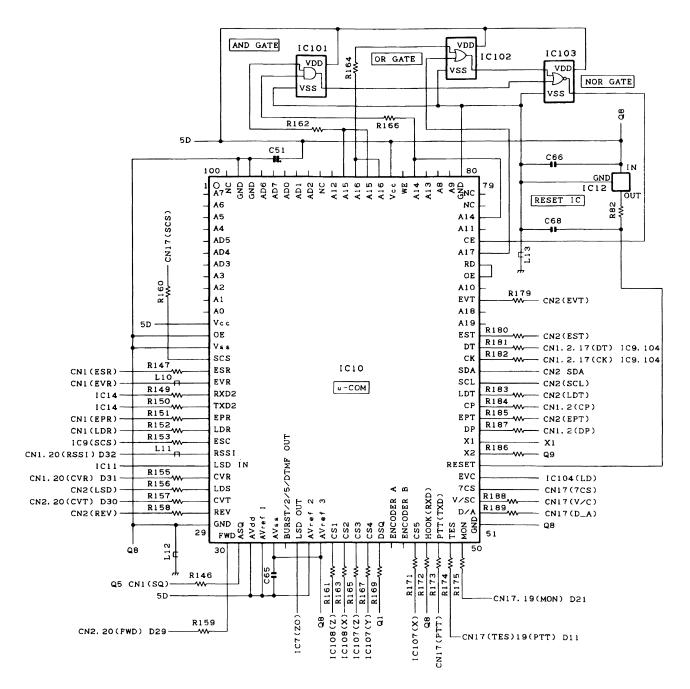


Fig.21 CPU



CIRCUIT DESCRIPTION

(2) Receive audio filter circuit

The receive audio filter circuit consists of operational amplifiers IC3 and IC5. The RA signal from the receiver unit (receive audio signal filtered by the receiver unit) passes through the second HPF (fc=300 Hz) in IC3 (A/2) and the twin T type notch filter (fo=3 kHz) in IC3 (B/2) to attenuate the signalling signal components under 300 Hz and prevent leakage of the signalling signal to the monitor audio. IC15 LFP (fc=3 kHz) cuts the high

frequency noise by low frequency pass characteristics. The signal passes through the volume adjustment variable resistor VR301 and goes to the AF PA circuit as the RAF signal. Its level is adjusted by V1 of electronic volume IC104, the signal passes through the operational amplifier IC105 (A/2) and is output from the CN19 D-sub 25-pin connector as the RA signal.

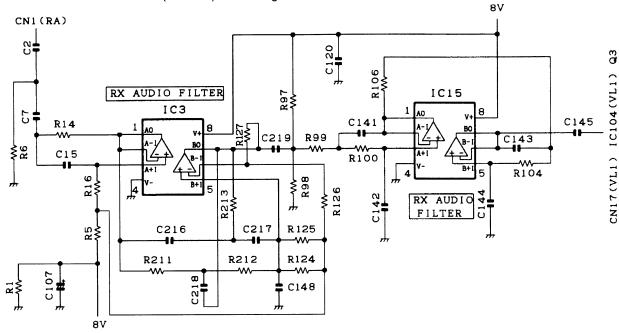


Fig.22 Receive audio filter circuit

(3) LSD filter circuit

The IC11 LSD filter circuit is a pre-filter required to process the receive signal LSD (low speed data) by CPU IC10 for future upgrading. The TKR-830 does not use it.

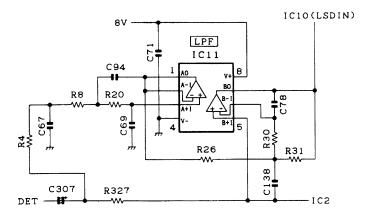
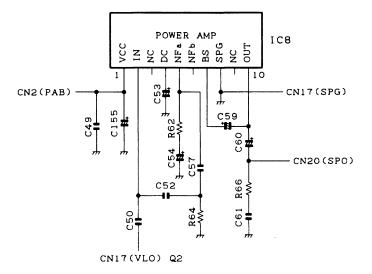


Fig.23 LSD filter circuit

CIRCUIT DESCRIPTION

(4) AF PA circuit

The IC8 AF PA circuit is an AF amplifier for driving speakers to monitor receive audio signals. The 4W audio output can be provided to the external speakers when power supply voltage 13.8 V/4 ohms is supplied by the 15-pin test connector "SPO.SPG" on the rear panel. The output impedance of the internal speaker is adjusted to provide an audio output of about 0.2 W when the internal speaker installed on the TKR-830 front panel is used.





(5) Microphone amplifier circuit

The display circuit contains 7-segment LED D212, D213 (orange: see page 9), D203 (green: power supply), D201 (red: transmission), D202 (green: busy), two-color LED D210 (green: internal/red: external reference state) to display channels and states.

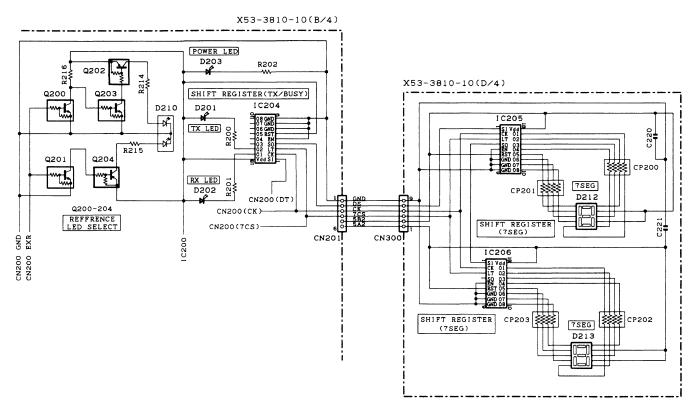
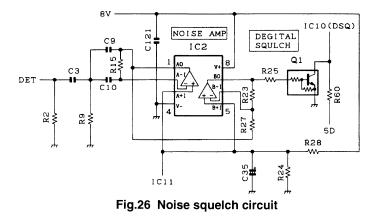


Fig.25 Microphone amplifier circuit

CIRCUIT DESCRIPTION

(6) Noise squelch circuit

The noise squelch circuit in the control unit is a pulse count type noise squelch circuit designed for future upgrading. The operational amplifier IC2 (A/2) HPF and IC2 (B/2) inverting amplifier convert high frequency noise components to pulse signals. The CPU counts the pulses to operate noise squelch. The TKR-830 does not use this circuit.



(7) Display circuit

The microphone amplifier circuit process the audio signal when modulating from the local microphone on the TKR-830 front panel or from the TA pin of the D-sub connector on the rear panel. It consists of AGC amplifier IC13 (B/2), Q7, HPF IC13 (A/2), amplifier Q4, twin T BEF IC5 (B/2), pre-emphasis/limiter (B/2), and splatter filter IC4. The audio signal coming from J201 of the local microphone passes through CN17 pin 25 (MI) and goes to the AGC amplifier IC13 (1/2), Q7. The audio signal is amplified and the gain is automatically controlled. The signal is then fed to "XO" of multiplexer IC7. (IC7 is controlled according to data from the CPU. When the local microphone is used, "XO" and "X" conduct.) The audio signal input to "XO" is output from "X" to the amplifier Q4. Q4 fine-adjusts the amplitude of the audio signal. The signal passes through the HPF, twin T BEF, pre-emphasis/limiter, and splatter filter. The HPF and twin T BEF damp the components under 300 Hz with the fc=300 Hz high pass characteristics and fo=210 Hz notch characteristics to prevent blocking by the signalling audio

signal. The pre-emphasis/limiter circuit gives the audio signal of 300 Hz to 3 kHz +6dB/octav frequency characteristics and emphasizes high frequency to improve the signal-to-noise ratio. The limiter circuit limits the amplitude. The splatter filter attenuates high frequency components and prevents spreading of the occupied frequency bandwidth by the high frequency audio signal. The splatter filter circuit contains two Chebyshev secondary filters to provide fc=3 kHz and the damping characteristics of -24 dB/octave. The audio signal processed by the microphone amplifier is output from connector CN2 to the transmitter unit as modulation signal "MOD". When the signal is modulated from the TA pin of the D-sub 25-pin connector, the audio signal TA is amplified by the amplifier IC106 (A/2), and its level is adjusted by V5 of the electronic volume IC104. The signal passes through "YO", "Y", and "XI" of multiplexer IC7 and is output to "X". The route of the signal after "X" is the same as that for the local microphone.

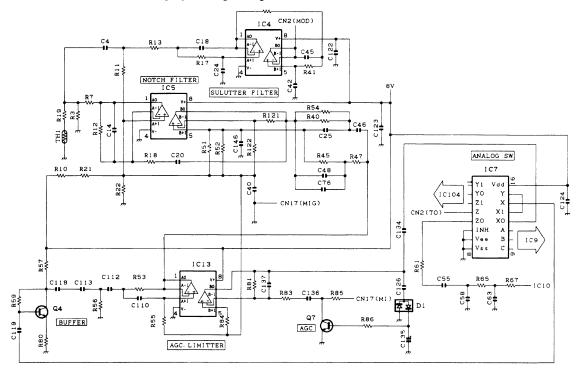


Fig.27 Display circuit

CIRCUIT DESCRIPTION

(8) Channel setting circuit

The channel setting circuit consists of DIP switch S1, S2, and multiplexer IC107, IC108. Channels 1 to 32 can be selected according to the 5-bit data of DIP switch S1, S2 or the 5-bit data input from the D-sub 25-pin connector. One of the data is

selected for channel setting according to the logic of the I/E pin of the D-sub 25-pin connector on the rear panel. If I/E is "H", the internal switch is selected. (see page 8) When it is "L", the external data is selected.

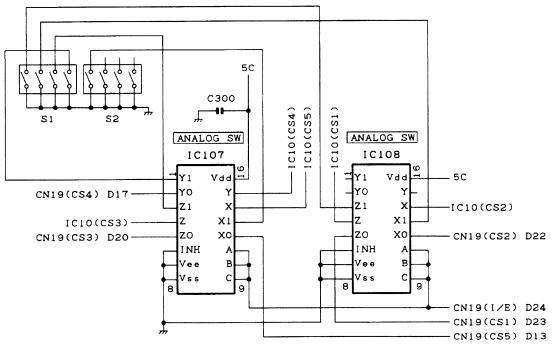
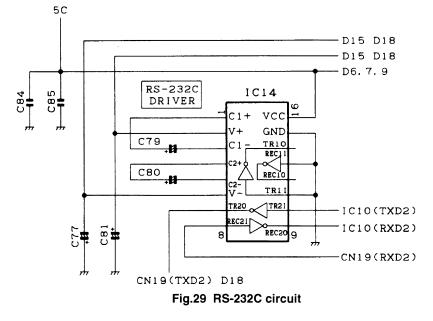


Fig.28 Channel setting circuit

(9) RS-232C circuit

The RS-232C circuit connects the RS-232C serial port of the personal computer directly to the TKR-830 to perform FPU operation. The FPU can also be operated by connecting a programming cable (KPG-46) to the local microphone on the front panel. When the D-sub connector on the rear panel is used, the programming cable is not required. The 232C driver IC (IC14) changes TTL-232C levels. The FPU (KPG-47D) has

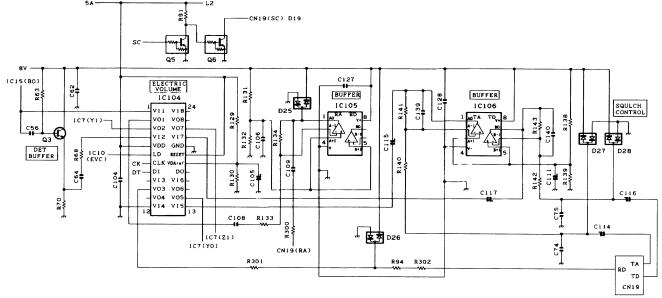
a new transmitter/receiver circuit monitor function (transmission: transmission progressive power display, transmission reflective power display, transmit main PLL lock voltage display; reception: RSSI display, receive main PLL lock voltage display). Data required for this function is also transferred through RS-232C. The firmware can only be modified by the local microphone on the front panel.



CIRCUIT DESCRIPTION

(10) External equipment connection circuit

The external equipment connection circuit has CN19 for RS-232C: RXD2/TXD2, external modulation input: TD (signalling)/ TA (audio), receive output: RD (signalling + audio)/RA (audio), speaker mute input: SPM, monitor control input: MON, transmission input: PTT, squelch output: SC, channel control: IN/EXT SW, and external channel input: EC1/EC2/EC3/EC4/ EC5. CN20 has receive output: RD (signalling + audio), receive signal strength output: RSSI, transmit main PLL lock voltage output: TXCV, receive first local oscillator PLL lock voltage output: RXCV, voltage check output: VC, transmit progressive power value output: FWD, and reference frequency display output: EXTREF.

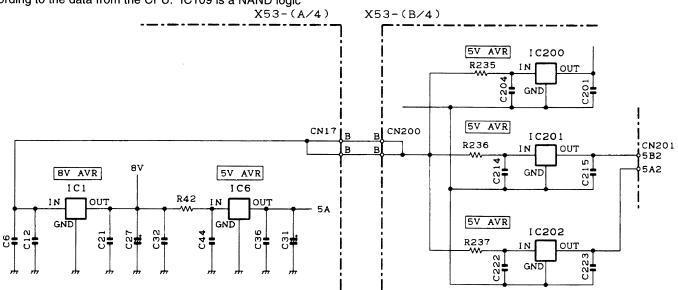




(11) Other circuits

IC1, IC6, IC200, IC201, and IC202 form a three-pin constant voltage power supply IC. It provides power to the control unit circuits. IC101, IC102, and IC103 form a logic IC used to switch the banks of the flash ROM. IC9 is a shift register that shifts the clock, performs AF mute, and controls the multiplexer IC according to the data from the CPU. IC109 is a NAND logic

IC. This IC NANDs the AF mute signal from IC109 and the mute signal SPM from CN19 and turns Q2 "ON" or "OFF" to control muting of the input signal of the AF PA. IC204, IC205, and IC206 compose a shift register that controls display according to the data from the CPU.



SEMICONDUCTOR DATA

Microprocessor : MC-8800-804 (Control Unit IC10)

Pin function

	n function			
Pin No.		1/0	Function	
1~4	A7~A4	-	Flash memory address bus	
5~7	AD5~AD3	-	Flash memory address & data bus	
8~11	A3~A0	-	Flash memory address bus	
12	Vcc	-	+5V	
13	OE	_	Address latch output enable(GND)	
14	Vss	-	GND	
15	SCS	1	NC : Scan switch	
16	ESR	0	RX shift register data strobe output	
17	EVR	0	RX D/A converter IC data strobe output	
18	RXD2	1	Serial interface input 2(ex. PC)	
19	TXD2	0	Serial interface output 2(ex. PC)	
20	EPR	0	RX PLL data strobe output	
21	LDR	I	RX PLL lock detect input	
22	ESC	0	Control shift register data strobe output	
23	RSSI	ļ	RSSI level input	
24	LSD IN	1	Low speed data input (QT/DQT/LTR)	
25	CVR	١	RX VCO voltage input	
26	LDS	I	Sub PLL lock detect input	
27.	CVT	1	TX VCO voltage input	
28	REV	I	Reverse power voltage input	
29	GND	-	GND	
30	FWD	Ι	Forward power voltage input	
31	ASQ	1	Analogue squelch input	
32	AVdd	-	+5V	
33	AVref1	-	+5V	
34	AVss	-	GND	
35	BURST/2/5/	0	Burst /2/5/DTMF output	
	DTMFOUT			
36	LSD OUT	0	Low speed data output(QT/DQT/LTR)	
37	AVref2	-	+5V	
38	AVref3	-	GND	
39	CS1	I	Channel select 1	
40	CS2	1	Channel select 2	
41	CS3	Ι	Channel select 3	
42	CS4		Channel select 4	
43	DSQ	1	NC : Digital Squelch input	
44	ENCODE A	I	NC : Encoder pulse input A	
45	ENCODE B	I	NC : Encoder pulse input B	
46	CS5	I	Channel select 5	
47	HOOK(RXD)	1	serial interface input 1(ex.PC)	
48	PTT(TXD)	I/O	PTT switch input	
			Serial interface output 1(ex. PC)	
L	L		· · · · · · · · · · · · · · · · · · ·	

Pin No.	Port name	1/0	Function
49	TES	I	Test switch input
50	MON	I	Monitor switch input
51	GND	-	GND
52	D/A	I	NC : D/A switch input
53	V/SC	I	NC : Voice scrambler switch input
54	7CS	0	7-segment LED data strobe
55	EVC	0	Control D/A converter IC data strobe output
56	RESET	1	Microcomputer reset input (reset active : L)
57,58	X2,X1	-	14.754MHz (System clock)
59	DP	0	PLL data output
60	EPT	0	TX PLL data strobe output
61	CP	0	PLL clock output
62	LDT	I	TX PLL lock detect input
63	SCL	0	Serial EEPROM clock output
64	SDA	1/0	Serial EEPRON data input/output
65	СК	0	Common clock output
66	DT	0	Common data output
67	EST	0	TX shift register data strobe output
68,69	A19,A18	-	Flash memory address bus
70	EVT	0	TX D/A convector IC data strobe output
71	A10	-	Flash memory address bus
72	OE	-	Flash memory output enable
73	RD	-	Flash memory RD bus
74	A17	-	Flash memory address bus
75	CE	-	Flash memory chip enable
76,77	A11,A14	-	Flash memory address bus
78,79	NC	-	Not used (open)
80	GND	-	GND
81,82	A9,A8	-	Flash memory address bus
83,84	A13,A14	-	Flash memory address bus
85	WE	-	Flash memory WE bus
86	Vcc	-	+5V
87,88	A16,A15	-	Flash memory address bus
89,90	A16,A15	-	Flash memory address bus
91	A12	-	Flash memory address bus
92	NC	-	Not used (open)
93~95	AD2~AD0	-	Flash memory address & data bus
96,97	AD7,AD6	-	Flash memory address & data bus
98,99	GND	-	GND
100	NC	-	Not used (open)

DESCRIPTION OF COMPONENTS

CONTROL UNIT (X53-3810-10)

CIRCUIT	NUMBER	DESCRIPTION
SYMBOL		
D1	DIODE	DET
D6	DIODE	SURGE PROTECT
D7	DIODE	SURGE PROTECT
D8	DIODE	SURGE PROTECT
D9	DIODE	SURGE PROTECT
D11	DIODE	SURGE PROTECT
D13	DIODE	SURGE PROTECT
D15	DIODE	SURGE PROTECT
D17	DIODE	SURGE PROTECT
D18	DIODE	SURGE PROTECT
D20	DIODE	SURGE PROTECT
D21	DIODE	SURGE PROTECT
D22	DIODE	SURGE PROTECT
D23	DIODE	SURGE PROTECT
D24	DIODE	SURGE PROTECT
D25	DIODE	SURGE PROTECT
D26	DIODE	SURGE PROTECT
D27	DIODE	SURGE PROTECT
D28	DIODE	SURGE PROTECT
D29	DIODE	SURGE PROTECT
D30	DIODE	SURGE PROTECT
D31	DIODE	SURGE PROTECT
D32	DIODE	SURGE PROTECT
D200	VARISTOR	CURRENT PROTECT
D201	LED	TX LED
D202	LED	RX LED
D202	LED	POWER LED
D200	DIODE	SURGE PROTECT
D208	DIODE	SURGE PROTECT
D200	DIODE	SURGE PROTECT
D210	LED	REFERENCE LED
D210	LED ASS'Y	7SEG
D212	LED ASS'Y	7SEG
D213	DIODE	SURGE PROTECT
IC1	IC	8V AVR
		NOISE AMP
IC2		
IC3		
IC4	IC	SPLUTTER FILTER
IC5	IC	NOTCH FILTER
IC6	IC	5V AVR
IC7	IC	AUDIO SW
IC8	IC	POWER AMP
IC9	IC	SHIFT REGISTER
IC10	IC	u-COM
IC11	IC	LPF
IC12	IC	RESET IC
IC13	IC	AGC, LIMITTER
IC14	IC	RS-232C DRIVER
IC15	IC	RX AUDIO FILTTER
IC101	IC	AND GATE
IC102	IC	OR GATE
IC103	IC	NOR GATE
L	1	

CIRCUIT SYMBOL	NUMBER	DESCRIPTION
IC104	IC	ELECTRIC VOLUME
IC105	IC	BUFFER
IC106	IC	BUFFER
IC107	IC	ANALOG SW
IC108	IC	ANALOG SW
IC109	IC	NAND GATE
IC200	IC	5V AVR
IC201	IC	5V AVR
IC202	IC	5V AVR
IC204	IC	SHIFT REGISTER(TX/BUSY)
IC205	IC	SHIFT REGISTER(7SEG)
IC206	IC	SHIFT REGISTER(7SEG)
Q1	TRANSISTOR	DEGITAL SQULCH
Q2	TRANSISTOR	AUDIO MUTE
Q3	TRANSISTOR	DET BUFFER
Q4	TRANSISTOR	BUFFER
Q5	TRANSISTOR	SQULCH CONTROL
Q6	TRANSISTOR	SQULCH CONTROL
Q7	TRANSISTOR	AGC
Q8	TRANSISTOR	НООК
Q9	TRANSISTOR	CLOCK SHIFT
Q10	TRANSISTOR	НООК
Q200	TRANSISTOR	REFERENCE LED SELECT
Q201	TRANSISTOR	REFERENCE LED SELECT
Q202	TRANSISTOR	REFERENCE LED SELECT
Q203	TRANSISTOR	REFERENCE LED SELECT
Q204	TRANSISTOR	REFERENCE LED SELECT
Q211	TRANSISTOR	REFERENCE MONITER SELECT

DESCRIPTION OF COMPONENTS

RX UNIT (X55-3040-10)

SYMBOL	NUMBER	DESCRIPTION										
	DIODE,LOCK DETECT											
1 1	VARIABLE	FREQUENCY CONTROL										
	CAPACITANCE DIODE											
D3 \	VARIABLE	FREQUENCY CONTROL										
	CAPACITANCE DIODE											
D4 \	VARIABLE	FREQUENCY CONTROL										
	CAPACITANCE DIODE											
D6 \	VARIABLE	FREQUENCY CONTROL										
	CAPACITANCE DIODE											
D9 \	VARIABLE	FREQUENCY CONTROL										
	CAPACITANCE DIODE											
D10 [DIODE,	IF SWITCH (WIDE/NARROW)										
D11 [DIODE,	DC SWITCH										
IC1 I	IC	PLL(1ST LOCAL)										
IC2	C	AVR										
IC3 I	C	LATCH										
	IC	AVR										
	IC	DC AMP										
	IC	AUDIO SWITCH										
	IC	IFIC										
	IC	IFIC										
	IC	ELECTRONIC VOLUME										
		EEPROM										
		AUDIO AMP										
	IC	AUDIO AMP										
	IC IC	AVR										
	IC IC	DC AMP										
	IC IC	PLL (2ND LOCAL)										
		AVR										
		AVR										
1		AND GATE (LOCK DE)										
1		NOT GATE										
	TRANSISTOR	1ST LOCAL AMP										
		1ST LOCAL AMP										
	TRANSISTOR	1ST LOCAL AMP										
	TRANSISTOR											
	TRANSISTOR	1ST LOCAL AMP										
	TRANSISTOR	FIRST AMPLIFIER										
	FET	VCO (1ST LOCAL)										
	FET	VCO (1ST LOCAL)										
	TRANSISTOR	VCO SWITCH										
	TRANSISTOR	VCO SWITCH										
1 1	TRANSISTOR	VCO SWITCH										
	TRANSISTOR	1ST LOCAL AMP										
	TRANSISTOR	2ND LOCAL AMP										
	TRANSISTOR	DC SWITCH(NARROW)										
	TRANSISTOR	RIPPLE FILTER										
	TRANSISTOR	DC SWITCH(NARROW)										
	TRANSISTOR	DC SWITCH(NARROW)										
	TRANSISTOR	DC SWITCH(WIDE)										
	FET	VCO (2ND)										
Q22	TRANSISTOR	DC SWITCH(WIDE)										
Q23	TRANSISTOR	2ND LOCAL AMP										

CIRCUIT SYMBOL	NUMBER	DESCRIPTION
Q24	TRANSISTOR	IF AMP
Q25	TRANSISTOR	IF AMP
Q26	TRANSISTOR	AF AMP
Q27	TRANSISTOR	2ND LOCAL AMP
Q28	TRANSISTOR	SQ SWITCH
Q29	TRANSISTOR	SQ SWITCH
Q30	TRANSISTOR	2ND LOCAL AMP
Q31	TRANSISTOR	IF AMP
Q32	TRANSISTOR	IF AMP
Q33	TRANSISTOR	2ND LOCAL AMP
Q34	FET	SQ SWITCH
Q35	FET	SQ SWITCH
Q36	TRANSISTOR	OR GATE (SQ CONT)
Q37	TRANSISTOR	OR GATE (SQ CONT)
Q38	TRANSISTOR	NOT GATE(SQ CONT)

DESCRIPTION OF COMPONENTS

TX UNIT (X56-3030-10)

CIRCUIT SYMBOL	NUMBER	DESCRIPTION
D1	VARIABLE	FREQUENCY CONTROL
	CAPACITANCE DIODE	
D2	VARIABLE	FREQUENCY CONTROL
	CAPACITANCE DIODE	
D3	VARIABLE	FREQUENCY CONTROL
	CAPACITANCE DIODE	
D4	VARIABLE	FREQUENCY CONTROL
	CAPACITANCE DIODE	
D5	VARIABLE	MODULATION
	CAPACITANCE DIODE	
D6	VARIABLE	MODULATION
	CAPACITANCE DIODE	
D7	DIODE	RF SWITCH
D8	DIODE	CURRENT CONTROL
D10	DIODE	RF SWITCH
D11	DIODE	CUEERNT STEERING
D12	DIODE	CUEERNT STEERING
D101	DIODE	RF SWITCH
D103	DIODE	RF SWITCH
D201	VARIABLE	FREQUENCY CONTROL
	CAPACITANCE DIODE	
D202	VARIABLE	FREQUENCY CONTROL
	CAPACITANCE DIODE	
D203	VARIABLE	MODULATION
	CAPACITANCE DIODE	
D205	DIODE	DET
D206	VARISTOR	CURRENT PROTECT
D207	VARISTOR	CURRENT PROTECT
D240	VARIABLE	FREQUENCY CONTROL
	CAPACITANCE DIODE	
D301	ZENER DIODE	VOLTAGE CONTROL
D302	DIODE	CURRENT STEERING
D303	SURGE ABS ORBER	SURGE PROTECTOR
D304	DIODE	CURRENT STEERING
D305	DIODE	REVERCE CONNECT
		PROTECTOR
D306	DIODE	DET
D308	DIODE	DET
D310	VARISTOR	CURRENT PROTECTOR
D311	VARISTOR	CURRENT PROTECTOR
IC1	IC	AVR
IC2	IC	AVR
IC3	IC	ELECTRIC VOLUME
IC4	IC	SHIFT REGISTOR
IC100	IC	AVR
IC101	IC	PLL
IC103	IC	AVR
IC105	IC	SUMMING AMP
IC106	IC	EEPROM
IC108	IC	AVR
IC109	IC	BUFFER
IC110	IC	AVR

CIRCUIT SYMBOL	NUMBER	DESCRIPTION
IC201	IC	PLL
IC202	IC	PLL
IC203	IC	DC AMP
IC204	IC	COMPARATOR
IC205	IC	BUFFER
IC301	IC	POWER MODULE
IC302	IC	COMPARATOR
IC303	IC	DC AMP
Q1	FET	OSC
Q2	FET	OSC
Q3	TRANSISTOR	DC SWITCH
Q4	TRANSISTOR	DC SWITCH
Q5	FET	DC SWITCH
Q6	TRANSISTOR	BUFF AMP
Q7	TRANSISTOR	RIPPLE FILTER
Q8	TRANSISTOR	DC SWITCH
Q9	TRANSISTOR	RF AMP
Q10	TRANSISTOR	DC SWITCH
Q11	TRANSISTOR	DC SWITCH
Q12	TRANSISTOR	DC SWITCH
Q13	TRANSISTOR	RF AMP
Q14	TRANSISTOR	RF AMP
Q15	FET	BUFF AMP
Q16	TRANSISTOR	DC SWITCH
Q17	TRANSISTOR	DC AMP
Q18	TRANSISTOR	DC SWITCH
Q102	TRANSISTOR	BUFF AMP
Q106	TRANSISTOR	DUBLER
Q107	TRANSISTOR	RF AMP
Q110	TRANSISTOR	DC SWITCH
Q111	TRANSISTOR	DC SWITCH
Q112	FET	DC SWITCH
Q113	FET	DC SWITCH
Q114	TRANSISTOR	DC SWITCH
Q115	TRANSISTOR	BUFF AMP
Q201	TRANSISTOR	OSC
Q202	TRANSISTOR	BUFF AMP
Q203	TRANSISTOR	DC SWITCH
Q205	TRANSISTOR	RF AMP
Q206	FET	DC SWITCH
Q240	TRANSISTOR	OSC
Q241	TRANSISTOR	BUFF AMP
Q301	TRANSISTOR	DC AMP
Q302	TRANSISTOR	DC SWITCH
Q304	TRANSISTOR	DC SWITCH
Q305	TRANSISTOR	DC SWITCH

PARTS LIST

L: Scandinavia Y: PX (Far East, Hawaii) T: England Y: AAFES (Europe) X: Australia

K: USA

P: Canada

E: Europe M: Other Areas

TKR-830

Ref. No.	Adrress	New parts	Parts No.	Description	Destination	Ref. No.	Adrress	New parts	Parts No.	D	escription	Destin
	1		тк	R-830	1	D210			B30-0864-05		(RE/EXT)(GR/IN	IT)
1	ЗА	*	A62-0587-03	PANEL (FRONT)		D212,213			LA301DB	LED ASSY		
						C1			CC73GCH1H101J	CHIP C	100PF J	
2	3B	•	B11-1192-04	FILTER (LED)		C2			CK73GB1H562J	CHIP C	5600PF J	
3		*	B11-1202-04	FILTER (7 SEG)		C3			CC73GCH1H101J	CHIP C	100PF J	
4		*	B62-1010-00	INSTRUCTION MANUAL		C4			CK73EB1C105K		1.0UF K	
•			562 1010 00			C5			CC73GCH1H101J		100PF J	
5	1A		E23-1115-04	GROUND TERMINAL(FINAL)		00		1		Crim C	10011 3	
6	20					C6			CK73GB1H102K	CHIP C	1000DF K	
	20		E30-3343-15	DC CORD							1000PF K	
7		*	E30-3344-05	DC CORD (ACCESSORY)		C7			CK73GB1H562J		5600PF J	
8			E31-3228-05	LEAD WIRE WITH CONNECTOR		C8			CC73GCH1H101J		100PF J	
9	2B	*	E37-0712-05	FLAT CABLE (CONT-TX,RX)		C9			CC73GCH1H180J	CHIP C	18PF J	
						C10,11			CC73GCH1H101J	CHIP C	100PF J	
10	1B	*	E37-0713-05	FLAT CABLE (TX-FINAL)								
11	2D	*	E37-0715-05	LEAD WIRE WITH CONNECTOR (25P)		C12			CK73FB1E104K	CHIP C	0.10UF K	
12	3B		E37-0716-05	LEAD WIRE WITH CONNECTOR		C13			CC73GCH1H101J		100PF J	
13	3B	*	E37-0717-05	LEAD WIRE WITH CONNECTOR (SP)		C14			CC73GCH1H330J		33PF J	
14	2C	-	E37-0718-05	LEAD WIRE WITH CONNECTOR (BNC)		C15			CK73GB1H562J		5600PF J	
						C16,17			CC73GCH1H101J	CHIP C	100PF J	
15	1B	*	E37-0719-05	LEAD WIRE WITH CONNECTOR TX-RX		1						
16	1B	*	E37-0720-05	LEAD WIRE WITH CONNECTOR		C18			CK73GB1H561K	CHIP C	560PF K	
17	2D	*	E37-0721-05	LEAD WIRE WITH CONNECTOR (15P)		C19			CC73GCH1H101J	CHIP C	100PF J	
18	3B	*	E37-0780-05	LEAD WIRE WITH CONNECTOR		C20			CK73GB1H472K	CHIP C	4700PF K	
19	1B	*	E37-0791-15	LEAD WIRE WITH TERMINAL DC(+)		C21			CK73GB1E103K		0 010UF K	
						C22			CC73GCH1H101J		100PF J	
20	2D		F06-4027-05	FUSE(BLADE) (4A/32V)		022			0073001111013	Crim C	10011 3	
20						000			0//705040405/	0.000		
21	2C	Ţ	F10-2296-04	SHIELDING PLATE (RX,BACK)		C23			CK73EB1C105K		1 OUF K	
22	2C	*	F10-2297-04	SHIELDING PLATE (RX, PARTITION)		C24			CK73GB1H331K		330PF K	
						C25			CK73GB1H272J	CHIP C	2700PF J	
23	1B		G02-0576-14	FLAT SPRING		C26			CC73GCH1H101J	CHIP C	100PF J	
24	2C	*	G02-0829-14	FLAT SPRING		C27			C92-0505-05	CHIP-TAN	10UF 16W	v
25	2C	•	G02-0831-04	FLAT SPRING (HELICAL UPPER)								
26	ЗB		G13-1653-04	CUSHION (SP)		C28-30			CC73GCH1H101J	CHIP C	100PF J	
27	3B		G13-1654-04	CUSHION (LED)		C31			C92-0505-05		10UF 16W	v
21	50		010 1004 04			C32			CK73GB1H102K		1000PF K	•
20	00		010 1000 04									
28	3B		G13-1669-04	CUSHION (MIC)		C33,34			CC73GCH1H101J	1	100PF J	
29	3B	*	G13-1670-04	CUSHION (VOL,TEST)		C35			C92-0505-05	CHIP-TAN	10UF 16W	v l
30	3B	*	G13-1703-14	CUSHION (FRONT, PANEL)								
						C36			CK73GB1E103K	CHIP C	0 010UF K	
31		*	H10-6612-02	FOAM PACKING MOLD		C37-39			CC73GCH1H101J	CHIP C	100PF J	
32			H20-1437-03	PROTECTION COVER		C40			CK73EB1C105K	CHIP C	1 OUF K	
33		*	H52-1109-02	ITEM CARTON CASE		C41			CC73GCH1H101J		100PF J	
00			1102 1103 02			C42			CC73GCH1H390J		39PF J	
24	1.0		121 0275 04			042			00730011113303	CHIF C	39FF J	
34	1A		J21-8375-04	HARDWARE FIXTURE		640			0070001411400		10005	
			V04 0404 67			C43			CC73GCH1H101J		100PF J	
36		•	K01-0421-05	HANDLE (ACCESSORY)		C44			CK73FB1E104K		0 10UF K	
37	ЗA		K29-3002-14	PUSHKNOB (TEST)		C45			CK73GB1H152K	CHIP C	1500PF K	1
38	3B		K29-4539-04	KNOB (VOL)		C46			CK73GB1H272J	CHIP C	2700PF J	
						C47			CC73GCH1H101J	CHIP C	100PF J	
39	2D	*	N09-2292-05	HEXAGON BOSS SCREW		1						1
A	1B	*	N32-3006-45	FLAT HEAD MACHINE SCREW		C48			CK73GB1H272J	CHIP C	2700PF J	
В	3A	*	N32-4008-45	FLAT HEAD MACHINE SCREW		C49			CK73GB1H102K	1	1000PF K	
				BINDING HEAD MACHINE SCREW(DC)								
C	1B		N35-3006-46			C50			CK73EB1C105K		1 OUF K	
F	1A		N67-2606-46	PAN HEAD SEMS SCREW W		C51		ľ	C92-0728-05	ELECTROLYTIC		v
						C52			CK73GB1H102K	CHIP C	1000PF K	
G			N67-3006-46	PAN HEAD SEMS SCREW W								
D	2D		N87-2606-46	BRAZIER HEAD TAPTITE SCREW		C53,54		*	C92-0726-05	ELECTROLYTIC	47UH 25W	v
E	1B	*	N87-2616-46	BRAZIER HEAD TAPTITE SCREW		C55			CK73GB1E103K	CHIP C	0.010UF K	
	1					C56			CK73FB1E104K		0 10UF K	
40	1A		S79-0401-05	THERMAL SWITCH		C57,58			CK73GB1H102K		1000PF K	
40	3B		T07-0347-05	SPEAKER		C59			C92-0726-05			N
41	1 30		107-0347-03	SI LANER	L	0.09			032-0720-05	ELECTROLYTIC	47UN 25W	v I
		CC	NTROL UN	IRT (X53-3810-10)		000			000 0777 77			
				· · · · · · · · · · · · · · · · · · ·		C60		1	C92-0728-05	ELECTROLYTIC		V (
D201	1	*	B30-2197-05	LED (RE/TX)		C61,62			CK73FB1E104K	CHIP C	0 10UF K	-
D201												

PARTS LIST

CONTROL UNIT (X53-3810-10)

Ref. No.	Adrress	New parts	Parts No.	Description			Destination	Ref. No.	Adrress	New parts	Parts No.	ſ	Destinatior		
C64			CK73FB1E104K	CHIP C	0 10UF	К		C205,206			CC73GCH1H101J	CHIP C	100PF	J	
C65,66			CK73GB1E103K	CHIP C	0 010UF	К	1	C207			C92-0505-05	CHIP-TAN	10UF	16WV	
C67			CK73GB1C683K	CHIP C	0 068UF	к		C208			CC73GCH1H101J	CHIP C	100PF	J	
C68			CK73FB1E104K	1	0 10UF			C209			CK73GB1H471K	CHIP C	470PF	к	
C69			CK73GB1H222K	1	2200PF			C210			CK73GB1H102K	CHIP C	1000PF		
								0210							
C70			CC73GCH1H680J			J		C211			CC73GCH1H101J	CHIP C	100PF	J	
C71			CK73GB1E103K	1	0 010UF	К		C212			CK73GB1H102K	CHIP C	1000PF	К	
C72,73			CC73GCH1H270J	CHIP C	27PF	J		C213			CK73GB1H471K	CHIP C	470PF	К	
C74,75			CK73GB1H102K	CHIP C	1000PF	К		C214			CK73FF1E334Z	CHIP C	0.33UF	Z	
C76			CK73GB1H272J	CHIP C	2700PF	J		C215			CK73FB1E104K	CHIP C	0 10UF		
_]											
C77			C92-0519-05			25WV		C216,217			CK73GB1H272J	CHIP C	2700PF		
C78			CC73GCH1H121J	CHIP C	120PF	J		C218		*	CK73GB1H562J	CHIP C	5600PF	J	
C79-81			C92-0519-05	CHIP-TAN	1 OUF	25WV		C219		ļļ	CK73EB1C105K	CHIP C	1 OUF	К	
C82,83			CK73GB1H102K	CHIP C	1000PF	К		C220,221			CK73GB1E103K	CHIP C	0 010UF	К	
C84			CK73FB1E104K	CHIP C	0 10UF	К		C222			CK73FF1E334Z	CHIP C	0 33UF	Z	
C85-89			CK73GB1H102K	CHIP C		К		C223			CK73FB1E104K	CHIP C	0 10UF		
C90			CC73GCH1H101J	CHIP C		J		C300-302			CK73GB1E103K	CHIP C	0 010UF		
C91			CK73GB1H102K	CHIP C		К		C305			CK73GB1E103K	CHIP C	0.010UF	K	
C92,93			CC73GCH1H101J	CHIP C	100PF	J		C306			CK73GB1H102K	CHIP C	1000PF	К	
C94			CK73GB1E123K	CHIP C	0 012UF	К		C307			C92-0505-05	CHIP-TAN	10UF	16WV	
C95			CK73GB1H102K	CHIP C	1000PF	к		CNI1 2			E40 5726 05			D 20D	
								CN1,2			E40-5736-05	FLAT CABLE C			
C96,97			CC73GCH1H101J	CHIP C		J	1	CN17			E40-5736-05	FLAT CABLE C		H 26P	
C98	1		CK73GB1H102K			к		CN19		*	E40-5960-05	PIN ASSY 301			
C99-102			CC73GCH1H101J	CHIP C		J		CN20			E40-5701-05	PIN ASSY 14	2		
C103			CK73GB1E103K	CHIP C	0.010UF	К		CN200			E40-5761-05	FLAT CABLE C	ONNECTO	R 26P	
C104			CK73GB1H102K	CHIP C	1000PF	к		CN201			E40-5821-05	PIN ASSY 6P			
				CHIP-TAN	1000F	10WV									
C105			C92-0628-05					CN203			E40-5538-05	PIN ASSY	_		
C106			CK73EB1C105K		1 OUF	К		CN205	1		E40-5701-05	PIN ASSY 14	Þ		
C107		l	C92-0505-05	CHIP-TAN	10UF	16WV		CN300		*	E40-5986-05	PIN ASSY 6P			
C108,109			CK73EB1C105K	CHIP C	1 OUF	К		CN301			E40-5701-05	PIN ASSY 14	Ρ		
C110		•	CK73GB1H562J	CHIP C	5600PF	J		J201			E08-0876-05	MODULAR JA	CK		
C111			C92-0628-05	CHIP-TAN	10UF	10WV		3201			200-0070-03	MODULANSA	icit.		
	1		CK73GB1H562J	CHIP C		J	1	1.1.0			1 40 1015 40			2(1001111)	
C112,113								L1-3			L40-1015-48	SMALL FIXED	INDUCTO	H(1000H)	
C114,115			C92-0519-05	CHIP-TAN	1 OUF	25WV		L5-11			L92-0140-05	FERRITE CHIP			
C116,117			C92-0628-05	CHIP-TAN	10UF	10WV		L12,13			L92-0131-05	FERRITE CHIP			
C118			CK73FB1C105K	CHIP C	1 OUF	К		X1			L78-0431-05	RESONATOR	(14 7456	M)	
C119			CK73FB1E104K	CHIP C	0 10UF	К				{					
C120-125			CK73GB1E103K	CHIP C	0 010UF			CP200-203	[R90-1016-05	MULTIPLE R	470		
				CHIP C	0 10UF			01200-203			1130-1010-03	NOLINELI	470		
C126			CK73FB1E104K	CHIPC			I	D1	1		DV70001 1024 1	CHIP R	020V	1/16\4/	
C127,128			CK73GB1E103K	Unir U	0 010UF	N	1 I	R1			RK73GB1J824J			J 1/16W	
			000 05	0.00		05144		R2			RK73GB1J473J	CHIP R	47K	J 1/16W	
C129			C92-0519-05	CHIP-TAN	1 OUF	25WV		R3,4			RK73GB1J223J	CHIP R	22K	J 1/16W	
C130-133			CC73GCH1H101J	CHIP C	100PF	J		R5			RK73GB1J824J	CHIP R	820K	J 1/16W	
C134	1		CK73FB1E104K	CHIP C	0.10UF	К		R6			RK73GB1J683J	CHIP R	68K	J 1/16W	
C135			C92-0501-05	CHIP-TAN	1 5UF	10WV		1	1						
C136			CK73FB1E104K	CHIP C	0 10UF	К		R7	l		RK73GB1J223J	CHIP R	22K	J 1/16W	
								R8	1		RK73GB1J184J	CHIP R	180K	J 1/16W	
C137			CC73GCH1H470J	CHIP C	47PF	J		R9	1		RK73GB1J183J	CHIP R	18K	J 1/16W	
C138		1	CK73FB1H333K	CHIP C	0 033UF		1	R10	1	1	RK73GB1J103J	CHIP R	10K	J 1/16W	
									1	1	1				
C139			CC73GCH1H101J	CHIP C	100PF	J		R11	1	1	RK73GB1J474J	CHIP R	470K	J 1/16W	
C140			CC73GCH1H330J	CHIP C	33PF	J		010	1		DK700D4 JOC4 J	CUIP D	COOK	1 1/1014/	
C141			CK73GB1H561J	CHIP C	560PF	J		R12 R13		1	RK73GB1J684J RK73GB1J184J	CHIP R CHIP R	680K 180K	J 1/16W J 1/16W	
C142			CK73GB1H331K	CHIP C	330PF	К		R14			RK73GB1J223J	CHIP R	22K	J 1/16W	
C142		+	CK73GB1H152J	CHIP C		J		R15			RK73GB1J824J	CHIP R	820K	J 1/16W	
		l		CHIP C	39PF	J				1	1				
C144		1	CC73GCH1H390J					R16			RK73GB1J474J	CHIP R	470K	J 1/16W	
C145	1		CK73EB1C105K	CHIP C	1 OUF	K		P17					2204	1/10\4/	
C146			CK73GB1H272J	CHIP C	2700PF	J		R17 R18			RK73GB1J224J RK73GB1J561J	CHIP R CHIP R	220K 560	J 1/16W	
C149			CK22CD1U102V	CHIPC	180055	ĸ								J 1/16W	
C148			CK73GB1H182K	CHIP C	1800PF	K		R19	1		RK73GB1J473J	CHIP R	47K	J 1/16W	
C155	1	1	C92-0729-05	ELECTROLYTIC		25WV		R20,21	1	1	RK73GB1J184J	CHIP R	180K	J 1/16W	
C201	1		CK73FB1E104K	CHIP C	0 10UF	к		R22			RK73GB1J224J	CHIP R	220K	J 1/16W	
C202,203			CC73GCH1H101J	CHIP C	100PF	J								-	
0202,200			CK73FF1E334Z	CHIP C	0.33UF	-		R23	1	1	RK73GB1J105J	CHIP R	1 0M	J 1/16W	1

PARTS LIST

CONTROL UNIT (X53-3810-10)

Ref. No.	Adrress	New parts	Parts No.	Description			Destination	Ref. No.	Adrress	New parts	Parts No.	Description				Destination	
R24			RK73GB1J104J	CHIP R	100K	J	1/16W		R111			RK73GB1J473J	CHIP R	47K	J	1/16W	
R25			RK73GB1J473J	CHIP R	47K	J	1/16W		R112,113			RK73GB1J102J	CHIP R	1 OK	J	1/16W	
R26			RK73GB1J154J	CHIP R	150K	J	1/16W		R115-117			RK73GB1J102J	CHIP R	1 OK	J	1/16W	
R27			RK73GB1J103J	CHIP R	10K		1/16W		R118-120			RK73GB1J473J	CHIP R	47K		1/16W	
R28			RK73GB1J104J	CHIP R	100K		1/16W		R121			RK73GB1J563J	CHIP R	56K		1/16W	
R29			RK73GB1J272J	CHIP R	2 7K	.1	1/16W		R122			RK73GB1J473J	CHIP R	47K	J	1/16W	
R30,31			RK73GB1J334J	CHIP R	330K		1/16W		R124			RK73GB1J274G	CHIP R	270K		1/16W	
R32-39			RK73GB1J102J	CHIP R	1.0K		1/16W		R125			RK73GB1J394J	CHIP R	390K		1/16W	
R40			RK73GB1J274J	CHIP R	270K		1/16W		R126			RK73GB1J473G	CHIP R	47K		1/16W	
R41			RK73GB1J224J	CHIP R	270K 220K		1/16W		R127			RK73GB1J563G	CHIP R	56K		1/16W	
D 40			B00 0005 05	0.000	20		4/014/		0100			DK20004 1400 I		101		1/1014/	
R42			R92-0685-05	CHIP R	22		1/2W		R129			RK73GB1J103J	CHIP R	10K		1/16W	
R43			RK73GB1J272J	CHIP R	2.7K		1/16W		R130			RK73GB1J123J	CHIP R	12K		1/16W	
R44			RK73GB1J224J	CHIP R	220K		1/16W		R131			RK73GB1J104J	CHIP R	100K		1/16W	
R45			RK73GB1J274J	CHIP R	270K	J	1/16W		R132	ļ	l	RK73GB1J124J	CHIP R	120K	J	1/16W	
R46			RK73GB1J332J	CHIP R	3 3K	J	1/16W		R133			RK73GB1J103J	CHIP R	10K	J	1/16W	
R47			RK73GB1J274J	CHIP R	270K	J	1/16W		R134			RK73GB1J563J	CHIP R	56K	J	1/16W	
R48			RK73GB1J473J	CHIP R	47K	J	1/16W		R137			RK73GB1J473J	CHIP R	47K	J	1/16W	
R49,50			RK73GB1J102J	CHIP R	1 0K		1/16W		R138			RK73GB1J104J	CHIP R	100K		1/16W	
R51,52			RK73GB1J274J	CHIP R	270K		1/16W		R139	1		RK73GB1J124J	CHIP R	120K		1/16W	
R53			RK73GB1J393J	CHIP R	39K		1/16W		R140,141			RK73GB1J104J	CHIP R	100K		1/16W	
R54			RK73GB1J334J	CHIP R	330K	1	1/16W		R142	-		RK73GB1J223J	CHIP R	22K	ı	1/16W	
R55			RK73GB1J474J	CHIP R	470K		1/16W		R143	ļ	ļ	RK73GB1J224J	CHIP R	220K		1/16W	
R56			RK73GB1J823J	CHIP R	82K		1/16W		R146			RK73GB1J102J	CHIP R	1 OK		1/16W	
R57,58			RK73GB1J332J	CHIP R	3.3K		1/16W		R147			RK73GB1J471J	CHIP R	470		1/16W	
R59			RK73GB1J394J	CHIP R	390K	J	1/16W		R149,150			RK73GB1J102J	CHIP R	1 OK	J	1/16W	
R60			RK73GB1J223J	CHIP R	22K	J	1/16W		R151			RK73GB1J471J	CHIP R	470	J	1/16W	
R61			RK73GB1J154J	CHIP R	150K	J	1/16W		R152			RK73GB1J102J	CHIP R	1 OK	J	1/16W	
R62			RK73GB1J471J	CHIP R	470	J	1/16W		R153			RK73GB1J471J	CHIP R	470	J	1/16W	
R63			RK73GB1J154J	CHIP R	150K	J	1/16W		R155-167		l	RK73GB1J102J	CHIP R	1 OK	J	1/16W	
R64			RK73GB1J105J	CHIP R	1 0M	J	1/16W		R169			RK73GB1J102J	CHIP R	1.0K	J	1/16W	
R65			RK73GB1J103J	CHIP R	10K	.1	1/16W		R171-175			RK73GB1J102J	CHIP R	1 OK	.1	1/16W	
R66			RK73FB2A2R2J	CHIP R	22		1/10W		R179,180			RK73GB1J471J	CHIP R	470		1/16W	
R67			RK73GB1J103J	CHIP R	10K		1/16W		R181-184			RK73GB1J102J	CHIP R	470 1 OK		1/16W	
R68			RK73GB1J472J	CHIP R	4.7K		1/16W		R185		1	RK73GB1J471J	CHIP R	470		1/16W	
R69			RK73GB1J472J	CHIP R	47K		1/16W		R186-189			RK73GB1J102J	CHIP R	470 1 OK		1/16W	
070			BICTOR LAND														
R70			RK73GB1J102J	CHIP R	1 OK		1/16W		R200			RK73FB2A331J	CHIP R	330		1/10W	
R71-75			RK73GB1J473J	CHIP R	47K		1/16W		R201,202			RK73FB2A221J	CHIP R	220	J	1/10W	
R76-79			RK73GB1J102J	CHIP R	1 OK		1/16W		R203			R92-1252-05	CHIP R	0 OHM			
R80			RK73GB1J222J	CHIP R	2 2K		1/16W		R204			RK73GB1J102J	CHIP R	1 OK		1/16W	
R81			RK73GB1J564J	CHIP R	560K	J	1/16W		R205			RK73GB1J681J	CHIP R	680	J	1/16W	
R82			RK73GB1J224J	CHIP R	220K	J	1/16W		R206			RK73GB1J102J	CHIP R	1 OK	J	1/16W	
R83-86			RK73GB1J103J	CHIP R	10K	J	1/16W	1	R207			R92-1279-05	CHIP R	33	J	1W	
R87	1		RK73GB1J473J	CHIP R	47K	J	1/16W		R208,209	1		RK73GB1J102J	CHIP R	1 OK	J	1/16W	
R88	1		RK73GB1J122J	CHIP R	1 2K	J	1/16W		R210			RK73GB1J683J	CHIP R	68K	J	1/16W	
R89			R92-0670-05	CHIP R	0 OHM				R211,212			RK73GB1J274G	CHIP R	270K	G	1/16W	
R90			RK73GB1J472J	CHIP R	4 7K	J	1/16W		R213			RK73GB1J184J	CHIP R	180K	J	1/16W	
R91			RK73GB1J103J	CHIP R	10K		1/16W		R214			RK73FB2A221J	CHIP R	220		1/10W	
R92,93			RK73GB1J122J	CHIP R	1.2K		1/16W		R215			RK73FB2A331J	CHIP R	330		1/10W	
R94			R92-1252-05	CHIP R	0.0HM	5	.,	1	R216	1		RK73FB2A472J	CHIP R	4 7K		1/10W	
R95			RK73GB1J122J	CHIP R	1 2K	J	1/16W		R235-237			R92-1213-05	CHIP R	100		1/2W	
POG			DK72CD1 1102 1	CHIP R	1 OK		1/16W		R300			DK720D1 1101 1		100		1/10\4/	
R96 R97,98			RK73GB1J102J RK73GB1J474J	CHIP R	470K				R300			RK73GB1J101J	CHIP R	100 0 OHM		1/16W	
			1	1			1/16W					R92-1252-05	CHIP R			1/10\4/	
R99,100			RK73GB1J224J	CHIP R	220K		1/16W	[R302			RK73GB1J101J	CHIP R	100		1/16W	
R101			RK73GB1J102J	CHIP R	1 OK		1/16W		R303,304			RK73GB1J102J	CHIP R	1 OK		1/16W	
R102,103			RK73GB1J473J	CHIP R	47K	J	1/16W		R305,306			RK73GB1J473J	CHIP R	47K	J	1/16W	
R104			RK73GB1J224J	CHIP R	220K		1/16W		R307-312			RK73GB1J102J	CHIP R	1 OK	J	1/16W	
4 - · ·			RK73GB1J473J	CHIP R	47K	J	1/16W		R313-318			RK73GB1J473J	CHIP R	47K	J	1/16W	
R105			Laura and the state		0001/	1	1/16W	1	R319	1		RK73GB1J102J	CHIP R	1 OK	.1	1/1014/	1
R105 R106			RK73GB1J224J	CHIP R	220K	J	1/1044	1 1	n319		1	1107300131023	1 Grill II	1.01	0	1/16W	
			RK73GB1J224J RK73GB1J473J	CHIP R	220K 47K		1/16W		R323			RK73GB1J473J	CHIP R	47K		1/16W	-

PARTS LIST

CONTROL UNIT (X53-3810-10)

Ref. No.	Adrress	New parts	Parts No.	Description	Destination	Ref. No.	Adrress	New parts	Parts No.		Descript	ion	Destination
R325	1		RK73GB1J103J	CHIP R 10K J 1/16W			l		RX UNIT (X55-304	10-10)		L
R326			RK73GB1J473J	CHIP R 47K J 1/16W		C1	1 1		CC73GCH1H030C	CHIP C	3.0PF	С	1
R327			RK73GB1J474J	CHIP R 470K J 1/16W		C2			CK73GB1H102K	CHIP C	1000PF	к	
R328			RK73GB1J2R2J	CHIP R 2.2 J 1/16W		C3			CK73GB1H471K	CHIP C	470PF	ĸ	
R331			RK73GB1J103J	CHIPR 10K J 1/16W		C4			CK73GB1H102K	CHIP C	1000PF		
1001			11073001010000			C5			CK73GB1H103K	CHIP C	0.010UF		
VR201			R12-6423-05	TRIMMING POT.(10K)		0.5			GRYSODITTOSK		0.01001	ĸ	
VR201						00			CK70CD1U102K	CUID C	100005	V	
VD301			R05-3442-05	POTENTIOMETER(10K)		C6			CK73GB1H102K	CHIP C	1000PF		
C1 0			070 0404 05	DID OM/ITOLISO		C7			CK73GB1H471K	CHIP C	470PF	K	
S1,2			S79-0421-05	DIP SWITCHES		C8			C92-0002-05	CHIP-TAN	0.22UF	35WV	
S200			S40-2441-15	PUSH SWITCH		C9			C92-0633-05	CHIP-TAN	22UF	10WV	
						C10		*	C92-0545-05	CHIP-TAN	2.2UF	6 3WV	
D1			HSM88AS	DIODE									
D6-9			DA204U	DIODE		C11			CK73GB1H471K	CHIP C	470PF	К	
D11	1		DA204U	DIODE		C12			CC73GCH1H070D	CHIP C	7.0PF	D	
D13			DA204U	DIODE		C13			CC73GCH1H2R5C	CHIP C	2.5PF	С	
D15			DA204U	DIODE		C14			C92-0001-05	CHIP-C	0.1UF	35WV	
						C15			CC73FCH1H060D	CHIP C	6.0PF	D	
D16			1SS355	DIODE									
D17,18			DA204U	DIODE		C16			CC73GCH1H080D	CHIP C	8.0PF	D	
D20-32			DA204U	DIODE		C17			CC73FCH1H120J	CHIP C	12PF	J	
D200		•	MINISMDC075-02	VARISTOR		C18			CK73GB1H103K	CHIP C	0.010UF		
D207-209	'		DA204U	DIODE		C19,20			CK73GB1H471K	CHIP C	470PF	ĸ	
						C21			CC73FCH1H050C	CHIP C	5 0PF	C	
D214			DA204U	DIODE						1		-	
						C22			CK73GB1H102K	CHIP C	1000PF	к	
IC1			NJM78L08UA	IC (VOLTAGE REGULATOR/ +8V)		C23			CC73GCH1H020C	CHIP C	2.0PF	C	
IC2-5	1		NJM4558E	IC (OP AMP X2)		C23			CC73GCH1H101J	CHIP C	100PF	J	
IC2-5			NJM78L05UA	IC (VOLTAGE REGULATOR/ +5V)		C24 C25			CC73FCH1H100D	CHIPC	100FF	D	
IC7			BU4053BCF			C25				CHIPC	470PF	ĸ	
				IC (AUDIO SWS SW)	1 1	626			CK73GB1H471K	CHIPC	47085	ĸ	
IC8			LA4422	IC (POWER AMP)		007			01/2000	0,000	100005		
	1		0			C27			CK73GB1H102K	CHIP C	1000PF	K	
IC9	1		BU4094BCFV	IC (8bit SHIFT/STORE REGISTER)		C28			CK73FB1E104K	CHIP C	0.10UF	K	
IC10		*	MC-8800-804	IC (MICROPROCESSOR)		C30,31			CK73GB1H471K	CHIP C	470PF	K	
IC11			NJM4558E	IC (OP AMP X2)	1	C32			CC73FCH1H080D	CHIP C	8.0PF	D	
IC12			RH5VL42C	IC (REGULATOR)		C33			CC73GCH1H220J	CHIP C	22PF	J	
IC13			NJM4558E	IC (OP AMP X2)	1								
					1 1	C34,35			CK73GB1H102K	CHIP C	1000PF	К	
IC14			ADM232LAR	IC (RS-232C DRIVERS/RECEIVERS)		C36			CK73GB1H471K	CHIP C	470PF	К	
IC15	1		NJM4558E	IC (OP AMP X2)		C38			CC73GCH1H101J	CHIP C	100PF	J	
IC101			TC7S08FU	IC (2INPUT AND GATE)		C39			CC73GCH1H150J	CHIP C	15PF	J	
IC102			TC7S32FU	IC (2INPUT OR GATE)		C40			CC73FCH1H080D	CHIP C	8.0PF	D	
IC103			TC7S02FU	IC (2, INPUT NOR GATE)									
						C41			CK73GB1H102K	CHIP C	1000PF	К	
IC104			M62364FP	IC (D/A CONVERTER)		C42			CK73FB1E104K	CHIP C	0.10UF	к	
IC105,106			NJM4558E	IC (OP AMP X2)	1 1	C43			CC73FCH1H100D	CHIP C	10PF	D	
IC107,108			BU4053BCF	IC (ANALOG SW)		C44			CC73FCH1H070D	CHIP C	7 OPF	D	
IC109			TC7S00FU	IC (NAND GATE)		C45,46			CK73GB1H102K	CHIP C	1000PF		
IC200-202			NJM78L05UA	IC (VOLTAGE REGULATOR/ +5V)		040,40			OK750B IIII02K	on o	100011	ĸ	
10200-202	1		, IOIVIT OLUGUM			C47			CC73FCH1H070D	CHIP C	7.0PF	D	
10204 206	1		BU2114E			1							
IC204-206			BU2114F	IC (LED DRIVER)		C48			C92-0628-05	CHIP-TAN	10UF	10WV	
			DTOLATION			C49			CC73GCH1H0R5C	CHIP C	0.5PF	С	
Q1	1	1	DTC144EUA	DIGITAL TRANSISTOR		C50			CC73FCH1H100D	CHIP C	10PF	D	
02			DTC363EK	DIGITAL TRANSISTOR		C51,52			CK73GB1H102K	CHIP C	1000PF	К	
Q3			2SC4081(R)	TRANSISTOR		1							
Q4			2SC2712(Y)	TRANSISTOR		C53			C92-0628-05	CHIP-TAN	10UF	10WV	
Q5		•	DTC144EUA	DIGITAL TRANSISTOR		C54			CK73GB1H102K	CHIP C	1000PF	Κ	
						C55			CK73GB1H103K	CHIP C	0 010UF	К	
Q6			DTC114EUA	DIGITAL TRANSISTOR		C57			CC73GCH1H0R5C	CHIP C	0 5PF	С	
07			2SD1757K	TRANSISTOR		C58			CK73GB1H102K	CHIP C	1000PF		
Q8			DTC114EUA	DIGITAL TRANSISTOR		1							
Q9			2SC4215(Y)	TRANSISTOR		C60,61			CK73FB1E104K	CHIP C	0 10UF	К	
Q10			DTA144EUA	DIGITAL TRANSISTOR		C62			CK73GB1H102K	CHIP C	1000PF		
			5 111 11204			C63			CK73GB1H102K	CHIP C	0.010UF		
Q200,201			DTC144EUA	DIGITAL TRANSISTOR		C63			CK73GB1H103K	CHIP C			
											1000PF		
Q202			DTA114EUA	DIGITAL TRANSISTOR		C65			CC73GCH1H100D	CHIP C	10PF	D	
Q203		*	DTC144EUA	DIGITAL TRANSISTOR									
Q204			DTA114EUA	DIGITAL TRANSISTOR		C66			CK73GB1H471K	CHIP C	470PF	K	
Q211	1	*	DTC144EUA	DIGITAL TRANSISTOR		C67			CC73GCH1H150J	CHIP C	15PF	J	
	1					C68			CC73GCH1H080D	CHIP C	8 0PF	D	
TH1	1	1 :	157-302-65801	THERMISTOR		C69			CK73GB1H471K	CHIP C	470PF	К	

PARTS LIST

Ref. No.	Adrress	New parts	Parts No.	D	escripti	on	Destination	Ref. No.	Adrress	New parts	Parts No.		Descripti	ion	Destination
C70			C92-0555-05	CHIP-TAN	0.047UF	35WV		C143,144			CK73GB1H103K	CHIP C	0.010UF	К	
C71			CC73GCH1H150J	CHIPC	15PF	J		C145		1	CK73GB1E223K	CHIP C	0.022UF	К	
C72,73			CK73GB1H102K	CHIP C	1000PF	к		C146-148			CK73GB1H103K	CHIP C	0 010UF		
C74			CK73GB1H471K	CHIP C	470PF	ĸ		C149			CK73FB1E104K	CHIP C	0 10UF	ĸ	
C75			CC73GCH1H150J	CHIP C	15PF	J		C150			C92-0628-05	CHIP-TAN	10UF	10WV	
C76			C92-0001-05	CHIP-C	0.1UF	35WV		C151,152			CK73GB1H103K	CHIP C	0.010UF	ĸ	
C78 C77			CK73FB1E104K	CHIP-C	0.100 0.10UF	K		C151,152 C153			CK73GB1H102K	CHIP C	1000PF		
				1				1							
C78	1		CC73GCH1H040C	CHIP C	4.0PF	C		C154,155			CK73GB1H103K	CHIP C	0.010UF		1
C79			CC73GCH1H080D	CHIP C	8.0PF	D		C156			CC73GCH1H040C	CHIP C	4.0PF	С	
C80			CK73GB1H102K	CHIP C	1000PF	К		C157			CK73GB1H102K	CHIP C	1000PF	K	
C81			CC73GCH1H020C	CHIP C	2.0PF	С		C158,159			CK73GB1H103K	CHIP C	0.010UF		
C82		*	C92-0728-05	ELECTROLYTIC	470UH	16WV		C160,161			CK73GB1H102K	CHIP C	1000PF	К	
C83-85			CK73GB1H103K	CHIP C	0.010UF	К		C162,163			CK73GB1H103K	CHIP C	0.010UF	К	
C86			CC73GCH1H470J	CHIP C	47PF	J		C164			CK73GB1H102K	CHIP C	1000PF	К	
C87			CK73GB1H102K	CHIP C	1000PF	К		C165			C92-0003-05	CHIP-TAN	0 47UF	25WV	
C88			C92-0633-05	CHIP-TAN	22UF	10WV		C166			CC73GCH1H080D	СНІР С	8.0PF	D	
C89-91			CK73GB1H103K	CHIP C				C167			CK73FB1E104K	CHIP C	0 10UF	к	
C92			CC73GCH1H040C	CHIP C	4.0PF	C		C168		1	CK73GB1H103K	CHIP C	0.010UF		
			CC73GCH1H120J	1				1			C92-0628-05	CHIP-TAN			1
C93				CHIP C	12PF	J		C169,170					10UF	10WV	
C94			CC73GCH1H050C	CHIP C	5.0PF	С		C171			C92-0003-05	CHIP-TAN	0.47UF	25WV	
C95			CC73GCH1H040C	CHIP C	4 0PF	С		C172,173			CK73FB1E104K	CHIP C	0.10UF	К	
C96,97			CK73GB1H103K	CHIP C	0 010UF	К		C174,175			CK73GB1H102K	CHIP C	1000PF	к	
C98			CC73GCH1H220J	CHIP C	22PF	J		C176,177			CK73FB1E104K	CHIP C	0.10UF	к	
C99			CK73GB1H103K	CHIP C	0.010UF	κ		C178,179			CK73GB1H221K	CHIP C	220PF	К	
C100			CC73GCH1H050C	CHIP C	5 OPF	С		C180			CK73FB1E104K	CHIP C	0.10UF	к	
C101			CK73FB1E223K	CHIP C	0.022UF	к		C181,182			CK73GB1H221K	CHIP C	220PF	к	
C102			CC73GCH1H020C	CHIP C	2 0PF	С	1	C183-186			CK73FB1E104K	CHIP C	0 10UF	к	1 1
C103,104			CK73GB1H103K	CHIP C	0.010UF			C187,188			CK73GB1H102K	CHIP C	1000PF	ĸ	
C105,104			C92-0589-05	CHIP-TAN	47UF	6.3WV		C189,190		1	CC73GCH1H270J	CHIP C	27PF	J	
C103,100			CK73GB1H471K	CHIP C	470PF	K.		C191,192			CK73FB1E104K	CHIP C	0 10UF	ĸ	
C100 110			047200101024		0.010115	v		C193			CC73GCH1H680J	CHIP C	68PF	J	
C108-110			CK73GB1H103K	CHIP C	0.010UF							1			
C111			CC73GCH1H220J	CHIP C	22PF	J		C194			CC73GCH1H220J	CHIP C	22PF	J	1
C112,113			CK73GB1H103K	CHIP C	0.010UF			C195			CK73GB1H102K	CHIP C	1000PF	К	
C114			CK73GB1H102K	CHIP C	1000PF	К		C196		ł	C92-0628-05	CHIP-TAN	10UF	10WV	
C115			CK73FB1E104K	CHIP C	0 10UF	К		C197			CK73GB1H102K	CHIP C	1000PF	к	
C116			CK73GB1H103K	CHIP C	0 010UF	к		C198-200			C92-0628-05	CHIP-TAN	10UF	10WV	
C117			CK73GB1H102K	CHIP C	1000PF	К	1	C201,202			CK73FB1E104K	CHIP C	0 10UF	К	1 1
C118-120			CK73GB1H103K	CHIP C	0 010UF	К		C203-205			C92-0628-05	CHIP-TAN	10UF	10WV	
C121			CC73GCH1H040C	CHIP C	4 0PF	С	1	C206			CC73GCH1H470J	CHIP C	47PF	J	
C122			CK73FB1E104K	CHIP C	0 10UF			C207			CK73GB1H471K	CHIP C	470PF	ĸ	
C123			CK73GB1H562K	CHIP C	5600PF	к		C208			CK73FB1E104K	CHIP C	0 10UF	ĸ	
C123			C92-0633-05	CHIP-TAN	22UF	10WV		C200			CK73GB1H103K	CHIP C	0 010UF		
							1					1			
C125			CC73GCH1H050C	CHIP C	5 OPF	C	1	C210			C92-0633-05	CHIP-TAN	22UF	10WV	
C126			CK73FB1E104K	CHIP C	0.10UF	K		C211			CC73GCH1H080D	CHIP C	8 OPF	D	
C127			CK73GB1H562K	CHIP C	5600PF	К		C212			CK73GB1H103K	CHIP C	0.010UF	K	
C128			CC73GCH1H040C	CHIP C	4 0PF	С		C213			CK73FB1E104K	CHIP C	0.10UF	к	
C129	1		CK73GB1C393K	CHIP C	0 039UF	К		C214			CK73GB1H102K	CHIP C	1000PF	К	
C130	1		CC73GCH1H050C	CHIP C	5 0PF	С		C215,216		1	CC73GCH1H270J	CHIP C	27PF	J	
C131	1		CK73GB1H103K	CHIP C	0 010UF			C217		1	CK73GB1H471K	CHIP C	470PF	K	
C132			CC73GCH1H040C	CHIP C	4 OPF	С		C218,219			CC73GCH1H220J	CHIP C	22PF	J	
C133			CK73GB1H103K	CHIP C	0 010UF	ĸ		C220	.		CC73GCH1H070D	CHIP C	7PF	D	
C133	1		C92-0633-05	CHIP-TAN	22UF	10WV		0220	1	1	50.0001110/00	0.00		-	
			CK73GB1H103K	CHIPC	0 010UF		I	TC1,2	{	1	C05-0393-05	CERAMIC TR			
C135								101,2	[000-0090-00	L CENAIVIIC IN	INNINGH CAP	(OF)	
C136			CC73GCH1H040C	CHIP C	4 OPF	C		CNI			F04 0400 05			C(CMD)	
C137			CK73GB1H103K	CHIP C	0 010UF	ĸ		CN1 CN2			E04-0409-05 E04-0154-05	RF COAXIAL PIN SOCKET	RECEPTACL	E(21A1R)	
C138			CK73GB1C333K	CHIP C	0 033UF	к	1	CN3-5	1		E40-5538-05	PIN ASSY			
				CHIPC	4 OPF	C		CN6				FLAT CABLE		9	
C139			CC73GCH1H040C							*	E40-5736-05	1			
C140			C92-0001-05	CHIP-C	0 1UF	35WV		CN7	1	1 Î	E04-0409-05	RF COAXIAL	HELEPIAUL	E(SIVIB)	.
C141			CC73GCH1H050C	CHIP C	5 OPF	C		051				CEDALAIO EN		EOE	
C142	1		CK73FB1E104K	CHIP C	0.10UF	К		CF1		Ľ	L72-0956-05	CERAMIC FIL		1001	1

PARTS LIST

Ref. No.	Adrress	New parts	Parts No.	Description	Destination	Ref. No.	Adrress	New parts	Parts No.		Description	Destination
CF2		*	L72-0953-05	CERAMIC FILTER CFWC450D		R1			RK73GB1J105J	CHIP R	1.0M J 1/16W	
CF3		*	L72-0956-05	CERAMIC FILTER CFWC450F		R2			RK73GB1J183J	CHIP R	18K J 1/16W	
CF4		•	L72-0953-05	CERAMIC FILTER CFWC450D		R3,4			RK73GB1J473J	CHIP R	47K J 1/16W	
						R5		1	R92-1252-05	CHIP R	0 OHM	
L1		•	L34-4523-05	AIR-CORE COIL		R6			RK73GB1J223J	CHIP R	22K J 1/16W	
.2		*	L40-1098-76	SMALL FIXED INDUCTOR(1UH)								
.3			L79-1529-05	HELICAL BLOCK 450-480MHZ		R7			RK73GB1J470J	CHIP R	47 J 1/16W	
L3 L4		*	L40-1098-76	SMALL FIXED INDUCTOR(1UH)		R8			R92-1252-05	CHIP R	0 OHM	
						R9			RK73GB1J560J	CHIP R		
L5			L40-1875-34	SMALL FIXED INDUCTOR(18NH)		R10					56 J 1/16W	
			1 40 4000 70						RK73GB1J222J	CHIP R	2 2K J 1/16W	
L6,7			L40-1098-76	SMALL FIXED INDUCTOR(1UH)	1	R11			RK73GB1J102J	CHIP R	10K J 1/16W	
L8		*	L34-4524-05	AIR-CORE COIL	1			1				
L9		*	L40-1098-76	SMALL FIXED INDUCTOR(1UH)		R12			RK73GB1J222J	CHIP R	2.2K J 1/16W	
L10		*	L34-4524-05	AIR-CORE COIL		R16,17			RK73GB1J222J	CHIP R	22K J 1/16W	
L11		*	L40-1098-76	SMALL FIXED INDUCTOR(10H)		R18,19			RK73GB1J103J	CHIP R	10K J 1/16W	
						R20			RK73FB2A100J	CHIP R	10 J 1/10W	
_12			L40-1575-34	SMALL FIXED INDUCTOR(15NH)		R21			RK73GB1J272J	CHIP R	27K J 1/16W	
_13			L40-1875-34	SMALL FIXED INDUCTOR(18NH)								
L14,15	1	+	L40-1098-76	SMALL FIXED INDUCTOR(1UH)		R22			RK73GB1J102J	CHIP R	1 0K J 1/16W	
_16			L79-1529-05	HELICAL BLOCK 450-480MHZ		R23			R92-0670-05	CHIP R	0 OHM	
.10		.	L40-1098-76	SMALL FIXED INDUCTOR(1UH)		R24			R92-1252-05	CHIP R	0 OHM	
.17			L+0-1030-/0			R25						
10	1		140 1005 01						RK73FB2A100J	CHIP R	10 J 1/10W	
.18			L40-1005-34	SMALL FIXED INDUCTOR(10UH)		R26			RK73GB1J101J	CHIP R	100 J 1/16W	
.19			L40-1575-34	SMALL FIXED INDUCTOR(15NH)		1.						
20			L40-1005-34	SMALL FIXED INDUCTOR(10UH)		R27	1		R92-0670-05	CHIP R	0 OHM	
21,22			L40-1875-34	SMALL FIXED INDUCTOR(18NH)		R29			RK73GB1J823J	CHIP R	82K J 1/16W	
23			L40-1575-34	SMALL FIXED INDUCTOR(15NH)		R30			RK73GB1J101J	CHIP R	100 J 1/16W	
						R31			RK73GB1J470J	CHIP R	47 J 1/16W	
_24			L40-1005-34	SMALL FIXED INDUCTOR(10UH)		R32			RK73GB1J101J	CHIP R	100 J 1/16W	
25			L40-1085-34	SMALL FIXED INDUCTOR(100NH)								
26			L40-1295-34	SMALL FIXED INDUCTOR(1 2UH)		R33			R92-1252-05	CHIP R	0 OHM	
						R35				CHIP R		
.27			L34-4528-05	COIL					RK73GB1J470J		47 J 1/16W	
.28			L34-4529-05	COIL		R36			R92-1252-05	CHIP R	0 OHM	
						R37,38			R92-0670-05	CHIP R	0 OHM	
L29			L40-1005-34	SMALL FIXED INDUCTOR(10UH)		R39			RK73GB1J101J	CHIP R	100 J 1/16W	
L30			L40-3385-34	SMALL FIXED INDUCTOR(330NH)								
L31		*	L34-4528-05	COIL		R40			R92-1252-05	CHIP R	0 OHM	
.32		*	L34-4529-05	COIL	1	R41			RK73GB1J271J	CHIP R	270 J 1/16W	
L33			L40-2285-34	SMALL FIXED INDUCTOR(220NH)		R42,43			R92-1252-05	CHIP R	0 OHM	
						R44			RK73GB1J470J	CHIP R	47 J 1/16W	
L34,35			L40-1085-34	SMALL FIXED INDUCTOR(100NH)		R45			RK73GB1J103J	CHIP R	10K J 1/16W	
L36,37			L40-1005-34	SMALL FIXED INDUCTOR(100H)		1145			110/300131033	Crim II		
		*				R46					4.7K 1/10\4/	
.38			L34-4528-05	COIL					RK73GB1J472J	CHIP R	4.7K J 1/16W	
L39		1	L34-4529-05	COIL		R48			RK73GB1J470J	CHIP R	47 J 1/16W	
L40		*	L34-4528-05	COIL		R49			RK73GB1J271J	CHIP R	270 J 1/16W	
						R50,51		1	RK73GB1J222J	CHIP R	2 2K J 1/16W	
.41	1	*	L34-4529-05	COIL		R53,54			RK73GB1J103J	CHIP R	10K J 1/16W	
.42	1		L40-1005-34	SMALL FIXED INDUCTOR(10UH)		1						
43	1	*	L34-4528-05	COIL		R55			RK73GB1J222J	CHIP R	2.2K J 1/16W	
.44		*	L34-4529-05	COIL		R56			RK73GB1J223J	CHIP R	22K J 1/16W	
L45			L40-1085-34	SMALL FIXED INDUCTOR(100NH)		R57			RK73GB1J101J	CHIP R	100 J 1/16W	
-1			L-0-1003-34			R58			RK73GB1J101J	CHIP R	47K J 1/16W	
•0			1 40 4005 04	CNAME EXCED INDUCTOR/40100								
L46	1		L40-1005-34	SMALL FIXED INDUCTOR(10UH)		R59,60		1	RK73GB1J221J	CHIP R	220 J 1/16W	
_47	1		L40-1085-34	SMALL FIXED INDUCTOR(100NH)			1					
L48	1		L40-1005-34	SMALL FIXED INDUCTOR(10UH)		R61			RK73GB1J472J	CHIP R	47K J 1/16W	
49,50	1		L40-1875-34	SMALL FIXED INDUCTOR(18NH)		R62			R92-1252-05	CHIP R	0 OHM	
51	1		L40-3985-34	SMALL FIXED INDUCTOR(390NH)		R63			RK73GB1J184J	CHIP R	180K J 1/16W	
						R64		1	RK73GB1J101J	CHIP R	100 J 1/16W	
52,53		*	L34-4530-05	COIL 455KHZ		R65		1	RK73GB1J102J	CHIP R	10K J 1/16W	
.54			L40-3985-34	SMALL FIXED INDUCTOR(390NH)				1				
.55			L40-6875-34	SMALL FIXED INDUCTOR(68NH)		R66		1	RK73GB1J103J	CHIP R	10K J 1/16W	
_56			L40-1075-34	SMALL FIXED INDUCTOR(10NH)		R67,68		1	RK73GB1J821J	CHIP R	820 J 1/16W	
	1				[
_57	1		L92-0131-05	FERRITE CHIP		R69,70			RK73GB1J103J	CHIP R	10K J 1/16W	
	1					R71			RK73FB2A150J	CHIP R	15 J 1/10W	
.58			L40-1575-34	SMALL FIXED INDUCTOR(15NH)		R72			RK73GB1J100J	CHIP R	10 J 1/16W	
X1		+	L77-1753-05	CRYSTAL RESONATOR(72 6MHZ)		R73,74		1	RK73GB1J331J	CHIP R	330 J 1/16W	
(F1	1	*	L71-0510-05	MCF (7.5K)		R75			R92-1252-05	CHIP R	0 OHM	
KF2	1	+	L71-0510-05	MCF (3 75K)		R76	1		RK73GB1J182J	CHIP R	18K J 1/16W	
KF2 KF3	1		L71-0511-05	MCF (375K) MCF (73.05MHZ 8 5K)		R77	1		RK73GB1J182J RK73GB1J470J	CHIP R		
									1			
XF4		1 *	L71-0528-05	MCF (73.05MHZ 4.25K)		R78	1	1	RK73GB1J103J	CHIP R	10K J 1/16W	

PARTS LIST

Ref. No.	Adrress	New parts	Parts No.		Descripti	on		Destination	Ref. No.	Adrress	New parts	Parts No.		Descrip	otion	1	Destination
		par 13	DK720D1 1102 I		1.0K		1/10\1/				purto		0.000				-
R79	1		RK73GB1J102J	CHIP R	1 OK		1/16W	1	R140			RK73GB1J103J	CHIP R	10K		1/16W	
R80			RK73GB1J122J	CHIP R	1 2K		1/16W		R141			RK73GB1J221J	CHIP R	220		1/16W	
R81			RK73GB1J103J	CHIP R	10K		1/16W		R142			RK73GB1J100J	CHIP R	10	J	1/16W	
R82			RK73FB2A220J	CHIP R	22	J	1/10W	1	R143			RK73GB1J680J	CHIP R	68		1/16W	
R83			R92-1252-05	CHIP R	0 OHM				R144,145			RK73GB1J101J	CHIP R	100	J	1/16W	
R84			RK73GB1J103J	CHIP R	10K	J	1/16W		R146			RK73GB1J221J	CHIP R	220	J	1/16W	
R85			RK73GB1J182J	CHIP R	1.8K	J	1/16W	1	R147,148			RK73GB1J560J	CHIP R	56	J	1/16W	
R86			RK73GB1J391J	CHIP R	390	J	1/16W	1	R149,150			RK73GB1J154J	CHIP R	150K	J	1/16W	
R87			RK73GB1J101J	CHIP R	100	J	1/16W		R151			RK73GB1J222J	CHIP R	2 2K	J	1/16W	
R88			RK73GB1J223J	CHIP R	22K	J	1/16W		R152,153			RK73GB1J103J	CHIP R	10K	J	1/16W	
R89			RK73GB1J103J	CHIP R	10K	J	1/16W		R154,155			RK73GB1J223J	CHIP R	22K	J	1/16W	
R90			RK73GB1J681J	CHIP R	680	J	1/16W	1	R156,157			RK73GB1J332J	CHIP R	3.3K	J	1/16W	
R91			RK73GB1J101J	CHIP R	100	J	1/16W		R158			RK73GB1J222J	CHIP R	2 2K	J	1/16W	
R92			RK73GB1J681J	CHIP R	680	J	1/16W		R159			RK73GB1J272J	CHIP R	2 7K	J	1/16W	
R93			RK73GB1J680J	CHIP R	68	J	1/16W		R160			RK73GB1J222J	CHIP R	2 2K	J	1/16W	
R94			RK73GB1J101J	CHIP R	100	J	1/16W		R161			RK73GB1J272J	CHIP R	2.7K	J	1/16W	
R95 .			RK73GB1J152J	CHIP R	1.5K	J	1/16W		R162			RK73GB1J153J	CHIP R	15K	J	1/16W	
R96			RK73GB1J470J	CHIP R	47	J	1/16W		R163			RK73GB1J123J	CHIP R	12K		1/16W	
R97			RK73FB2A220J	CHIP R	22	J	1/10W		R164,165			RK73GB1J473J	CHIP R	47K		1/16W	
R98			RK73GB1J680J	CHIP R	68		1/16W		R166			RK73GB1J474J	CHIP R	470K		1/16W	
R99			RK73GB1J152J	CHIP R	1 5K	J	1/16W		R167			RK73GB1J224J	CHIP R	220K	1	1/16W	
R100			RK73GB1J470J	CHIP R	47		1/16W		R168			RK73GB1J224J	CHIP R	120K		1/16W	
R101			RK73GB1J100J	CHIP R	10		1/16W	1 1	R169			RK73GB1J124J	CHIP R	120K		1/16W	
R102			RK73GB1J680J	CHIP R	68		1/16W		R170			RK73GB1J124J	CHIP R	120K		1/16W	
R103			RK73GB1J101J	CHIP R	100		1/16W		R171,172			RK73GB1J124J	CHIP R	120K 100K		1/16W	
R104			RK73GB1J100J	CHIP R	10	I	1/16W		D170 174			DK700D1 1100 I	CUID D	1.01/		1/10/04	
R105			RK73GB1J680J	CHIP R	68		1/16W		R173,174			RK73GB1J103J	CHIP R	10K		1/16W	
			RK73GB1J222J	CHIP R			1/16W		R175			RK73GB1J224J	CHIP R	220K		1/16W	
R106 R107			RK73GB1J222J RK73GB1J564J	CHIPR	2.2K 560K		1/16W	1	R176-178			RK73GB1J104J	CHIP R	100K		1/16W	
R108			RK73GB1J304J	CHIP R	47K		1/16W		R179 R180,181			R92-0670-05 RK73GB1J102J	CHIP R CHIP R	0 OHM 1 OK		1/16W	
B100			DK70001 1000 I		224		1 (10) 11										
R109			RK73GB1J223J	CHIP R	22K		1/16W		R182			R92-0670-05	CHIP R	0 OHM			
R110			RK73GB1J101J	CHIP R	100		1/16W		R183			RK73GB1J560J	CHIP R	56		1/16W	
R111			RK73GB1J222J	CHIP R	2 2K		1/16W		R184			RK73GB1J102J	CHIP R	1 OK		1/16W	
R112			RK73GB1J223J	CHIP R	22K		1/16W		R185			RK73GB1J180J	CHIP R	18		1/16W	
R113			RK73GB1J103J	CHIP R	10K	J	1/16W		R186			RK73GB1J102J	CHIP R	1 OK	J	1/16W	
R114			RK73GB1J394J	CHIP R	390K		1/16W		R187			RK73GB1J180J	CHIP R	18		1/16W	
R115,116			RK73GB1J222J	CHIP R	2 2K		1/16W		R188-191	ļ		R92-1252-05	CHIP R	0 OHM			
R117			RK73GB1J101J	CHIP R	100		1/16W		R193			RK73FB2A220J	CHIP R	22	J	1/10W	
R118			RK73GB1J104J	CHIP R	100K		1/16W		R194			RK73GB1J224J	CHIP R	220K	J	1/16W	
R119			RK73GB1J393J	CHIP R	39K	J	1/16W		D1			1SS355	DIODE				
R120			R92-0679-05	CHIP R	0 OHM				D2-4			1SV283	VARIABLE		CE D	IODE	
R121	1		RK73GB1J104J	CHIP R	100K	J	1/16W		D2-4			1SV283	VARIABLE				
R122	1	1	RK73GB1J101J	CHIP R	100		1/16W		D9	1		1SV283	VARIABLE				
R123	1		RK73GB1J681J	CHIP R	680		1/16W		D10			DAN235K	DIODE	2010 AU	JUJ		
R124			RK73GB1J223J	CHIP R	22K		1/16W		010			DHINZOOK	DIODE				
R125			RK73GB1J103J	CHIP R	10K	J	1/16W		D11			DAN202U	DIODE				
R126		1	RK73GB1J183J	CHIP R	18K		1/16W		IC1			SA7025DK					
R127		1	RK73GB1J681J	CHIP R	680		1/16W		IC1	1			IC (PLL SYS		001	. =\/\	
R128		1	RK73GB1J680J	CHIP R	68		1/16W		IC3	1		NJM78L05UA BU4094BCFV	IC (VOLTAG				
R129			RK73GB1J152J	CHIP R	1 5K		1/16W		IC4			TA7808S	IC (8bit SHI IC (REGULA		15012	HEN)	
R130	1		RK73GB1J101J	CHIP R	100	J.	1/16W		IC5	1		NJM2904E	IC (OP AMF	X2)			
R131	1		RK73GB1J470J	CHIP R	47		1/16W		IC6			BU4053BCF	IC (AUDIO S	SM/1			
R132	1	1	RK73GB1J103J	CHIP R	10K		1/16W		IC7,8		*	TA31137FN	IC (IF IC)	2441			
R133	1		RK73GB1J680J	CHIP R	68		1/16W		IC7,8 IC9	1		M62364FP					
R134	1		RK73GB1J152J	CHIP R	1 5K		1/16W		IC10			AT2408N10SI2 5			11.41		
									IC10 IC11,12			NJM4558E	IC (8kbit SE IC (0P AMF		/IVI}		
R135		1	RK73GB1J103J	CHIP R	10K		1/16W		1			l					
R136		1	RK73GB1J470J	CHIP R	47		1/16W		IC13			NJM78L08UA	IC (VOLTAG	E REGULAT	OR/ ·	+8V)	
R137		1	RK73GB1J100J	CHIP R	10		1/16W		IC14			NJM2904E	IC (OP AMF	X2)			-
	1	1	RK73GB1J680J	CHIP R	68	.1	1/16W	1 I	IC15	1	1 I	LMX1511TMX	IC (PLL FRE	NIENICY SV	(NITH		
R138 R139			RK73GB1J223J	CHIP R	22K		1/16W	1	1013				TICTUL	2011/01/01	INTEL	COIZENI	

PARTS LIST

RX UNIT (X55-3040-10)

Ref. No.	Adrress	New parts	Parts No.	Description	Destination	Ref. No.	Adrress	New parts	Parts No.		Descript	ion	Destination
IC17			NJM78L08UA	IC (VOLTAGE REGULATOR/ +8	0	C33			CK73GB1H471K	CHIP C	470PF	к	
IC18			TC4S81F	IC (UNLOCK COMPALETER)		C34			CK73GB1H103K	CHIP C	0 010UF	К	
IC19			TC74HC14AF	IC (SCHMITT INVERTER)		C35,36			CC73GCH1H040C	CHIP C	4.0PF	С	
						C37			CK73GB1H471K	CHIP C	470PF	K	
Q1			2SC3357	TRANSISTOR		C38			CC73GCH1H050C	CHIP C	5 OPF	С	
Q3			2SC3356	TRANSISTOR									
Q5	1		2SC3357	TRANSISTOR		C39	1		CK73GB1H471K	CHIP C	470PF	К	
Q6			2SC4226(R24)	TRANSISTOR		C40		l l	C92-0633-05	CHIP-TAN	22UF	10WV	
Q7			2SC3357	TRANSISTOR		C41			CK73FB1E104K	CHIP C	0 10UF	К	
						C42			CK73GB1H103K	CHIP C	0 010UF	К	
Q8,9			2SK508NV(K53)	FET		C43			CC73GCH1H040C	CHIP C	4.0PF	С	
Q10	(2SC3722K(S)	TRANSISTOR		1							
Q12			2SC3722K(S)	TRANSISTOR		C44			CC73GCH1H020C	CHIP C	2.0PF	С	
Q13			DTC114EUA	DIGITAL TRANSISTOR		C45			C92-0633-05	CHIP-TAN	22UF	10WV	
Q14			2SC4226(R24)	TRANSISTOR		C46]		CK73FB1E104K	CHIP C	0 10UF	К	
						C47			CK73GB1H103K	CHIP C	0 010UF	К	
Q15			2SC4215(Y)	TRANSISTOR		C48			CK73GB1H471K	CHIP C	470PF	К	
Q16			2SB1386(R)	TRANSISTOR			1						
017			2SC3722K(S)	TRANSISTOR		C49	1		CC73GCH1H020C	CHIP C	2.0PF	С	
Q18,19	1		DTC114EUA	DIGITAL TRANSISTOR		C50			CK73GB1H471K	CHIP C	470PF	K	
Q20			2SB1386(R)	TRANSISTOR		C51	1		CC73GCH1H100D	CHIP C	10PF	D	
	1					C52	1		CK73GB1H102K	CHIP C	1000PF	K	
021			2SK508NV(K52)	FET		C53-55	1		CK73GB1H471K	CHIP C	470PF	K	
022			DTC114EUA	DIGITAL TRANSISTOR			1			-			
023			2SC4215(Y)	TRANSISTOR		C56	1		CC73GCH1H070D	CHIP C	7 0PF	D	
024,25		l	2SC3357	TRANSISTOR		C57			C92-0560-05	CHIP-TAN	10UF	6.3WV	
026			2SC4081(R)	TRANSISTOR		C58-60			CK73GB1H471K	CHIP C	470PF	K	
						C61			CK73GB1H102K	CHIP C	1000PF	К	
027			2SC4215(Y)	TRANSISTOR		C62,63			CK73GB1H471K	CHIP C	470PF	к	
028			2SC4081(R)	TRANSISTOR									
029	1		DTC114EUA	DIGITAL TRANSISTOR		C64			CC73GCH1H151J	CHIP C	150PF	J	
Q30			2SC4215(Y)	TRANSISTOR		C65			CC73GCH1H101J	CHIP C	100PF	J	
Q31,32		!	2SC3357	TRANSISTOR		C66			CK73GB1H102K	CHIP C	1000PF	ĸ	
						C67			CK73GB1H471K	CHIP C	470PF	K	
Q33		1	2SC4215(Y)	TRANSISTOR		C100	ľ	1	CC73GCH1H070D	CHIP C	7.0PF	D	
Q34,35			2SJ106(GR)	FET								-	
Q36-38			DTC114EUA	DIGITAL TRANSISTOR		C101			CK73GB1H103K	CHIP C	0 010UF	к	
						C102			C92-0502-05	CHIP-TAN	0 33UF		
TH1,2	1		157-302-65801	THERMISTOR		C103,104	1		CK73GB1H103K	CHIP C	0 010UF		
,2			10, 002 00001			C105			CK73GB1H102K	CHIP C	1000PF		
A1		*	W02-1940-05	DBM		C106			CK73GB1H471K	CHIP C	470PF	ĸ	
<u> </u>	1	L		X56-3030-10)									
C1,2	Т	r	CK73GB1H102K	CHIP C 1000PF K		C107 C108,109			C92-0606-05 CK73GB1H102K	CHIP-TAN CHIP C	4 7UF 1000PF	10WV	
			CK73GB1H471K	CHIP C 470PF K		C100,103			CK73GB1H102K	CHIP C			
C3,4 C5,6	1		CC73FCH1H070B	CHIPC 470PF K		C110			C92-0001-05	CHIP-C	0 010UF 0 1UF		
C5,6 C7		*	CC73FCH1H070B	CHIP C 7 UPP B		C112			CS2-0001-05 CK73GB1H102K	CHIP-C			1
C8			CC73FCH1H120G	CHIPC 12PP G		6112				Unir U	1000PF	N	
00			GG73FGH1H040D	UNIFG 4UFF B		C113			CC73GCH1H020C	CHIP C	2 OPF	С	
C9	1		CC73FCH1H100D	CHIP C 10PF D		C113		1	CK73GB1H103K	CHIP C	2 UPF 0 010UF		
C9 C10			CC73FCH1H100D CC73FCH1H050B	CHIP C TUPP D CHIP C 5 OPF B		C114 C116			CK73GB1H103K CK73GB1H103K	CHIP C	0 0100F 0 010UF		
C10 C11	1		CK73GB1E103K	CHIPC 5 OPF B		C116 C117			CC73GCH1H101J	CHIP C	100PF		
C12	1		CC73GCH1H0R5B	CHIPC 00100F K		C117 C118-120			CK73GB1H102K	CHIP C			
C12 C13			CK73GB1H471K	CHIP C U SPF B		0110-120			UK730D IMTUZK		1000PF	r.	
			5.0000 mm/ fix	I NOT K		C121			CK73FB1E104K	CHIP C	0 10UF	К	
C14			CC73GCH1H0R5B	CHIP C 0 5PF B		C122			CC73GCH1H101J	CHIP C		J	
C15,16			CK73GB1H102K	CHIP C 1000PF K		C122	1		CK73GB1H103K	CHIP C	0 010UF		
C17,18			CC73FCH1H070D	CHIP C 7.0PF D		C127			C92-0589-05	CHIP-TAN	47UF	6 3WV	
C19-21			CK73GB1H102K	CHIP C 1000PF K		C128			CK73FB1E104K	CHIP C	0 10UF		
C22			CC73FCH1H090D	CHIP C 9 OPF D			1				0.001		
						C130			CK73GB1H103K	CHIP C	0 010UF	К	
C23			CC73FCH1H070D	CHIP C 7 OPF D		C131			C92-0628-05	CHIP-TAN	10UF	10WV	
224			CC73FCH1H110J	CHIP C 11PF J		C133			C92-0628-05	CHIP-TAN	10UF	10WV	
C25			CC73FCH1H080D	CHIP C 8.0PF D		C135,136	1	1	C92-0628-05	CHIP-TAN	10UF	10WV	
	1		CK73GB1H102K	CHIPC 1000PF K		C137	1		CC73GCH1H100D	CHIP C	10PF	D	
C26	1		CC73GCH1H0R5B	CHIP C 0 5PF B		1	1						
			1			C138		1	C92-0628-05	CHIP-TAN	10UF	10WV	
C26 C27,28													
		*	C92-0728-05	ELECTROLYTIC 470UH 16V	v								
C27,28		*	C92-0728-05 CK73GB1H471K	ELECTROLYTIC 470UH 16V CHIP C 470PF K	v	C139			C92-0004-05	CHIP-TAN	1 OUF	16WV	
C27,28 C29		*	C92-0728-05 CK73GB1H471K CK73GB1H103K	ELECTROLYTIC 470UH 16V CHIP C 470PF K CHIP C 0 010UF K	v							16WV K	

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PARTS LIST

TX UNIT (X56-3030-10)

Ref. No.	Adrress	New parts	Parts No.		Descriptio	on	Destination	Ref. No.	Adrress	New parts	Parts No.	Description	Destination
C144			CK73GB1H102K	CHIP C	1000PF	К		C302			CK73GB1H471K	CHIP C 470PF K	
C145			CK73GB1H103K	CHIP C	0.010UF	К		C303			CK73GB1H102K	CHIP C 1000PF K	
C146			CK73GB1H471K	CHIP C	470PF	К		C304			CK73GB1H471K	CHIP C 470PF K	
C147			CK73FB1E104K	CHIP C	0.10UF	К		C305			CK73GB1E103K	CHIPC 0.010UF K	
C168			C92-0633-05	CHIP-TAN	22UF	10WV		C307			CM73F2H020C	CHIP C 2 OPF C	
C169			CK73GB1H103K	CHIP C	0.010UF	к		C308			CK73GB1H471K	CHIP C 470PF K	
C170	[CK73FB1E104K	CHIP C		K		C309	ļ	l	CK73GB1E103K	CHIPC 0 010UF K	
C173	Ì		CK73GB1H103K	CHIP C	0.010UF			C310			CK73FB1E104K	CHIPC 0.10UF K	
C174			C92-0589-05	CHIP-TAN	47UF	6.3WV		C311			C92-0729-05	ELECTROLYTIC 330UH 25WV	
C175			CK73FB1E104K	CHIP C		К		C312			CM73F2H080D	CHIP C 8 OPF D	
C201			C92-0003-05	CHIP-TAN	0.47UF	25WV		C313			CK73GB1H102K	CHIP C 1000PF K	
C202-204	1		CK73GB1H103K	CHIP C	0.010UF	К		C315			CM73F2H100D	CHIP C 10PF D	
C205			C92-0633-05	CHIP-TAN	22UF	10WV		C316			CM73F2H080D	CHIPC 8 OPF D	
C206,207			CC73GCH1H271J	CHIP C	270PF	J		C317		*	C92-0729-05	ELECTROLYTIC 330UH 25WV	
C208			C92-0606-05	CHIP-TAN	4.7UF	10WV		C318			CK73GB1H562K	CHIP C 5600PF K	
C209			C92-0519-05	CHIP-TAN	1.0UF	25WV		C319-322			CK73GB1H471K	CHIP C 470PF K	
C210			CC73GCH1H151J	CHIP C		J		C323-328			CK73GB1H102K	CHIP C 1000PF K	
C211			CK73GB1H103K	CHIP C	0.010UF			C329			CK73GB1H103K	CHIPC 0.010UF K	
C212			CC73GCH1H151J	CHIP C		J		C330,331			CK73GB1H102K	CHIP C 1000PF K	
C213			CK73GB1H103K	CHIP C	0 010UF			C332,333			CK73FB1E104K	CHIP C 0 10UF K	
C214			CC73GCH1H100D	CHIP C	10PF	D		C334			C92-0003-05	CHIP-TAN 0 47UF 25WV	
C215,216 C217			CK73GB1H103K CC73GCH1H560J	CHIP C CHIP C	0.010UF 56PF	K J		TC1,2			C05-0393-05	CERAMIC TRIMMER CAP(8P)	
C218			CK73GB1H103K	CHIP C	0.010UF			101,2					
C219			CC73GCH1H820J	CHIP C	82PF	J		CN1		*	E04-0409-05	RF COAXIAL RECEPTACLE(SMB)	
								CN2			E40-5758-05	FLAT CABLE CONNECTOR 12P	
C220			CK73GB1H103K	CHIP C	0.010UF	К		CN3			E40-5736-05	FLAT CABLE CONNECTOR 26P	
C221-224			CC73GCH1H271J	CHIP C	270PF	J		CN101,102		*	E04-0409-05	RF COAXIAL RECEPTACLE(SMB)	
C231,232			CK73GB1H471K	CHIP C	470PF	К		CN103,104			E40-5538-05	PIN ASSY	
C233			CC73GCH1H080D	CHIP C	8 OPF	D							
C234			CC73GCH1H150J	CHIP C	15PF	J		CN301 CN302		*	E04-0408-05 E40-5758-05	RF COAXIAL RECEPTACLE(SMB) FLAT CABLE CONNECTOR 12P	
C235			CC73GCH1H080D	CHIP C	8.0PF	D		CN304,305			E40-5538-05	PIN ASSY	
C235			C92-0004-05	CHIP-TAN	1.0UF	16WV		CN304,303			E23-0902-05	TERMINAL	
C230 C237-239			CK73GB1H102K	CHIP-TAIN CHIP C	1000PF	K		CN308			E04-0408-05	RF COAXIAL RECEPTACLE(SMB)	
C237-235 C240			C92-0519-05	CHIP-TAN	1.0UF	25WV		011300			L04-0400-03	NF CUAXIAL RECEFTACLE(SIVID)	
C240 C241			CK73GB1H103K	CHIP-TAIN CHIP C	0.000F			CN502		•	E40-5783-05	PIN ASSY	
C242			C92-0606-05	CHIP-TAN	4.7UF	10WV		J402			J13-0071-05	FUSE HOLDER	
C243			CC73GCH1H560J	CHIP C	56PF	J							
C244			C92-0003-05	CHIP-TAN	0.47UF			L1,2			L40-1095-34	SMALL FIXED INDUCTOR(1UH)	
C245			CK73GB1H103K	CHIP C	0 010UF			L3			L40-1071-36	SMALL FIXED INDUCTOR(10NH)	
C246,247			CC73GCH1H151J	CHIP C	150PF	J		L5,6		1	L34-4545-05	AIR-CORE COIL	
C240			017000111001		0.040115	V.		L7-10			L40-1095-34	SMALL FIXED INDUCTOR(10H)	
C248			CK73GB1H103K	CHIP C	0 010UF			L11,12			L40-1571-36	SMALL FIXED INDUCTOR(15NH)	
C249			CC73GCH1H100D	CHIP C	10PF	D		L13			140 1071 00	CMALL EVED INDUCTOR/40404	
C250-252 C253	1		CK73GB1H103K CC73GCH1H560J	CHIP C CHIP C	0.010UF			L13 L14			L40-1071-36 L40-1571-36	SMALL FIXED INDUCTOR(10NH)	
C253 C254			CC73GCH1H271J	CHIPC	56PF 270PF	J		L14 L15			L40-1571-36 L40-1271-36	SMALL FIXED INDUCTOR(15NH)	
6204			00/300H1H2/1J	Unir L	27085	J		L15 L18,19			L40-1271-36 L40-1095-34	SMALL FIXED INDUCTOR(12NH)	
C255			C92-0633-05	CHIP-TAN	22UF	10WV		L101,102			L40-1095-34 L40-1095-34	SMALL FIXED INDUCTOR(10H) SMALL FIXED INDUCTOR(10H)	
C255 C256			CK73GB1H103K	CHIP C	0.010UF			2.37,102					
C250 C257			CC73GCH1H271J	CHIPC		J		L103			L40-3385-34	SMALL FIXED INDUCTOR(330NH)	
C258			CK73FB1E104K	CHIP C	0.10UF			L103 L104,105			L40-3385-34 L40-1015-34	SMALL FIXED INDUCTOR(3000H)	
C259			CK73GB1H103K	CHIP C	0.1001 0.010UF			L201			L40-1013-34 L40-4785-34	SMALL FIXED INDUCTOR(1000H)	
								L202			L40-1095-34	SMALL FIXED INDUCTOR(10H)	
C260,261			CC73GCH1H050C	CHIP C		C		L203			L40-1595-34	SMALL FIXED INDUCTOR(1.5UH)	
C262			CK73GB1H102K	CHIP C	1000PF			100			140 40:5 0		
C263			CK73GB1H471K	CHIP C	470PF	ĸ		L204			L40-1015-34	SMALL FIXED INDUCTOR(100UH)	
C264,265			CC73GCH1H560J	CHIP C	56PF	J		L205,206			L40-4785-34	SMALL FIXED INDUCTOR(470NH)	
C266,267			CK73GB1E223K	CHIP C	0 022UF	К		L207			L40-1015-34	SMALL FIXED INDUCTOR(100UH)	
								L210			L40-1095-34	SMALL FIXED INDUCTOR(1UH)	
C268			C92-0628-05	CHIP-TAN		10WV		L240			L40-1015-34	SMALL FIXED INDUCTOR(100UH)	
C269,270			CK73GB1E103K	CHIP C	0 010UF			1					
C271			CK73GB1H471K	CHIP C	470PF	К		L241,242			L40-1095-34	SMALL FIXED INDUCTOR(1UH)	-
C272			CC73GCH1H470J C92-0729-05	CHIP C	47PF	J		L243			L40-4785-34	SMALL FIXED INDUCTOR(470NH)	
C301				ELECTROLYTI		25WV		L244,245			L40-1871-36	SMALL FIXED INDUCTOR(18NH)	

PARTS LIST

TX UNIT (X56-3030-10)

	Adrress	New parts	Parts No.		Descript	ion		Destination	Ref. No.	Adrress	New parts	Parts No.		Descript	ion		Destination
L301			L34-1113-05	AIR-CORE C					R100			RK73GB1J103J	CHIP R	10K		1/16W	
L302,303			L34-1039-05	AIR-CORE C	OIL				R101			RK73GB1J105J	CHIP R	1 0M	J	1/16W	
L304			L79-0558-05	FILTER					R102			RK73GB1J473J	CHIP R	47K	J	1/16W	
L305		*	L34-4523-05	AIR-CORE C	OIL				R103,104			R92-0670-05	CHIP R	0 OHM			
V101		*	177 1795 05	тсхо		120			R105			RK73GB1J332J	CHIP R	3 3K	J	1/16W	
X101 X201,202		*	L77-1735-05 L77-1748-05	CRYSTAL RE	SUNATOR		MHZ) 2MHZ)		R106			RK73GB1J101J	CHIP R	100	1	1/16W	
XF210		*	L71-0529-05	MCF(20MHz		(15	21111121		R107			RK73GB1J471J	CHIP R	470		1/16W	
71210			271 0323 00		- 21()				R108			RK73GB1J183J	CHIP R	18K		1/16W	
R1,2			R92-1252-05	CHIP R	0 OHM				R109-111			R92-0670-05	CHIP R	0 OHM	-	.,	
R3,4			RK73GB1J473J	CHIP R	47K	J	1/16W		R112			RK73GB1J183J	CHIP R	18K	J	1/16W	
R5,6			RK73GB1J104J	CHIP R	100K	J	1/16W										
R7			RK73GB1J683J	CHIP R	68K	J	1/16W		R113			RK73GB1J102J	CHIP R	1 OK	J	1/16W	
R8			RK73GB1J473J	CHIP R	47K	J	1/16W		R114			RK73GB1J222J	CHIP R	2 2K	J	1/16W	
									R115			RK73GB1J101J	CHIP R	100	J	1/16W	
R9			RK73GB1J101J	CHIP R	100	J	1/16W		R116			RK73GB1J472J	CHIP R	4 7K	J	1/16W	
R10,11			R92-1252-05	CHIP R	0 OHM				R117			RK73GB1J101J	CHIP R	100	J	1/16W	
R12			RK73GB1J101J	CHIP R	100		1/16W										
R13			RK73GB1J181J	CHIP R	180		1/16W		R118,119			RK73GB1J103J	CHIP R	10K		1/16W	
R14			RK73GB1J103J	CHIP R	10K	J	1/16W		R120			RK73GB1J102J	CHIP R	1.0K		1/16W	
									R121,122			RK73GB1J101J	CHIP R	100		1/16W	
R15			RK73GB1J331J	CHIP R	330		1/16W		R123			RK73GB1J103J	CHIP R	10K		1/16W	1
R16			RK73GB1J103J RK73GB1J473J	CHIP R	10K		1/16W		R124			RK73GB1J102J	CHIP R	1 OK	J	1/16W	
R17				CHIP R	47K		1/16W	1	R129			DK70CD1 1100 I	CHIP R	1.01/		1/10/04	
R18 R19			RK73GB1J103J	CHIP R CHIP R	10K 47		1/16W 1/16W		R129 R130			RK73GB1J102J R92-0679-05	CHIP R	1 OK 0 OHM	J	1/16W	
n19			RK73GB1J470J	Unirn	47	J	1/10**		R130			RK73GB1J102J	CHIP R	1 OK		1/16W	
R20			RK73GB1J103J	CHIP R	10K	ı	1/16W	1	R132			RK73GB1J124J	CHIP R	120K		1/16W	
R21			RK73GB1J470J	CHIP R	47		1/16W		R133			RK73GB1J104J	CHIP R	100K		1/16W	
R22			RK73GB1J103J	CHIP R	10K		1/16W		11133			1107505151045		1001	J	1/1044	
R23			RK73GB1J183J	CHIP R	18K		1/16W		R134-136			R92-0679-05	CHIP R	0 OHM			
R24 -			RK73GB1J101J	CHIP R	100		1/16W		R137			RK73GB1J103J	CHIP R	10K	J	1/16W	
						-	.,		R138			RK73GB1J124J	CHIP R	120K		1/16W	
R25			RK73GB1J472J	CHIP R	4 7K	J	1/16W		R139			RK73GB1J104J	CHIP R	100K		1/16W	
R26			RK73GB1J220J	CHIP R	22	J	1/16W		R140			RK73GB1J474J	CHIP R	470K	J	1/16W	
R27			RK73GB1J101J	CHIP R	100	J	1/16W										
R28			RK73GB1J103J	CHIP R	10K	J	1/16W		R141			RK73GB1J102J	CHIP R	1 OK	J	1/16W	
R29			RK73GB1J183J	CHIP R	18K	J	1/16 W		R142			RK73GB1J104J	CHIP R	100K	J	1/16W	
									R143	1		RK73GB1J473J	CHIP R	47K	J	1/16W	
R30			RK73GB1J103J	CHIP R	10K		1/16W		R144			RK73GB1J334J	CHIP R	330K		1/16W	
R31			RK73GB1J101J	CHIP R	100		1/16W		R145			RK73GB1J102J	CHIP R	1 OK	J	1/16W	
R32			RK73GB1J471J	CHIP R	470		1/16W										
R33			RK73GB1J103J	CHIP R	10K		1/16W		R146			RK73GB1J101J	CHIP R	100		1/16W	
R34			RK73GB1J222J	CHIP R	2 2K	J	1/16W		R147			RK73GB1J102J	CHIP R	1 OK		1/16W	
Dor			DK70001 1100 1	CUID D	1.01/		1/1014		R148			RK73GB1J101J	CHIP R	100	J	1/16W	
R35 R36			RK73GB1J182J RK73GB1J472J	CHIP R CHIP R	1 8K 4 7K		1/16W 1/16W		R201,202 R203			R92-1252-05 RK73GB1J223J	CHIP R CHIP R	0 OHM	1	1/16\//	
R30 R37			RK73GB1J472J	CHIPR	47K 12K		1/16W		n203			NK/3GB1J223J	Unir n	22K	J	1/16W	
R38			RK73GB1J122J	CHIP R	8 2K		1/16W		R204			RK73GB1J103J	CHIP R	10K		1/16W	
R39			RK73GB1J471J	CHIP R	470		1/16W		R204			RK73GB1J102J	CHIP R	1 OK		1/16W	
						5	.,		R210			RK73GB1J224J	CHIP R	220K		1/16W	
R40			RK73GB1J101J	CHIP R	100	J	1/16W		R211			RK73GB1J103J	CHIP R	10K		1/16W	
R41			RK73GB1J152J	CHIP R	1 5K		1/16W		R212			RK73GB1J223J	CHIP R	22K		1/16W	
R42			RK73GB1J471J	CHIP R	470		1/16W								-		
R43			RK73GB1J221J	CHIP R	220		1/16W		R213			RK73GB1J821J	CHIP R	820	J	1/16W	
R44	1		RK73GB1J681J	CHIP R	680		1/16W		R214			RK73GB1J101J	CHIP R	100		1/16W	
									R215			RK73GB1J103J	CHIP R	10K		1/16W	
R45			RK73GB1J100J	CHIP R	10	J	1/16W		R216			RK73GB1J223J	CHIP R	22K	J	1/16W	
R46			RK73FB2A470J	CHIP R	47		1/10W		R217,218	1]	RK73GB1J471J	CHIP R	470	J	1/16W	
R47			RK73GB1J222J	CHIP R	2 2K		1/16W										
R48			RK73GB1J103J	CHIP R	10K		1/16W		R219			RK73GB1J103J	CHIP R	10K		1/16W	
R49	1		RK73GB1J123J	CHIP R	12K	J	1/16W		R222			RK73GB1J103J	CHIP R	10K		1/16W	
DEA			DK7000111711	0.000	170				R223	1		RK73GB1J153J	CHIP R	15K		1/16W	
R50			RK73GB1J471J	CHIP R	470		1/16W		R226			RK73GB1J474J	CHIP R	470K		1/16W	
R51,52			RK73GB1J101J	CHIP R	100		1/16W		R227			RK73GB1J473J	CHIP R	47K	J	1/16W	
R53	1		RK73GB1J120J	CHIP R	12 22K		1/16W		P220					1001		1/1014/	
R54 R55			RK73GB1J223J	CHIP R	22K		1/16W		R228			RK73GB1J104J	CHIP R	100K		1/16W	
D 22	1		RK73GB1J101J	CHIP R	100	J	1/16W		R240 R241	1		RK73GB1J102J	CHIP R	1 OK 10K		1/16W	
100				1				1	nz41	ł	1	RK73GB1J103J	CHIP R	10K	J	1/16W	1
R56			RK73GB1J473J	CHIP R	47K	I.	1/16W		R242	1		R92-1252-05	CHIP R	0 OHM		-	

TKR-830 TKR-830

TSIJ STAA

Ts⊅⊃⊃

Color*

1st number		103 = 0.01µF
Jadmun braz		$4\mu 100.0 = 400001 = 501$
neilqitluM		7001 = 101
		100 = 10pF
2 0 = 22pF	2	7q1 = 010
		• Capacitor value

7 200	∓ 520	∓J50	09∓	∓ 30	ງ ູ/ພdd
٦	К	ſ	н	Ð	2nd Word

	2)°\mqq0ð	∓ 0∠⊅-	= HT84C)) : əlqmex∃
7009	∓ 520	7120	09∓	Ŧ 30	ງ ູ/wdd
Г	К	ſ	н	Ð	2nd Word

(Aq0r	nedt	ssəŋ	

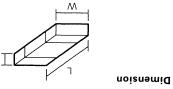
∓ 5	LŦ	5.0±	70.25	ſ.0±	(∃q)
Ð	F	D	С	В	əpoʻ

					GΓ + ~ 0Γ − ∃μΓ.
Ŧ	9.0±	∓ 0.25	r.0±	(∃q)	10hF-10~+50
	D	С	В	aboJ	ерор

	00	00	60	01	-
-	0.8	6.3	0.C	4.0	g
Λ	К	ſ	Н	Ð	

(anoticedec	(Chip	noiznamiQ	

T	Μ	٦	Dimension code				
0.S nedt seeJ	G.0 ± 0.5	9.0 ± 8.8	Empty				
0.S nedt iseal	3.2 ± 0.4	4.5 ± 0.5	A				
0.5 nedt seel	5.0 ± 0.3	G.0 ± ∂.4	В				
25.1 nedt seeJ	1.25± 0.2	9.0 ± 8.4	Э				
G.F nedt seel	5 [.] 2∓ 0 [.] 3	3.2 ± 0.4	D				
25.1 nedt seeJ	2.0 ± ∂.1	3.0 ± 0.2	Э				
25.1 nsht seel	1.25±0.2	2.0 ± 0.3	E				
0.1 nedt seel	Q.8 ± 0.2	2.0 ± ∂.1	Ð				



Dimension (Chip resistor)						
Ţ	M	٦	Dimension code			
0.1	2.0 ± ∂.1	3.2 ± 0.2	E			
0.1	1.25 ± 0.2	2.0 ± 0.3	E			
 1.0±∂.0	0.8±0.2	2.0±∂.1	Ð			

 0.00000000	90.
agettew	6ui1

eging wettage								
egetteW	əpoƏ	egetteW	əpoƏ	90etteW	əpoƏ			
M۱	₹	M9/L	5C	M91/1	٢١			
5M	3D	M4/1	SE	MOI/I	2V			
		MZ/L	НZ	M8/1	58			
		AA7/1	117	110/1	07			

(01-0606-36X) TINU X	C
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1			u	· u			
	• Temperature o	tneisit					
	3 = Temp. coeffic	:			NOT = 1	eranc	
	sqeh2 = S	$\Lambda = G$ $\Omega = \Lambda$					
	1 = Type cera	electro	h∕tic, et	.ofe	A = Voltage		
Destination		L	5	3_7	<u>S</u>	_9	
(26-3030-10)	ROTIDA9AD	၁၁	. 9 ⊅	HI HI	520	ſ	

Π	T	S	Я	d	٦	С	1st Word
teloiV	Blue	Green	WolleY	Orange	рәЯ	Black	Color*
092-	-410	-330	-520	-120	08-	0	ე°∖mqq

(Iq01	nsdt	(More	Tolerance	•

C D C 1 K W X Z b No code	əpo၂							
±0.28 ±0.5 ±2 ±5 ±10 ±20 +40 +80 +100 More than 10μF -1	(%)							
Γ – 3μ7.4 nsthan 4.7μ8								

6 = Tolerance

eniter agetloV = 4

eniter seetloV .

-	0008	0089	2000	4000	3120	2500	2000	0091	1520	1000	3
-	008	630	200	400	312	520	200	09l	152	00L	5
32	08	63	20	40	31.5	55	50	91	15.5	ΟL	l
-	0.8	6.3	0. 0	4.0	3.15	2.5	0.2	9. l	1.25	0.1	0
											1st word
Λ	К	ſ	Н	Ð	F	Э	D	С	В	¥	Sud word

erotice capacitors

6 = Value 7 = Tolerance	(Chip) (B, F)	
$c = \sqrt{c}$		
 3 = Dimension 4 = Temp. coefficient 	СКУЗЕЕЛНООО Z	(X3)
9qpf = 1 Pqpe S = 2	(Chip) (CH, RH, UJ, SL)	
	J 5 3 4 2 6 1	
Refer to the table above.		(X3)

SROTSISER

					(B B)	(aid2)	
L	9	g	4	3	2	L	
 1	000	5 B				Ш В К	(×∃)
			(uc	arbo	0r (C	teiser o	id) •

(Cuib) (b'L)

B SC 000 1 B 1 1 8 (X3) • Carbon resistor (Normal type)

2 = Shape 9 = Rating wattage ∋qγT = Γ J 5 3 4 2 8 L

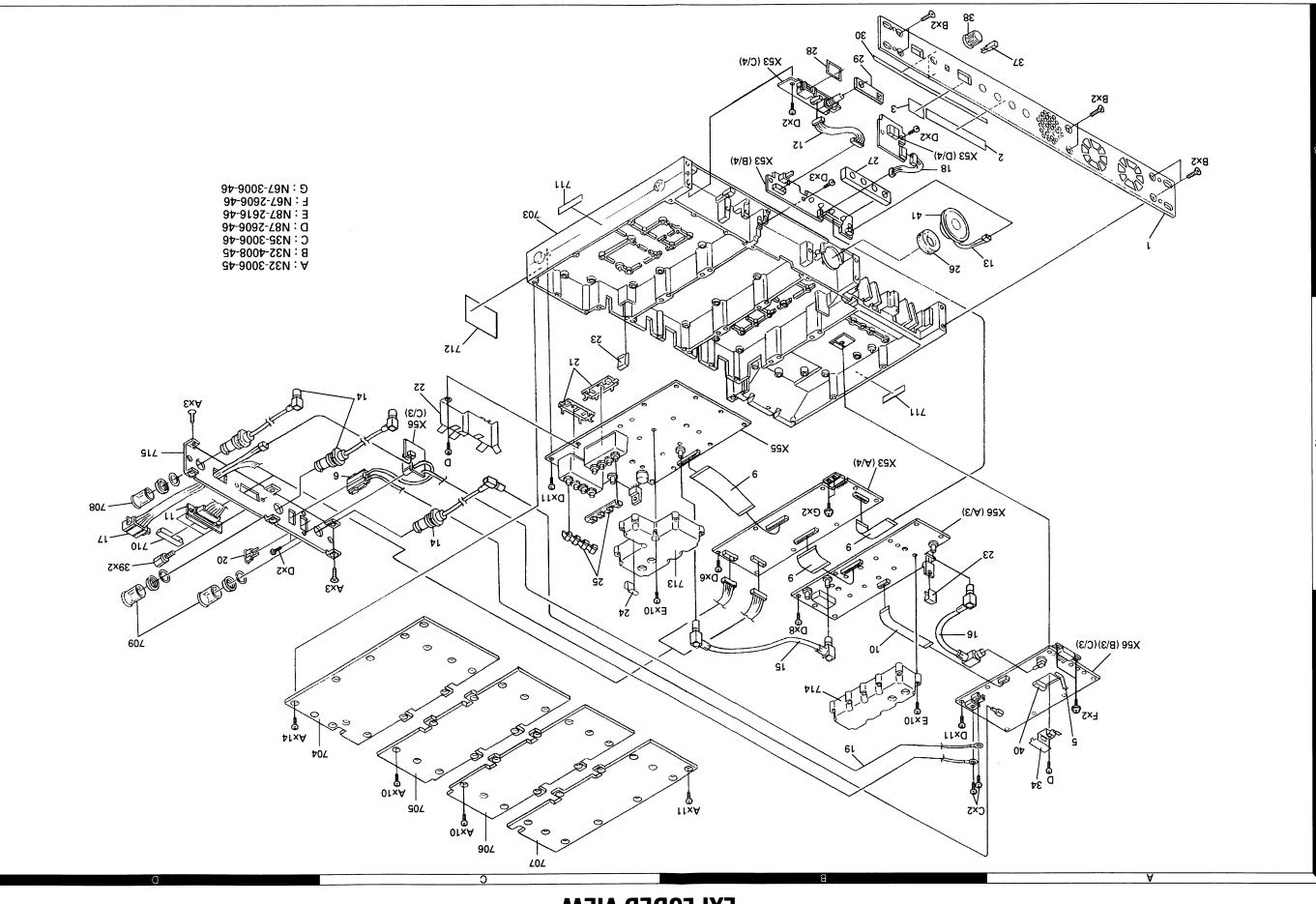
4 = Temp. coefficient 7 = Tolerance noiznemid = cəuleV = ∂

Destina	Description	Parts No.	WeW Strisg	ssennbA	.oN . 1 9Я		Destination	
	DIODE	ramem20			D302			
	DIODE	SA88M2H			9060			
	adid Rotriaav	HZMDC075-02 HZMDC075-02	*		D310'311 D308			
						•		
	IC (REGULATOR) IC (VOLTAGE REGULATOR/ +8V)	28087AT AU80J87MLN			ICS ICI			
		M62364FP			1C3 701			
	IC (8bit SHIFT/STORE REGISTER)	RU4094BCFV			10100			
	(90 AMA) (90 AMA)	FIO237AT			00101			
	IC (PLL FREQUENCY SYNTHESIZER)	XMTIIBIXMJ			10101			
	IC (VOLTAGE REGULATOR/ +5V) IC (OP AMP X2)	AU20187MLN AU20187MLN			10102 10103			
	IC (8kpit SERIAL EEPROM)	2.21201 N8042TA			90101			
	(V8+ \ROTAJUƏƏR ƏƏATJOV) JI	AU80187MLN			80101			
	IC (OP AMP X2)	AJM2904E			IC103			
	(VC+ \ROTADER EGULATON) II (VOLTADER 2001)	AUZ0187MLN			01120			
	IC (OF AMP X2) IC (OP AMP X2)	NJW2904E SPJ052DK			ICS03 ICS01'S0S			
	(SX ROTARA9MOD) DI	MEOGZMLN			IC204			
	IC (UNLOCK COMPALETER)	TC4S81F			IC205			
	IC (LOMER MODULE)	M02UA-2	*		IC301			
	IC (OP AMP X2)	AJM2904E			IC305'303			
	TET	SSK208NA(K2S)			ζ, rD			
	ROTSISNART	SSK1837			02't			
	FET Transistor	52C4556(H54) 52K1854			09 02			
	ROTZIZNART	SSC3722K(S)			40			
	Rotsisnart jatiðig	AU34110TO			80			
	REPORT AND A DESIGNARY	52C4556(B54)			6D			
	ROTZIZIANARI JATIĐIO	DTC144EUA	+		010			
	rotsisuart Rotsisuart jatiðig	2281386(R) DTC114EUA			015 011			
		WORLDON			תוד			
	ROTZIZIAAAT	52C4093(B27)			010 013			
	ROT2I2NART Tət	SZK30S(A) SZC3322			012 017			
	Rotsiznart jatijio	AU3411ATO			91D			
	ROTZIZNART	(RD,Y)8881A22			۲ID			
	ROTZIZNART JATIĐIO	DTC143EUA	*		81D			
	ROTSISNART	52C4512(A)			2010Z			
	ROTZIZNART ROTZIZNART	52C4556(H54) 52C4512(A)			2010 9010			
	ROTSISNART JATIĐIO	AU3411ATO			0110			
		VII36110			0			
	rotsismart jadior Fet	DTC114EUA 2SK1824			0115'113 0111			
	Rotsiznart jatijio	AU3411ATO			¢11⊄			
	ROTZIZIZIAART ROTZIZIZIAART	52C4512(X) 52C4512(X)			0301 303 0112			
	ROTSIZNART	52C4512(A)			202'102D			l
	ROTZIZNART JATIĐIO	DTC114EUA			0303			
	RDISISNART Fet	52K1854 52C4556(H54)			0306 0302			
	REI RANSISNART	52C4512(A)			0540'541 0700			
	ROTZIZNART	22C4081(B)			0301			ĺ
	ROTSIZNART JATIÐIQ	DTC144EUA	*		0302			
	ROTZIZNART JATIĐIO	DTC144EUA	*		0304'302			
	THERMISTOR	121-203-23000			105HT			
			1					l

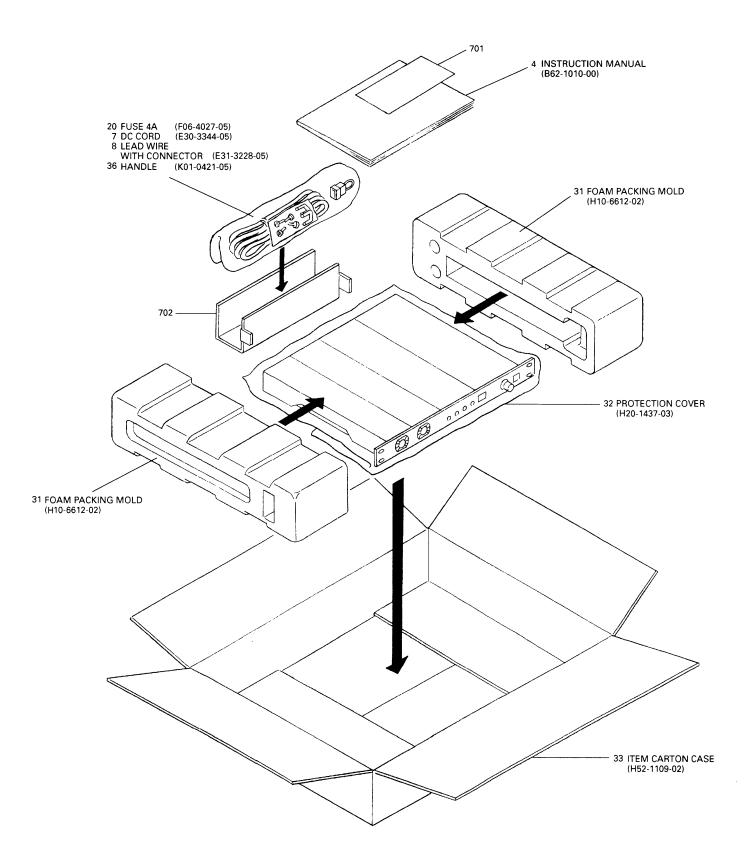
TSIJ STAA9

0304 125222 0100E 0303 1252322 0100E 0303 1252322 20100E 0303 1252322 20100E 0305 1252322 20100E 0506 125232 20100E 0513 125232 0100E 0514 125322 0100E 0513 125328 0100E 0111 125328 0100E 0101 125328 0100E 0101 125328 0100E 0101 125328 0100E 0102 125328 0100E 0103 125328 0100E 0114 125329 0100E 0124 125329 0100E 0133 4K326817027 0Hb H 347 125329 0100E 12532 12532 12533 0Hb H 12533 12532 12533 0Hb H 12533 12533 12533 0Hb H 12533 12		Wði\r L Wði\r L	100 10K	CHIP R CHIP R	68171017 1017 1037			8246 R245
0000 0000 0000 0000 0000 0000 0000 00				1				
D000 D000 D000 D000 D000 D000 D000 D00		₩91/1 ſ	55K	СНЬ В	RK73GB1J223J			642A
D000 D000 D000 D000 D000 D000 D000 D00		₩91/1 ſ						
D033 EBC-WI 40KS20W RINGE RESOLUBER 0305 1232328 0000E 0303 123238 AVBIVETE CVEWOLVACE DIDDE 0500 123238 0000E 0500 123238 0000E 0501 123238 0000E 0101 123338 0000E 0101 123358 0000E 011 123358 0000E 012 123358 0000E 012 123358 0000E 012 123357 0116 13347 012 123358 0000E 13347 012 123357 0116 1337 012 123358 0000E 1347,07 013 123357 0116 137,07 1233 12337 <th>١</th> <td>W81/1 L</td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td>	١	W81/1 L						
D300 D301 EBY-WI 40KSZOW 123282 CANE RE WE WI 40KSZOW 123282 CANE RE WE	I				RK73GB1J224J			
D300 EBY-WI 40KSZOW 2000 E D301 123282 0000 E D301 123282 NPBIVERC VEVCILVACE DIODE D302 123383 123383 D303 123383 NPBIVERC VEVCILVACE DIODE D304 123383 NPBIVERC VEVCILVACE DIODE D305 123383 NVEVRE CVEVCILVACE DIODE D101 123435 DIODE D101 123435 DIODE D101 123435 DIODE D101 123435 BX306911037 D101 123435 BX306911037 D101 123435 BX306911037 B335 BX306911037 CHIB B 10K B335 BX306911037 CHIB B 10K 1,10M B335 BX306911037 CHIB B 10K 1,10M B335 BX306911037 </th <th></th> <th></th> <th>MHO 0</th> <th>СНІ В</th> <th>S0-0767-26A</th> <th></th> <th></th> <th>6928</th>			MHO 0	СНІ В	S0-0767-26A			6928
D300 EB:Y-M140KZSOM 2000 E D301 123282 NPBIEE D11'15 123282 NPBIEE D101 12332 12332 D101 12332 000E B333 HK326B11047 000E B333 HK326B11047 000E B333 HK326B11047 130K B333 HK326B11047 130K B333 HK326B11047 130K B333 HK36B11047 130K </td <th></th> <td>M91/1 r</td> <td>100K</td> <td></td> <td></td> <td></td> <td></td> <td></td>		M91/1 r	100K					
D300 EHS-WI-40KSZOW 2RIVE BIODE 0301 - IZ2362 D00E 0301 - IZ2362 D00E 0500 - MWIRWEQU2-0S AVENTER EVENTIVE DIODE 0501 IZAS33 AVENTER EVENTIVE DIODE 0501 IZAS33 AVENTER EVENTIVE DIODE 0103 IZAS33 AVENTER EVENTIVE DIODE 0103 IZAS33 AVENTER EVENTIVE DIODE 0103 IZAS33 DIODE 0103 IZAS33 DIODE 0103 IZAS33 DIODE 0103 IZAS33 DIODE 0104 IZAS33 DIODE 0133 IZAS33 DIODE 0133 IZAS33 DIODE 0134 IZAS33 DIODE 0135 IZAS33 DIODE 0134 IZAS33 DIODE 0133 IZAS33 DIODE 0134 IZAS33 DIODE 0134 IZAS33 DIODE IZAS3		W81/1 L	L1					
1000 EHS-W140KSZOW 2000E 2000E 0303 - 122328 DIODE 0304 - 1202323 ANEIRET CAPACILYACE DIODE 0305 - MINIZMEC02-03 ABILIZOH 0301 - 120.5323 ANEIRET CAPACILYACE DIODE 0101 120.532 ANEIRET CAPACILYACE DIODE 0101 120.533 ANEIRET CAPACILYACE DIODE 0101 120.533 120.533 0101 120.533 120.533 0101 120.533 000E 0101 120.533 120.533 0101 120.533 000E 0102 120.533 000E 0103 120.533 000E 0101 120.533 000E 0102 120.533 000E 0123 0000E 1.1000 </th <th></th> <th>War\r L</th> <th>¢∠0</th> <th>СНІР В</th> <th>LT4L145557471J</th> <th></th> <th>Į</th> <th></th>		War\r L	¢∠0	СНІР В	LT4L145557471J		Į	
D303 E45-WI40KSOW 20HEE VESOBEBU 0303 - 12X328 DIODE 0304 - 12X328 NAHINETE CAPACILWACE DIODE 0305 - MINIZVDC02-0S NAHINETE CAPACILWACE DIODE 0301 - MINIZVDC03-0S NAHINETE CAPACILWACE DIODE 0301 12X328 DIODE DIODE 0101 12X158 DIODE DIODE 0102 12X158 DIODE DIODE 0103 12X158 DIODE DIODE 011 12X258 MUSEPERCEVACE DIODE NEX328PERTION 84325 KK12368171037 CHIB H </th <th></th> <th></th> <th></th> <th></th> <th></th> <th></th> <th></th> <th></th>								
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D3303 E45-WI+QKSZOW 2NBGE VB20BEBU D301 - ND2Y181 SEREE DIODE D301 - ND2Y181 SEREE DIODE D301 - NWIRKDC02-05 NPHIBEIE CVPACILYACE DIODE D50103 - H2NBBR2 DIOOE D103 - JAX583 DIOOE D103 - JAX583 DIOOE D104 12AX58 DIOOE D105 - JAX583 DIOOE D101 12AX58 DIOOE DIOOE D101 12AX58 DIOOE DIOOE D102 - JAX582 DIOOE D102 - JAX583 DIOOE D102 - JAX583 DIOOE D14 LXX583 AVBIPEIE CVACILYACE DIODE D24040 DIOOE - JAX584 D33 KX3268171037 CHIB H JX<0K		M91/1 L	32K		8673681J223J			
D3333 EHS-WI-QKSZOW RINGE RESOUBER D301 - 128282 DIOGE D301 - IDX'ISI SERENDIDE D5240 - IZS282 DIOGE D5201 - IZS283 MURRETE CAPCLEVICE DIODE D103 - IZS282 DIODE D103 - IZS282 DIODE D104 - IZS282 DIODE D103 - IZS282 DIODE D104 - IZS282 DIODE D105 - IZS282 DIODE D106 - IZS282 DIODE B325 BK236B-11037 CHIE B J B326 BK236B-11037 CHIE B J B325 BK236B-11037 CHIE B J B326 BK236B-11	ļ		100K	СНІЬ В	RK73GB1J104J			
D303 EEX-W14DKSZOW 2NBGE B820BEE D304 . 122322 DIODE D304 . 122322 NERE DIODE D304 . 127233 NEWBRE CEVECLENCE DIODE D305 . . 127233 NEWBRE CEVECLENCE DIODE D304 . .		W81/1 L	JOK	CHIP R	RK73GB1J103J			
D303 EEX-WIDDE 12322 CHIGE B820BEE 123232 D304 - ID2410 2000 2000 D305 - ID2410 2000 2000 D304 - ID2410 2000 2000 D305 - MINIRWDC02-05 AVEINET C CHACLENICE DIODE 2000 2000 D304 - ID24283 AVEINET C CHACLENICE DIODE 2000 D305 - 120,158 DIODE 2000 D101 120,158 DIODE 2000 0000 D101 120,158 DIODE 2000 1/10M D100 120,153 CHIB B 1/10M D100 120,153 CH		W31/1 L	\$7K	CHIP R	RK73GB1J473J			
D303 EHZ-WI4DKXSOW 2NBGE B820BEE 0305 123222 123282 DIODE 05301 128282 DIODE DIODE 05302 128282 DIODE DIODE 05303 128282 DIODE DIODE 05304 128282 DIODE DIODE 05305 128282 DIODE NEINBER CK-KCILM/CE DIODE 05305 128282 DIODE NEINBER CK-KCILM/CE DIODE 05305 128282 DIODE DIODE 0501 128232 NENBER VIADION DIODE 0510 128232 CHIB H J/J MM 0511 128282 DIODE J/J MM 0512 128237 CHIB H J/J MM 0511 128282 J/J MM J/J MM 0511 1282327 CHIB H J/J MM		W81/1 L	Я0.1	CHIP R	L2011189573A			69ZH
D303 EEZ-WI4DEX20W SUBCE BSOUBEE D303 . 125282 DIODE D240 . . MINISMDC02-02 VARIABLE CAPCITANCE DIODE D200:202 . . MINISMDC02-02 VARIABLE CAPCITANCE DIODE D200:203 . . . MINISMDC02-02 VARIABLE CAPCITANCE DIODE D201:203 D11,12 . <th></th> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td>								
D303 EHS-WI 40KSSOW RINGE RBOUBEH D304 . 122326 DIODE D305 . . MINIZWDC02-05 ARHVRE CVPACILYACE DIODE D540 . . MINIZWDC02-05 ARHVRE CVPACILYACE DIODE D5002 . . MINIZWDC02-05 ARHVRE CVPACILYACE DIODE D5003 . . MINIZWDC02-05 ARHVRE CVPACILYACE DIODE D1013 D1015 D1010 D1011 D1010 D1010 D1010E D1010E 		W31/1 L	18K	CHIP R	RK73GB1J183J			
D303 EHY.WI 40KSSOW 20/06 E 2000 E 0305 122328 DIODE DIODE 0201 - 127328 DIODE 0501 - MINIZWDC012-05 ABIMBRE CVEVCLUVCE DIODE 0502 12AS83 ABIMBRE CVEVCLUVCE DIODE 0503 12AS83 NEHVBRE CVEVLUVCE DIODE 0103 12AS83 DIODE 0104 12AS83 DIODE 0103 12AS83 DIODE 0104 12AS83 DIODE 0105 12AS83 DIODE 0104 12AS8 DIODE 0105 12AS83 DIODE 0104 12AS83 DIODE 0105 12AS83 DIODE 0106 12AS83 DIODE 0107 12AS83 DIODE 0108 12AS83 DIODE 0109 12AS83 DIODE 0109 12AS83 ABIBRE CVEVLIVACE DIODE 0109 12AIS8 DIODE <td< td=""><th></th><td>W31/1 L</td><td>410</td><td>CHIP R</td><td>RK73GB1J471J</td><td></td><td></td><td>R302</td></td<>		W31/1 L	410	CHIP R	RK73GB1J471J			R302
D303 EHY.WI 40KSSOW RHE RE WI 40KSSOW RHE RE RE WI 40KSSOW RHE RE	ļ	WOI/I L	081	CHIP R	LI81A2876739	1		B303
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D303 EHS-W140KSOW 2006E 2000E 0305 123362 DIODE DIODE 0305 123362 DIODE DIODE 0307 123362 DIODE DIODE 0307 123362 DIODE DIODE 0307 127,518 256,62 DIODE 0308 127,58 DIODE DIODE 0103 127,58 DIODE DIODE 0133 HK132GE17057 CHILB JVE 0134 HK32GE17057 CHILB JVE 0133 HK14 DIODE JVE 0134 HK32GE17057 CHILB JVE 0134 HK32GE17057 CHILB JVE 1144 <th></th> <td>W01/1 [</td> <td>081</td> <td>CHIP R</td> <td>BK73FB2A1811</td> <td></td> <td></td> <td>8305</td>		W01/1 [081	CHIP R	BK73FB2A1811			8305
D303 E45-W14DK320W 2NHEE B820BBEH D305 . D107;1[B] 2EKEH D10DE D304 . .								
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D303 EHZ-WI14DKZSOW S/HEE B820HBEH D305 - 122322 DIODE D301 - - 122322 DIODE D301 - - 127883 AVHIBET CAPACILARCE DIODE D301 - - MINIRWDC02-0S AVHIBET CAPACILARCE DIODE D301 - - MINIRWDC02-0S AVHIBET CAPACILARCE DIODE D301 - 127833 AVHIBET CAPACILARCE DIODE D103 12715 127883 DIODE D104 127158 DIODE D101 127158 DIODE D101 127158 DIODE B325 HK3268171037 CHIB H JK B321 HK3268171037 CHIB H JK B321 HK326817037 CHIB H JK B325 HK326817037		MZ/1 r	520	CHIP R	R92-1201-05			ОГЕН
B313 BKX36B11021 CHIP H J.0K J.16W B313 J.306,203 VBHBLE CPPCITANCE DIODE B314 HX36B11031 CHIP H J.16W B315 J.2V283 VBHBLE CPPCITANCE DIODE B101 J.303 CHIP H J.16W B11,125 J.2V283 DIODE B11,125 J.2S326 DIODE B11,125 J.2S328 DIODE B11,125 J.2S328 DIODE B240 J.16W J.16W B11,125 J.2S328 DIODE B240 J.16W J.16W B31 J.2S328 DIODE B32 J.4FBE CPACITANCE DIODE B33 J.16W J.16W								
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D303 EBZ-WI 1057 CHIB H J.VEE BRC328 DIODE D301 - 122322 DIODE DIODE DIODE D301 - 122328 DIODE DIODE DIODE D301 - MINIRWDC02-05 AMEINBEC CEVECITANCE DIODE DIODE D301 - 127,833 AMEINBEC CEVECITANCE DIODE DIODE D301 127,158 DIODE DIODE DIODE D101 127,158 DIODE DIODE DIODE D103 127,158 DIODE DIODE DIODE DIODE D101 127,158 DIODE DIODE <th>ļ</th> <th></th> <th></th> <th></th> <th></th> <th></th> <th></th> <th></th>	ļ							
D303 EBZ-WI 40KZSOW S/NBGE B820BBEB D301 - ND241(B) SEMEB DIODE D301 - ND241(B) SEMEB DIODE D301 - NUNIRWDC02-0S NABINALE CAPACITANCE DIODE D301 - MINIRWDC02-0S NABINALE CAPACITANCE DIODE D301 - MINIRWDC02-0S NABINALE CAPACITANCE DIODE D301 - MINIRWDC02-0S NABINALE CAPACITANCE DIODE D301 - 12AX83 NABINALE CAPACITANCE DIODE D101 12AX88 DIODE 000E D101 12AX88 DIODE 000E D101 12AX88 DIODE 000E D101 12AX88 DIODE 000E D102 12AX88 DIODE 000E B33 HK736B11031 CHIB H 47K 1/16W B320 HBK326B11031 CHIB H 47K 1/16W B33 HK326B11031 CHIB H 47K 1/16W B33 J/16W J/16W								
D303 EHZ-WI14DKZSOW 2/04E B820HBEH D305 122322 DIODE D301 - 1024'1(B) SEMEH DIODE D3040 12/0583 APHIPARE CAPACITANCE DIODE D301 - WINI2WDC02-0S APHIPARE CAPACITANCE DIODE D301-S03 12/0583 APHIPARE CAPACITANCE DIODE D103 12/0583 APHIPARE CAPACITANCE DIODE D103 12/0583 DIODE D101 12/0583 DIODE D102 12/0583 DIODE B325 KKJ36817031 CHIB H 33 B325 KKJ36817031 CHIB H J/10/M B33 KKJ36817031 CHIB H J/10/M B33 J/100 J/10/M J/10/M		M91/1 ∩	X0.1	R 41HD	C20101896/3H			GIEH
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B321 EEX-W14DK2SOM SUBGE BSOBBEH B321 - UD24/16 12/2355 DIODE D302 - UD24/16 12/2355 DIODE D301 - UD24/16 12/2355 DIODE D302 - MINISMDC075-02 VARIABLE CAPACITANCE DIODE D301 - MINISMDC075-02 VARIABLE CAPACITANCE DIODE D103 12/12S 12/2326 DIODE D103 12/12S 12/2326 DIODE D103 12/12S 12/2326 DIODE D101 12/12S 12/2326 DIODE D101 12/12S 12/2326 DIODE D101 12/12S 12/2326 DIODE D101 12/12S 12/2326 DIODE D11/17S 12/2328 DIODE 1/16/M D101 12/12S 12/2428 1/16/M D101 12/15S 12/2428 DIODE D11/17S 12/2428 DIODE 1/16/M <td< td=""><th>ļ</th><td></td><td></td><td></td><td></td><td></td><td></td><td></td></td<>	ļ							
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D303 EBZ-WI10370 CHIP H JK J/16W D301 - UD24/1(B) ZEKER DIODE 123252 D301 - UD24/1(B) ZEKER DIODE D301 - UD24/1(B) ZEKER DIODE D301 - MINISMDC075-02 VARIABLE CAPACITANCE DIODE D301 - MINISMDC075-02 VARIABLE CAPACITANCE DIODE D101 12/1/2S 13/2336 DIODE D101 12/1/2S 13/23362 DIODE D102 12/1/2S 13/23362 DIODE D101 12/1/2S 12/23262 DIODE D102 12/1/2S 12/23262 DIODE D101 12/1/2S 12/23262 DIODE D102 12/15S 12/3/283 NARIABLE CAPACITANCE DIODE D1/1/1S 12/15X 12/3/282 DIODE D1/1/1S 12/15X 12/3/282 DIODE D1/1/1S 12/15X 12/15X DIODE D1/1/1S 12/15X 12/15X					-			
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D1-6 ISV283 VERIABLE CPACITANCE DIODE D303 - UD24/0 SURGE ABSORBER D301 - UD24/128 DIODE D301 - UD24/168 SERER DIODE D301 - UD24/168 SERER DIODE D301 - MINISMDC075-02 VARIABLE CAPACITANCE DIODE D101 15/128 DIODE DIODE D103 15/128 DIODE DIODE D104 15/128 DIODE DIODE D105 12/158 DIODE DIODE D103 12/158 DIODE DIODE								1
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D204 122322 D10DE			RBBR					
				DIODE	122322			D304

EXPLODED VIEW TKR-830 TKR-830



PACKING



TERMINAL FUNCTION

CONTROL UNIT (X53-3810-10)

Connector No.	Terminal No.	Terminal name	Terminal function
	1	RA	RX Audio input (filtered)
	2	RXG	RX Audio ground
	3	DET	Detection signal input
	4	DEG	Detection signal ground
	5	SC	Noise squelch controll input
	6	RSSI	Receiving signal strength indicator input
	7	СК	Common clock output
	8	DT	Common data output
	9	RSR	Shift register enable signal
			output
	10	EVR	Electrical volume
			loadenable signal output
	11	SCL	EEPROM serial clock
			output
CN1 A/4	12	SDA	EEPROM serial data input/
	:		output
for Rxunit	13	DP	PLL data signal output
CN6	14	CP	PLL clock signal output
	15	EPR	RX main PLL strobe signal
			output
	16	LDR	RX PLL lock detector input
	17	GND	Ground
	18	CVR	RX main PLL lock voltage
	10		input
	19	NC	No connection
1	20 21	NC	No connection
	21	B B	Power supply output
	22	B	Power supply output Power supply output
	23	NC	No connection
1	24	NC	No connection
	25	NC	No connection

	4	MOD	Madulation signal output
			Modulation signal output
	2	то	Signaling signal output
	3	MIG	Microphone ground
	4	EVT	TX Elecrorical volume
			enable signal output
	5	EST	TX Sift-register strobe
			signal output
CN2 A/4	6	DT	Data signal output for
			IC3,IC4
for Txunit	7	СК	Clock signal output for
			IC3,IC4
CN3 A/3	8	NC	No connection
	9	NC	No connection
	10	SDA	EEPROM serial data input/
			output
	11	SCL	EEPROM serial clock
			output

Connector No.	Terminal No.	Terminal name	Terminal function
	12	LDT	TX main PLL lock detector
			input
	13	LDS	TX sub PLL lock detector
			input
	14	CP	TX PLL clock signal output
	15	EPT	TX main PLL strobe signal
			output
	16	DP	TX PLL data signal output
CN2 A/4	17	EXR	Exit reference detector
			input
for Txunit	18	CVT	TX main PLL lock voltage
			input
CN3 A/3	19	REV	Reverse power detector
			voltage input
	20	FWD	Forward power detector
			voltage input
	21	GND	Ground
	22	NC	No connection
	23	В	Power supply input
	24	В	Power supply input
	25	В	Power supply input
	26	PAB	Power supply input for AF
			PAIC
	1	В	Power supply voltage
		FWD	output
	2		Forward power voltage
	3	EXR	output Reference indicator signal
	3		•
	4	СVТ	output TX main PLL lock voltage
	4		
CN20	5	CVR	output RX main PLL lock voltage
CINZU	5		-
for 15pip	6	RD	output RX signal output (data &
for 15pin	0		_
TEST I/O	7	RSSI	voice) Radia signal strongth
12311/0			Radio signal strength
	8	SPO	indicator output
	9	SPO	Speaker signal output Speaker signal output
	10	SPU SPI	Speaker signal input
	11		Ground
	12	GND	Ground
	12	GND	
	13	SPG SPG	Speaker ground
	14	SPG	Speaker ground

TERMINAL FUNCTION

Connector No.	Terminal No.	Terminal name	Terminal function
NO.	1	SPO	Speaker input
		SPG	Speaker ground
	2 3		
	3	VLO	AF signal from volume
		101	
	4	VLI	AF signal for volume control
	5	GND	Ground
	6	NC	No connection
	7	SCS	
	8	HOK	Scan-SW input (No use)
	9		Hook-SW input (No use)
	-	PTT	PTT output
	10	EXR	Ext reference indicater input
	11	NC	No connection
CN200 B/4	12	NC	No connection
	13	В	Power supply input
for CONT unit	14	В	Power supply input
CN17 A/4	15	NC	No connection
	16	NC	No connection
	17	TES	TEST SW output
	18	NC	No connection
	19	NC	No connection
	20	7CS	7segment latch signal input
	21	MON	Monitor SW signal output
	22	DT	7segment data signal input
	23	СК	7segment clock signal
			input
	24	GND	Ground
	25	MI	Microphone signal output
	26	MIG	Microphone signal ground

CONTROL UNIT (X53-3810-10)

Connector	Terminal	Terminal	Terminal function
No.	No.	name	
	1	SPM	Speaker mute signal input
	2	CS5	EXT.Channel bit 5 input
	3	RXG	RX signal ground
	4	CS4	EXT.Channel bit 4 input
	5	RA	RX signal output(voice)
	6	CS3	EXT.Channel bit 3 input
	7	RD	RX signal output (data &
	· ·		voice)
	8	CS2	EXT.Channel bit 2 input
	9	TA	TX signal input (voice)
	10	CS1	EXT.Channel bit 1 input
	11	TD	TX signal input (data or signaling)
	12	I/E	INT./EXT channel control select.
CN19	13	DG	Control line's ground
for 25pin	13	TXG	TX signal ground
Dsub	14	AUX3	Auxiliary output 3 (IC9 Q7)
Dann	15	KEY	KEY signal input (no
			connection)
	17	AUX2	Auxiliary output 2 (IC9 Q6)
	18	SC	SQ control output
	19	AUX1	Auxiliary output 1 (IC9 Q5)
	20	PTT	PTT input
	21	TXD2	RS-232C output (for FPU)
	22	MON	Monitor SW input
	23	RXD2	RS-232C input (for FPU)
	24	NC	No connection
	25	NC	No connection
	26	NC	No connection
	27	NC	No connection
	28	NC	No connection
	29	NC	No connection
	30	NC	No connection
	L		L
	1	VLO	AF signal from volume
			control
	2	VLI	AF signal for volume
			control
	3	GND	Ground
	4	NC	No connection
	5	В	Power supply output
	6	GND	Ground
CN205 B/4	7	PTT	PTT input
CN301 C/4	8	MIG	Microphone signal ground
	9	MIC	Microphone signal input
	10	HOK	Hook-SW input (No use)
	11	NC	No connection
	12	NC	No connection
	13 14	NC NC	No connection No connection

TERMINAL FUNCTION

CONTROL UNIT (X53-3810-10)

Connector No.	Terminal No.	Terminal name	Terminal function
	1	GND	Ground
	2	DS	7segment data signal output
CN201	3	СК	7segment data signal output
	4	7CS	7segment latch signal output
	5	5B2	5V output for D212 & IC205
	6	5A2	5V output D213 & IC206
	1	5A2	Evinent for D012 8 10006
			5v input for D213 & IC206
	2	5B2	5V input for D212 & IC205
CN300	3	7CS	7segment latch signal input
	4	СК	7segment data signal input
	5	DS	7segment data signal input
	6	GND	Ground

CN203	1 SPG		Speaker ground				
	2	SP	Speaker signal output				

TX UNIT(X56-3030-10) A/3

Connector	Terminal	Terminal	Terminal function
No.	No.	name	
CN1		DRV OUT	TX driver signal output

	1	PAB	Power supply for AF PA IC
	2	В	Power supply input
	3	В	Power supply input
	4	В	Power supply input
CN2 A/3	5	NC	No connection
FINAL unit	6	FWD	Forward power detector
			voltage input
CN302 B/3	7	REV	Reverse power detector
			voltage input
	8	PC	Power control signal output
	9	NC	No connection
	10	GND	Ground
	11	8T	TX 8V output
	12	DB	TX 8V output(No use)

CN101	-	EXT REF IN	EXT. reference signal output, coaxial connector
CN102	-	REF OUT	RX PLL reference signal output, coaxial connector
CN103	1 2	GND FB	Ground Fused +B (power supply for fan), No use
CN104	1 2	GND FB	Ground Fused +B (power supply for fan), No use

FINAL UNIT (X56-3030-10) B/3

Connector No.	Terminal No.	Terminal name	Terminal function				
CN301	-	DRV IN	TX driver signal inpu coaxial connector				
CN304	1 2	GND FB	Ground Fused +B (power supply for fan), No use				
CN305	1 2	GND FB	Ground Fused +B (power supply for fan), No use				
CN306 CN307		+B GND	Power supply input Ground				
CN308	-	RF OUT	TX RF signal output, coaxial connector				

Connector No.	Terminal No.	Terminal name	Terminal function
CN1	-	RX IN	Receive signal input,
			coaxial connector
CN2			Use for RX helical BPF
CINZ	-	-	tuning
	·		
CN3	1	IN	Use for RX MCF tuning
	2	GND	Use for RX MCF tuning
0114	r		
CN4	1	OUT	Use for wide band MCF
		GND	tuning
	2	GND	Use for wide band MCF
			tuning
CN5	1	OUT	Use for narrow band MCF
			tuning
	2	GND	Use for narrow band MCF
			tuning
			r
CN7		REF IN	RX PLL reference signal
			input, coaxial connector

ADJUSTMENT

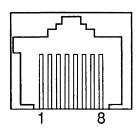
No. Test Equipment		Major Specifications
1. Standard Signal Generator	Frequency Range	340 to 520MHz.
(SSG)	Modulation	Frequency modulation and external modulation.
	Output	$0.1\mu V$ to greater than 1mV.
2. Power Meter	Input Impedance	50Ω.
	Operation Frequency	340 to 520MHz or more.
	Measurement Capability	Vicinity of 50W.
3. Deviation Meter	Frequency Range	340 to 520MHz.
4. Digital Volt Meter	Measuring Range	1 to 20V DC.
-	Accuracy	High input impedance for minimum circuit loading
5. Oscilloscope		DC through 30MHz.
6. High Sensitivity	Frequency Range	10Hz to 600MHz.
Frequency Counter	Frequency Stability	0.2ppm or less.
7. Ammeter		5A or more.
8. AF Volt Meter	Frequency Range	50Hz to 10kHz.
(AF VTVM)	Voltage Range	3mV to 3V.
9. Audio Generator (AG)	Frequency Range	50Hz to 5kHz.
· · ·	Output	0 to 1V.
10. Distortion Meter	Capability	3% or less at 1kHz.
	Input Level	50mV to 10Vrms.
11. Voltmeter	Measuring Range	10 to 1.5V DC or less.
	Input Impedance	$50k\Omega/V$ or greater.
12. 4Ω Dummy Load		Approx. 4Ω, 5W

Test Equipment Required for Alignment

The Following Parts are Required for Adjustment

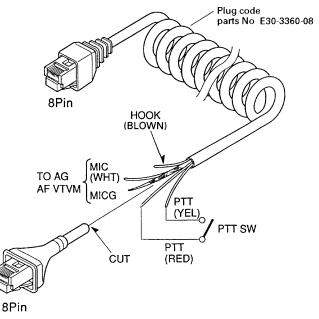
• Test cable for local microphone

MIC connector front PANEL view



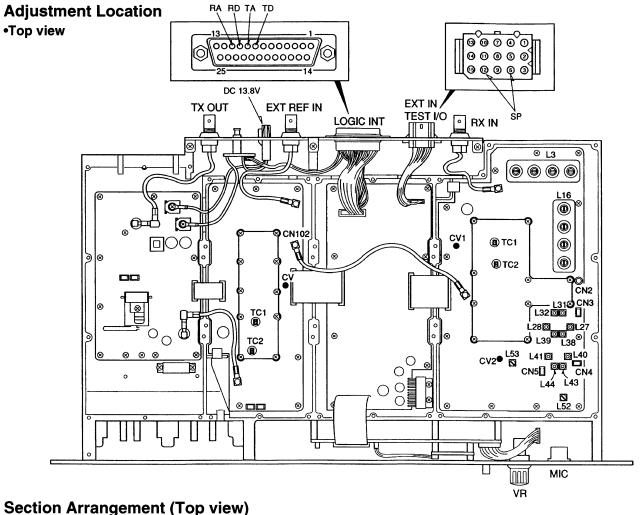
No.	Terminal name & Description
1	NC
2	+B
3	GND
4	PTT/TXD1(PC serial data from radio)
5	MIC G
6	MIC
7	HOOK/RXD1(PC serial data to radio)
8	NC

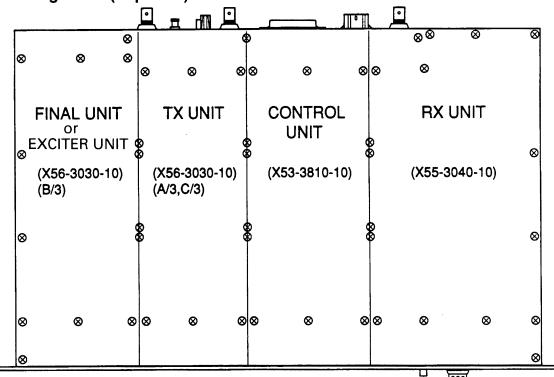
• The following test cables are recommended.



Test cable for Microphone input

ADJUSTMENT





ADJUSTMENT

TEST FREQUENCY LIST

СН	RX Frequency	TX Frequency	Beat Shift	W/N	VCO	NOTE
1	450.1000	450.0000	No	Wide	A Low	vcoA Low
2	457.6000	457.5000	No	Wide	A Center	vcoA Center
3	464.9000	464.9500	No	Wide	A High	vcoA High
4	465.1000	465.0000	No	Wide	B Low	vcoB Low
5	472.6000	472.5000	No	Wide	B Center	vcoB Center
6	479.9000	480.0000	No	Wide	B High	vcoB High
7	450.1000	450.0000	No	Narrow	A Low	vcoA Low
8	457.6000	457.5000	No	Narrow	A Center	vcoA Center
9	464.9000	464.9500	No	Narrow	A High	vcoA High
10	465.1000	465.0000	No	Narrow	B Low	vcoB Low
11	472.6000	472.5000	No	Narrow	B Center	vcoB Center
12	479.9000	480.0000	No	Narrow	B High	vcoB High
13	457.6000	457.5000	Yes	Wide	A Center	vcoA Center
14	472.6000	472.5000	Yes	Wide	B Center	vcoB Center
15	462.5000	467.5000	No	Wide	A(Hi)/B(Lo)	
16	467.5000	462.5000	No	Wide	B(Lo)/A(Hi)	
17	462.4000	462.4000	No	Wide	A High	helical filter (center) Low edge
18	467.6000	467.6000	No	Wide	B Low	helical filter (center) High edge
19	462.4000	462.4000	No	Narrow	A High	helical filter (center) Low edge
20	467.6000	467.6000	No	Narrow	B Low	helical filter (center) High edge
21	452.6000	452.6000	No	Wide	A Low	helical filter (Low) High edge
22	452.6000	452.6000	No	Narrow	A Low	helical filter (Low) High edge
23	477.4000	477.4000	No	Wide	B High	helical filter (High) Low edge
24	477.4000	477.4000	No	Narrow	B High	helical filter (High) Low edge
25	450.1000	450.0000	No	Wide	A Low	efficiency warranty Range Low edge
26	465.1000	465.0000	No	Wide	B Low	efficiency warranty Range Center
27	479.9000	480.0000	No	Wide	B High	efficiency warranty Range High edge
28	465.9750	460.9750	No	Wide	B(Lo)/A(Hi)	Repeater
29	465.9750	460.9750	No	Narrow	B(Lo)/A(Hi)	Repeater
30	465.5500	465.5500	No	Wide	B Low	
31	457.6000	472.6000	No	Narrow	A(Ce)/B(Ce)	
32	472.6000	457.6000	No	Narrow	B(Ce)/A(Ce)	

•

ADJUSTMENT

RX UNIT

		Mea	ent		Ad	Specifications/		
Item	Condition	Test equipment	Unit	Terminal	Unit	Parts	Method	Remarks
1. Setting	1) VOL : OFF 2) 13.8V External power supply 3) POWER : ON							
2. RX Lock Voltage	1) CH6 (RX B Hi) 2) CH4 (RX B Lo) 3) CH3 (RX A Hi) 4) CH1 (RX A Lo) 5) SUB (RX, ANY CHANNEL OK)	DVM	RX.U	CV1	RX.U	TC2 TC1	4.5V ADJ Check 4.5V ADJ Check Check	±0.1V 1V or more ±0.1V 1V or more 1 to 4.5V
3. BPF ADJ	Connect the TG to RX. IN, then connect CN2 to the spectrum analyzer.	TG spectrum analyzer		RX.IN CN2		L3 L16	Center the frequency you are using, then adjust it to look like the wave on page 58.	Refer to page 58
4. MCF ADJ	Connect the TG to CN3, then connect CN4 to the spectrum analyzer input. 1) CH4 (Wide)			CN3 CN4		L31 L27 L38 L40 L43	Adjust it to look like the wave or page 58.	Refer to page 58
	Connect the TG to N3, then connect CN5 to the spectrum analyzer input. 2) CH10 (Narrow)			CN3 CN5		L32 L28 L39 L41 L44	Adjust it to look like the wave or page 58.	Refer to page 58
5. Discre ADJ	Connect the SSG to RX.IN 1) CH4 (Wide) MOD : 1kHz DEV : 3kHz LEVEL : -53dBm	SSG AFVM		EXT.SP		L52	Adjust for maximum	
	2) CH10 (narrow) MOD : 1kHz DEV : 1.5kHz LEVEL : -53dBm					L53		
6. Sensitivity check	 Connect the SSG to RX.IN, then select the channel that the user will use (Wide) MOD : 1kHz DEV : 3kHz LEVEL : -113dBm Connect the SSG to RX.IN, then select the channel that the user will use (narrow) MOD : 1kHz DEV : 1.5kHz LEVEL : -113dBm 	SSG Audio,Ana		RX.IN EXT.SP			Check	12dB SINAD or more

ADJUSTMENT

RX UNIT

		Mea	ent		Ad	justment	Specifications/	
Item	Condition	Test equipment	Unit	Terminal	Unit	Parts	Method	Remarks
7. Analog squelch	1) Connect the SSG to RX.IN, then select the channel that the user will use (Wide) MOD : 1kHz DEV : 3kHz LEVEL : 3dB below to 12dB SINAD level	SSG Audio,Ana VTVM oscilloscope	RX.U	RX.IN EXT.SP 4Ω Load	RX.U		PC ADJ Adjust to point of opening squelch	
	2) Connect the SSG to RX.IN, then select the channel that the user will use (narrow) MOD : 1kHz DEV : 1.5kHz LEVEL : 3dB below to 12dB SINAD level							
8. RSSI squelch	1) Connect the SSG to RX.IN, then select the channel that the user will use (Wide) MOD : 1kHz DEV : 3kHz LEVEL : 3dB below to 12dB SINAD level							
	 2) Connect the SSG to RX.IN, then select the channel that the user will use (narrow) MOD : 1kHz DEV : 1.5kHz LEVEL : 3dB below to 12dB SINAD level 							
9. RX S/N	1) Connect the SSG to RX.IN, then select the channel that the user will use (Wide) MOD : 1kHz DEV : 3kHz LEVEL : -53dBm						Check	-53dB or less
	 2) Connect the SSG to RX.IN, then select the channel that the user will use (narrow) MOD : 1kHz DEV : 1.5kHz LEVEL : -53dBm 							- 47dB or less
10. RD OUTPUT Level	1) Connect the SSG to RX.IN, then select the channel that the user will use (Wide) MOD : 1kHz DEV : 3kHz LEVEL : -53dBm	SSG DVM		RX.IN D-sub RD Terminal (pin 10) 600Ω Load			PC ADJ 80mV	±3mV
	2) Connect the SSG to RX.IN, then select the channel that the user will use (narrow) MOD : 1kHz DEV : 1.5kHz LEVEL : -53dBm							

ADJUSTMENT

RX UNIT

		Measurement			Adjustment			Specifications/
Item	Condition	Test equipment	Unit	Terminal	Unit	Parts	Method	Remarks
11. RA OUTPUT Level	1) Connect the SSG to RX.IN, then select the channel that the user will use (Wide) MOD : 1kHz DEV : 3kHz LEVEL : -53dBm	SSG DVM		RX.IN D-sub RA Terminal (pin 11)			PC ADJ 400mV	±20mV
	2) Connect the SSG to RX.IN, then select the channel that the user will use (narrow) MOD : 1kHz DEV : 1.5kHz LEVEL : -53dBm			600Ω Load				

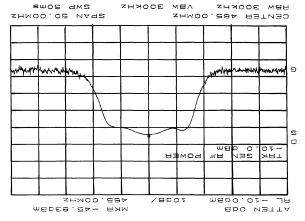
TX UNIT

		Mea	surem	ent		Ad	justment	Specifications/	
Item	Condition	Test equipment	Unit	Terminal	Unit	Parts	Method	Remarks	
12. TX LOCK Voltage	1) CH3 (TX A Hi) 2) CH1 (TX A Lo) 3) CH6 (TX B Hi) 4) CH4 (TX B Lo)	DVM	TX.U A/3	CV		TC1 TC2	4.5V ADJ Check 4.5V Check	±0.1V 1V or more ±0.1V 1V or more	
13. RX Ref check	Connect a frequency counter to CN102, then measure the frequency. 1) CH2	f.counter		CN102			Check	19.2MHz±1.0ppm	
14. EXT. Ref check	 Connect a frequency counter to CN102, then measure the frequency. Connect a SSG to EXT.REF IN. 1) CH2 LEVEL : 10MHz	f.counter SSG					Check	19.2MHz	
15. TX. Power	Measure the power level at TX.OUT. 1) CH1 (Lo) 2) CH4 (Center) 3) CH6 (Hi)	POWER meter		TX.OUT			PC ADJ 5.0W	±0.1W	
16. Max.DEV (Wide)	1) CH1 (VCO-A LO) 2) CH2 (VCO-A center) 3) CH3 (VCO-A Hi) 4) CH4 (VCO-B Lo) 5) CH5 (VCO-B center) 6) CH6 (VCO-B Hi) MOD : 1kHz LEVEL : 50mV (Terminal load)	MOD.ANA	TX.U B/3				PC ADJ 4.1kHz	±0.2kHz	
Max.DEV (narrow)	 CH7 (VCO-A LO) CH8 (VCO-A center) CH9 (VCO-A Hi) CH10 (VCO-B.Lo) CH11 (VCO-B center) CH12 (VCO-B Hi) MOD : 1kHz LEVEL : 50mV (Terminal load) 						PC ADJ 1.7kHz	±0.1kHz	

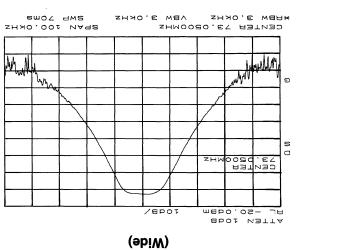
TKR-830 TKR-830

TNAMTZULDA

BPF-wave



MCF-wave



Specifications/	tnemteui	pΑ		Measurement			
Remarks	bodîeM	stheq	tinU	Terminal	tinU	tse tneme	
1.5kHz±0.25kHz	Сһеск			τυο.χτ	U.XT	ANA,	
ZHXI:0∓ZHXS7.0	урөсү				E/3	edoos	
	PC ADJ				U.XT £\A		
	Make the demodula- tion waves into square waves.				~~~		
Ossilloscope							
DC range							
	PC ADJ						
zH≯30.0±	гня∂7.0						
	PC ADJ						
zНяг.0±	г Н≯∂.↑						
±0.05kHz	РС АDJ						
-52dB or less	Сһеск						

of 465,000 MHz Example : The wave will look like this when using a frequency

хнуо.е мау снуо.е маяж

/8POT

(Warrow)

CENTER 73.05000MHz

MM

CENTER CENTER

RL -20.04Bm Aboi Natta

89

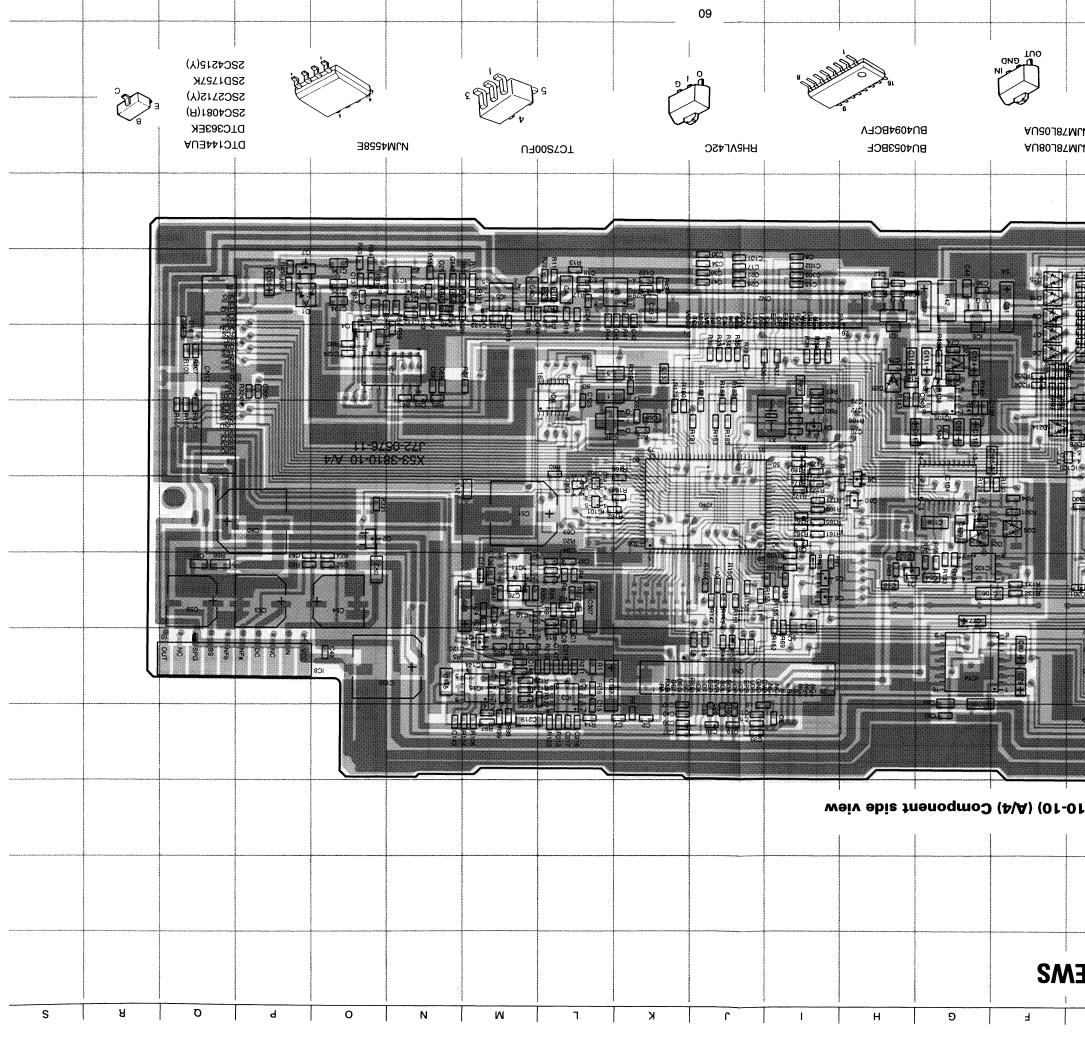
2440 20.00kHz 5440 50.00kHz

haythay

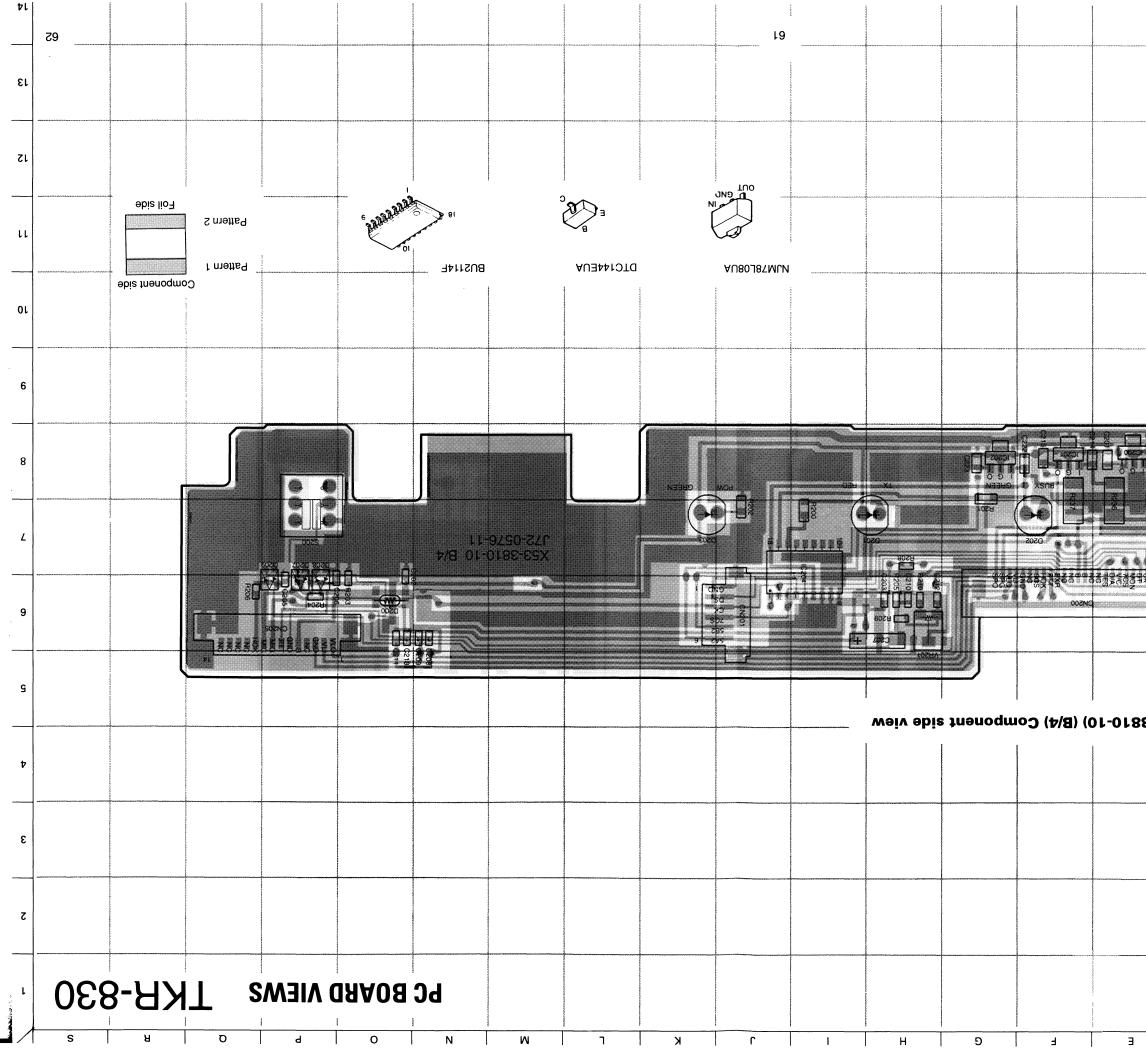
TNAMTZULDA

TINU XT

Tern	tinU	tramojupa	Condition	mətl
' XL	U.XT	MOD,ANA	1) CH2 (VCO-A center)	17. MIC,
).XT	B/3	ANA, COM Oscilloscope	1) CH2 (VCO-B center) 2) CH5 (VCO-B center)	SENCE
	0/2	adoseoiiioso		(ebiW)
			LEVEL : 3mV (Terminal load)	()
			1) CH8 (VCO-A center)	MIC'
			2) CH11 (VCO-B center)	SENCE
			ZHAF : DOM	(narrow)
			LEVEL : 3mV (Terminal load)	
	U.XT		1) CH2 (VCO-A center)	18. DQT
	£/A		2) CH5 (VCO-B center)	Balance
			(องธพ อาธups) รH0ट : 1.อA	(əbiW)
			dus-G ent otni qq&.0 heent : J3V3J	
			TD terminal (pin 8)	
			1) CH8 (VCO-A center)	DQT
			2) CH11 (VCO-B center)	Balance
			(evave vave (sequere vave) sH03 : 1.DA	(narrow)
			LEVEL : Insert 0.5pg into the D-sub D-sub (Angle 2)	
			TD terminal (pin 8)	
			1) CH2 (VCO-A center)	9. Signaling
			2) CH5 (VCO-B center) A CH2 (100Hz (Sine wave)	(Wide) DEV
			AG.f : 1001 (Sine wave) LEVEL : Insert 0.5pp into the D-sub	
			TEVEE: moor or opp moor of opp 2	
			1) CH8 (VCO-A center)	 BriliangiS
			2) CH11 (VCO-B center)	DEA
			(ever enic) zH03 : 1.DA	(narrow)
			LEVEL : Insert 0.5pp into the D-sub	
			(8 niq) lanimət OT	
			1) CH4 (Center)	20. Line Input
			(9vsw eni2) stkt: 1.0A	DEA
			dus-O ərt otni Vm041 tiəsnl : J3V3L	(əbiW)
			(9 niq) Isnimət AT	
			2) CH10 (Center)	1ndul ənil
			Aug Cott of a line wave)	(DEA
			dus-G ett of in Vm04f thesnl : JBV5L (9 dig) legimet AT	(narrow)
			(9 nig) Taterninal (pin 9)	
			1) CH2 (VCO-A center)	N/S .XT.15
			2) CH5 (VCO-B center)	(əbiW)
			AG: OFF	
			1) CH8 (VCO-A center)	N/S XL
			2) CH11 (VCO-B center)	(narrow)
			AG : OFF	



				******			69	<i>v</i> .
	əbis lio							٤L
		ern 2	Patte		8F	D214		
	ningung anno-				9 <u>E</u>	D35		
					ΞS	D31		
ſN	L	L nie	Patte		2E	D30		21
ſN	ebis tnenoc	lmoJ			4E H6	D58 D58		01
			1		96	D38		
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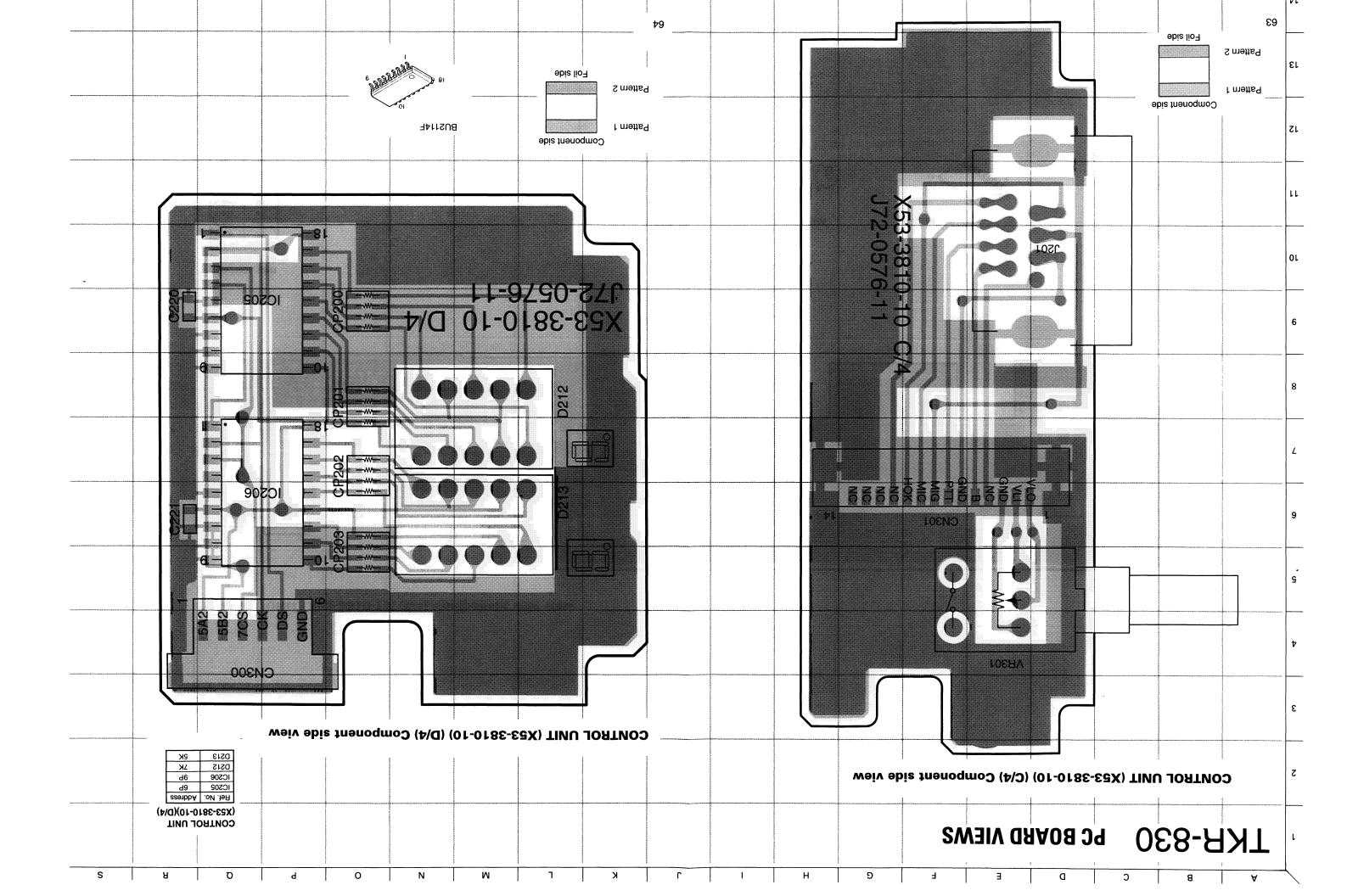


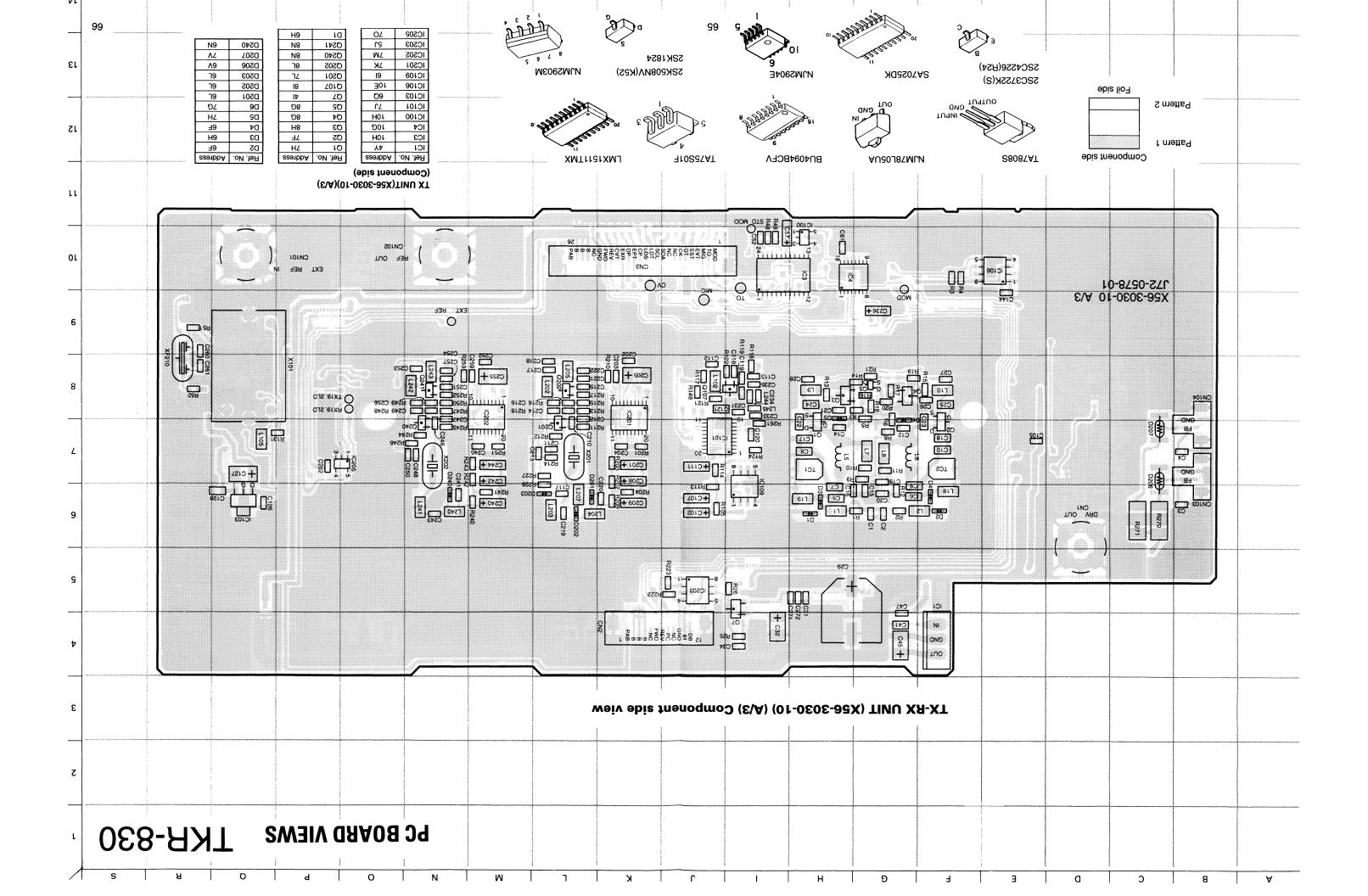
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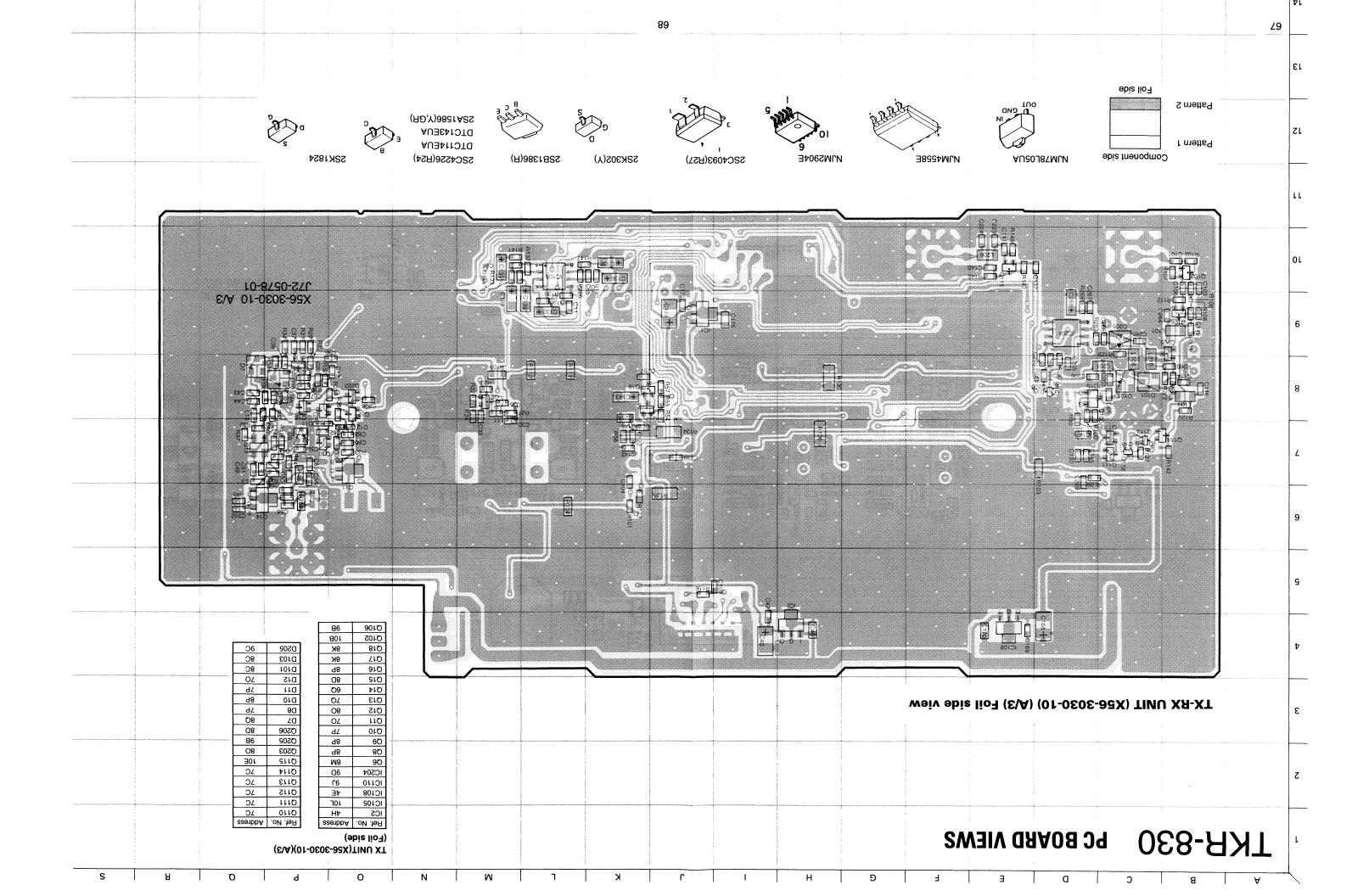
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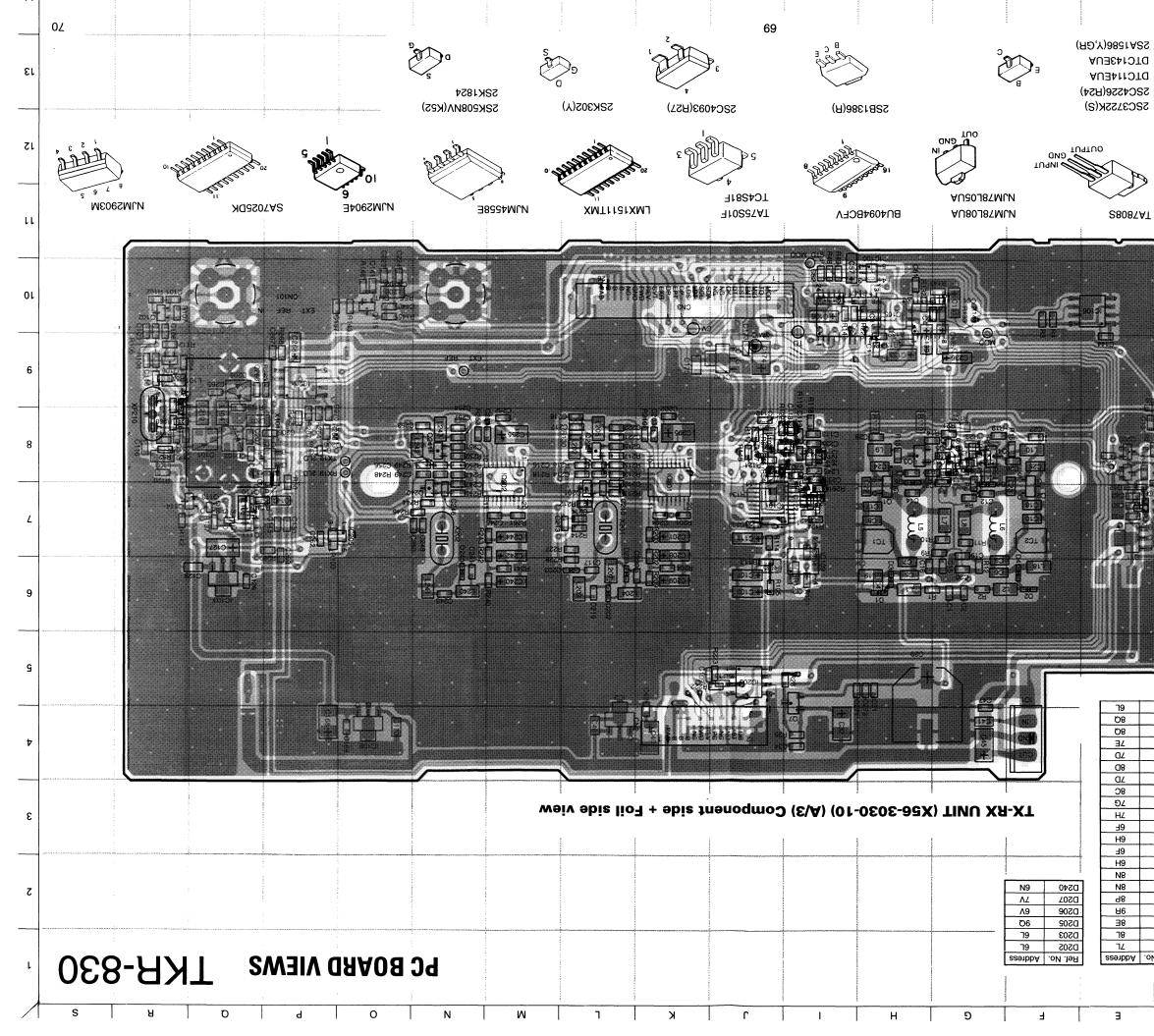
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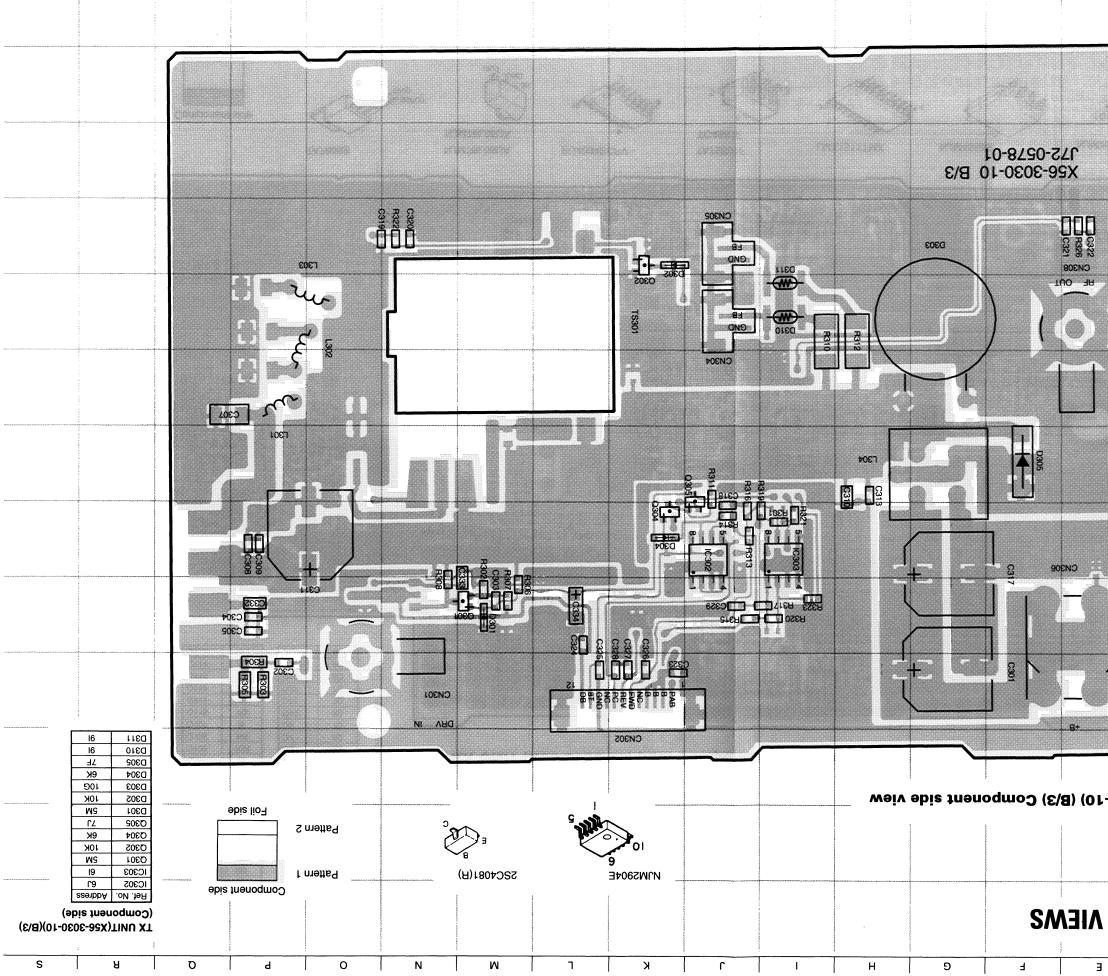




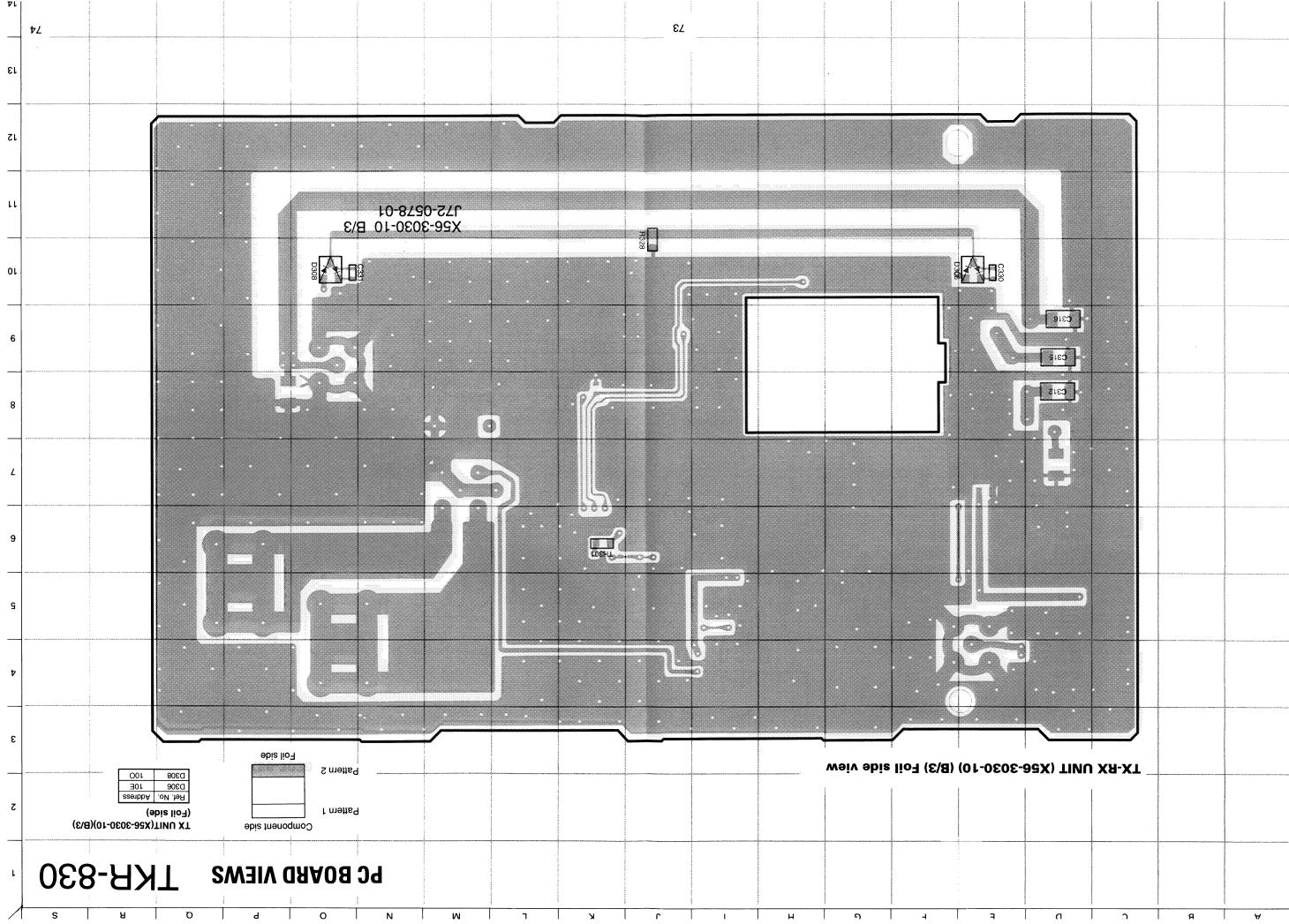


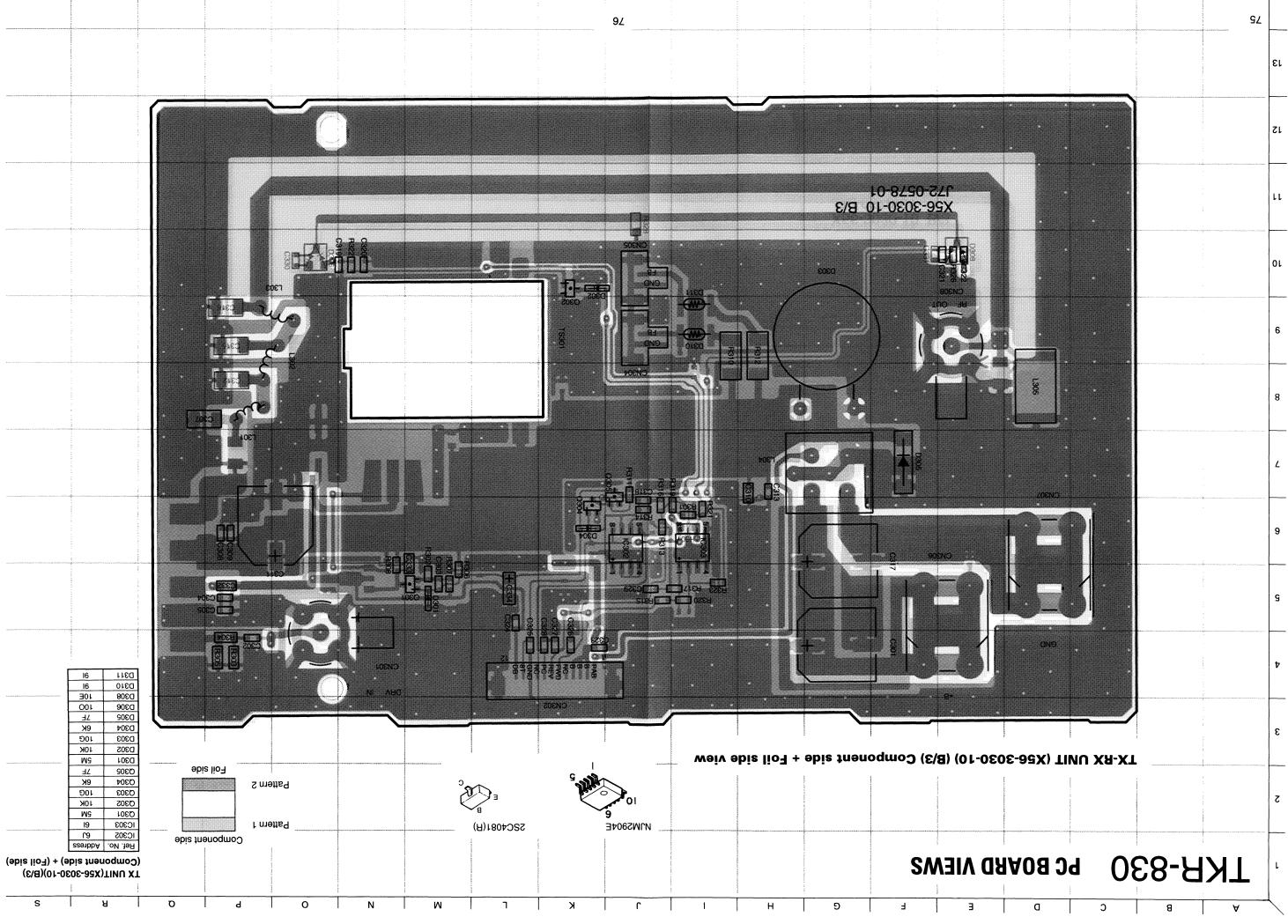


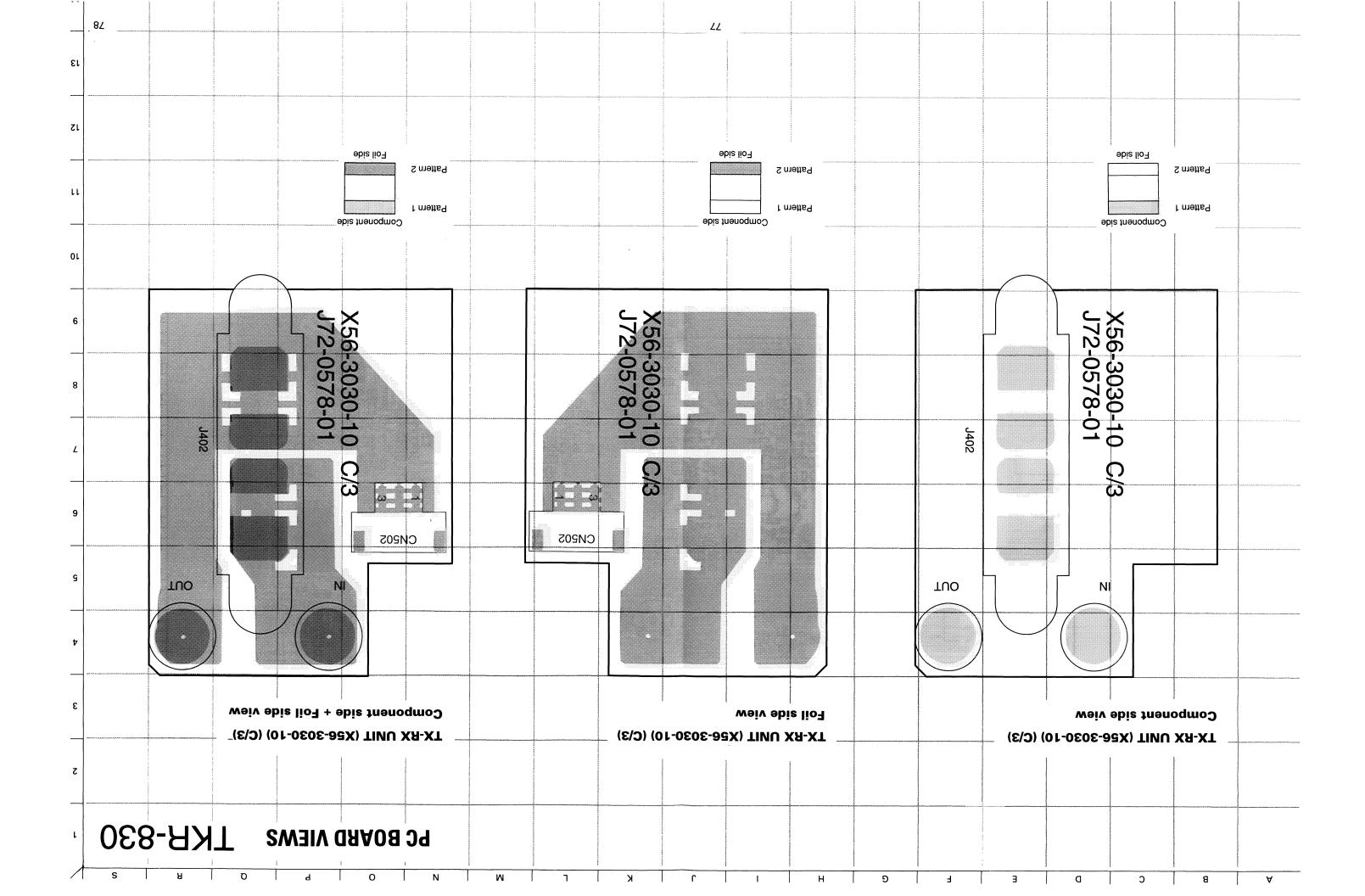
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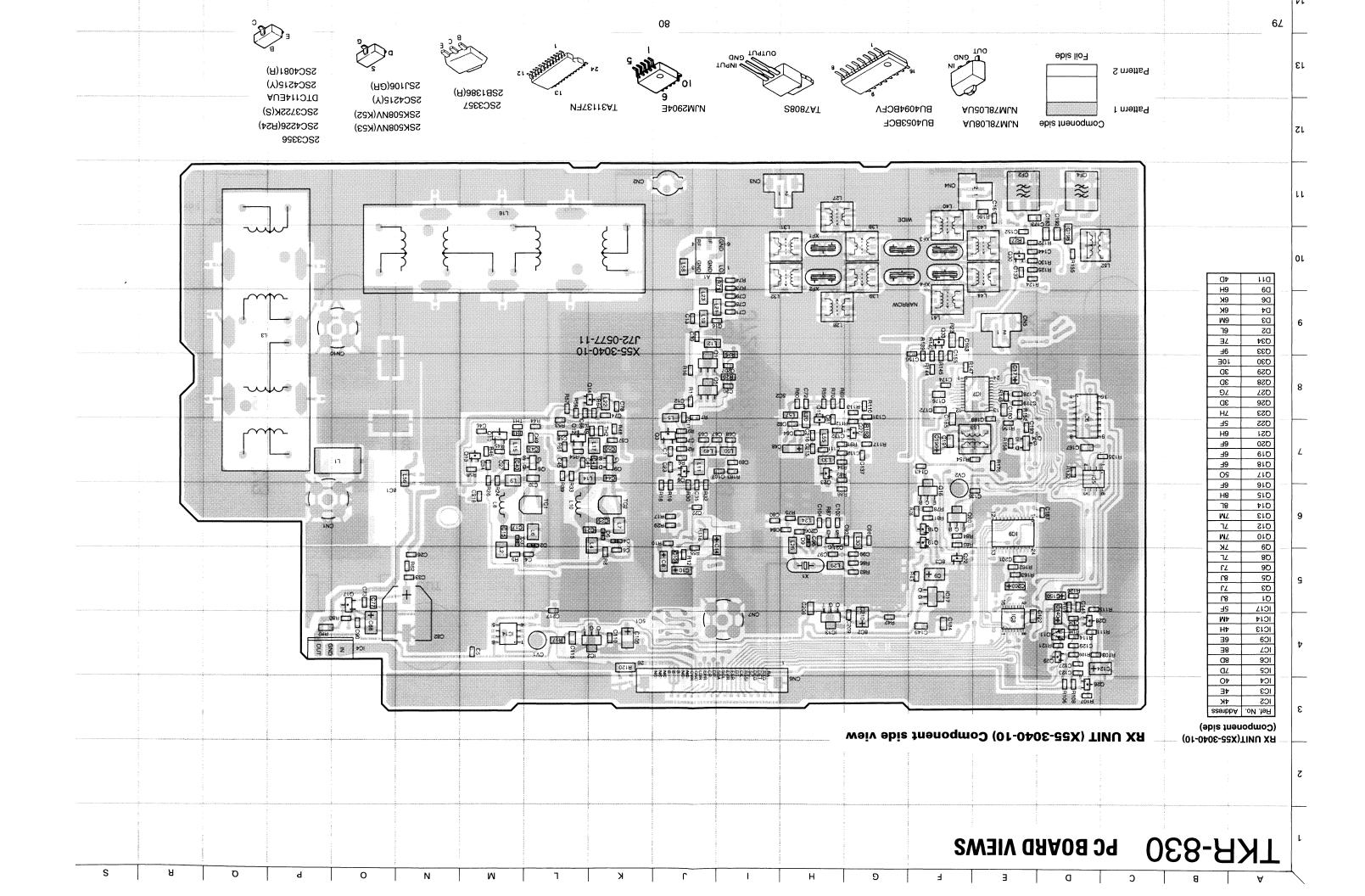


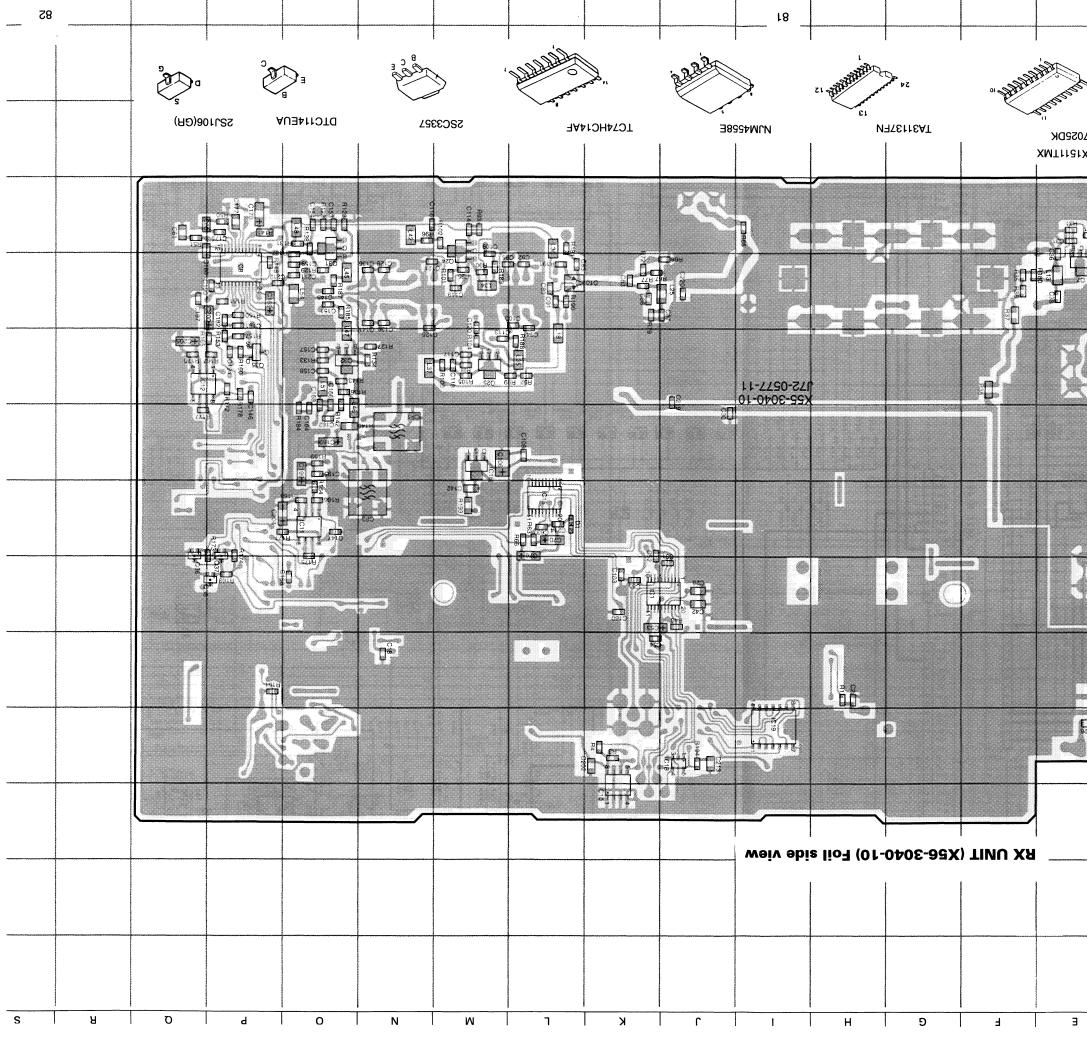
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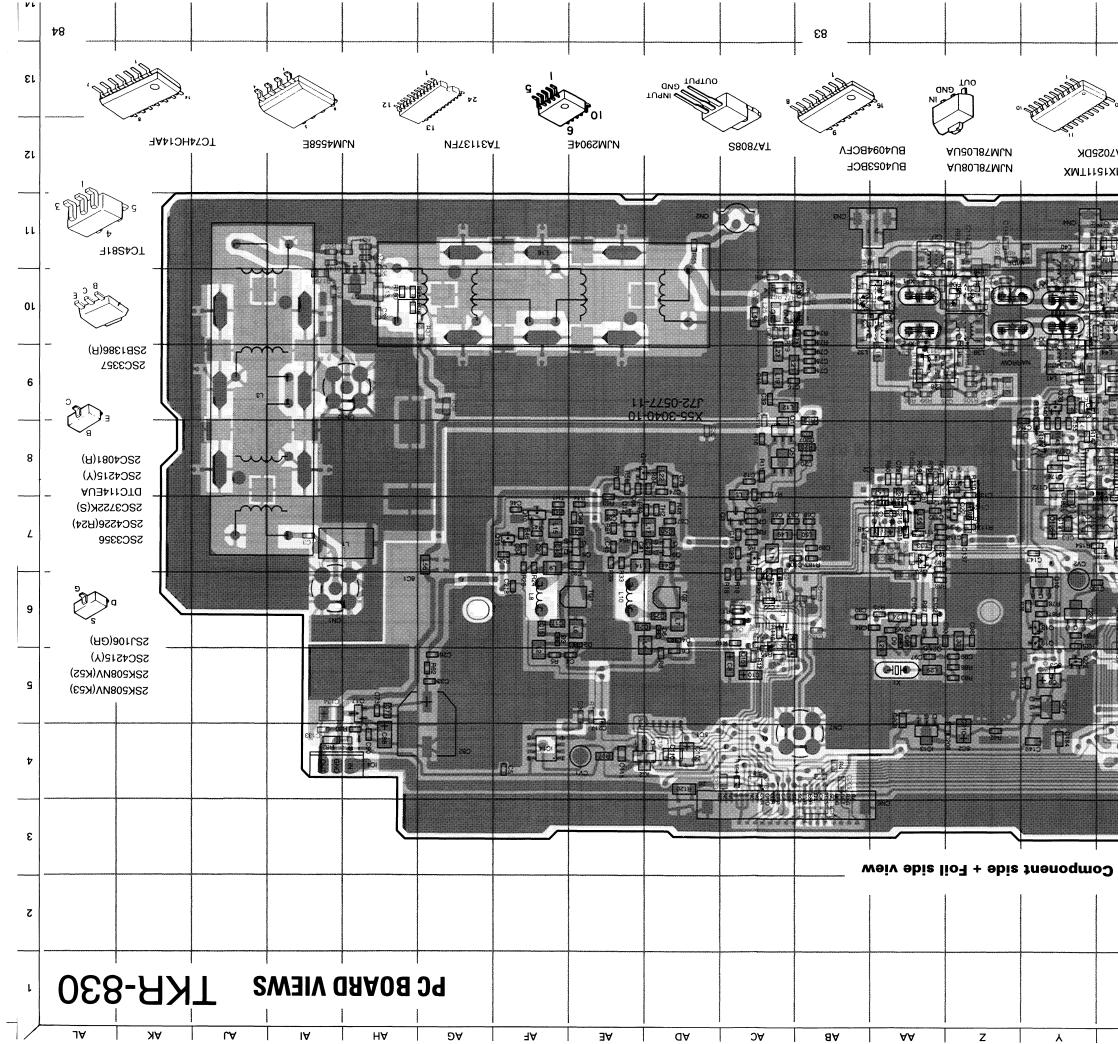




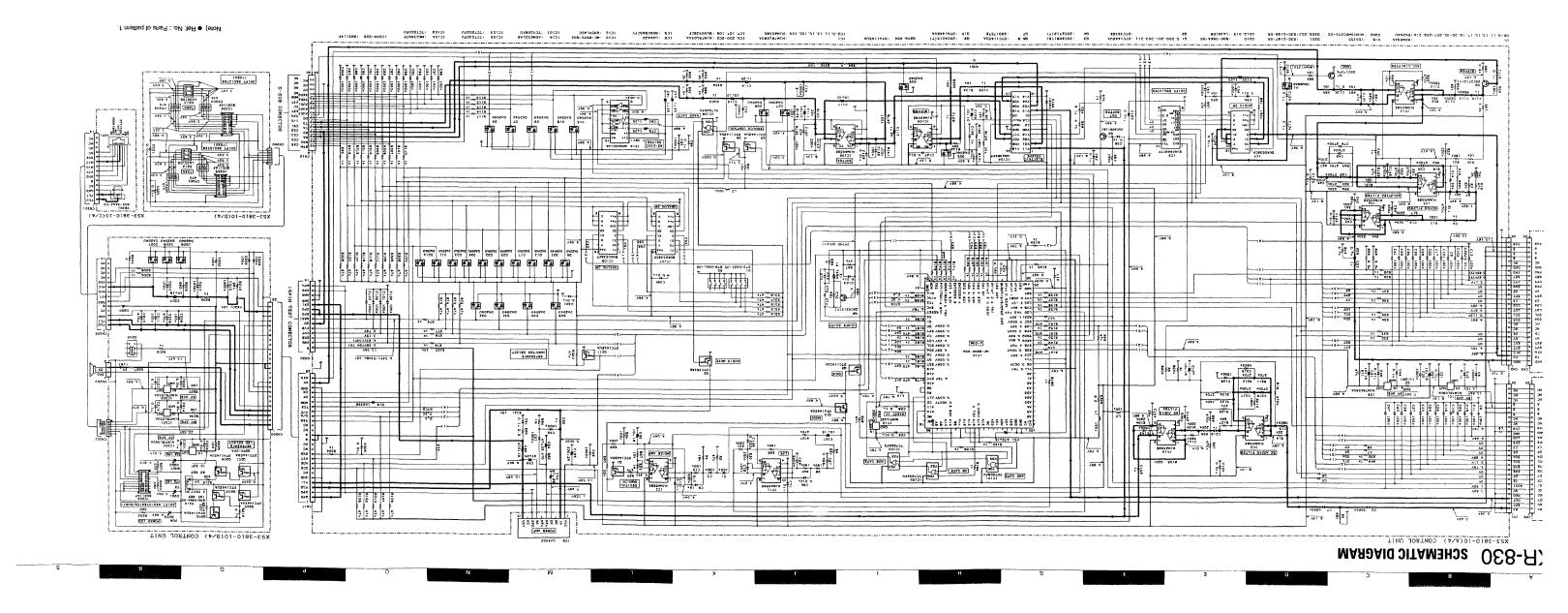


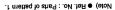


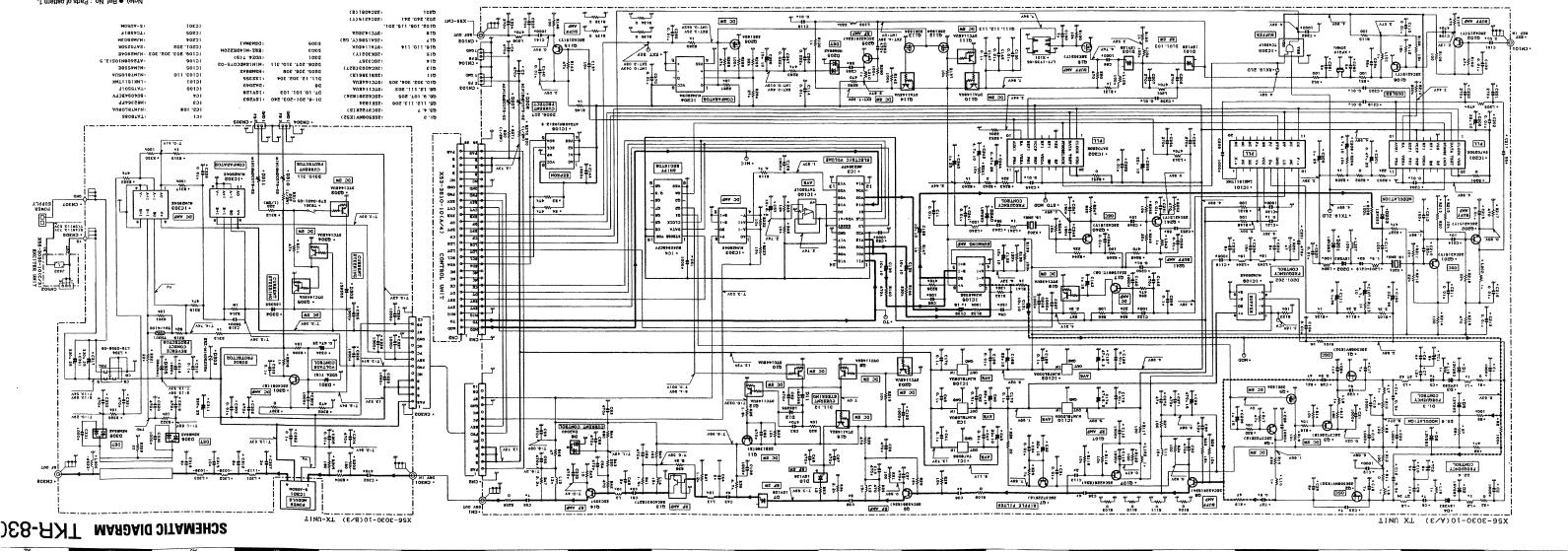
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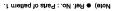


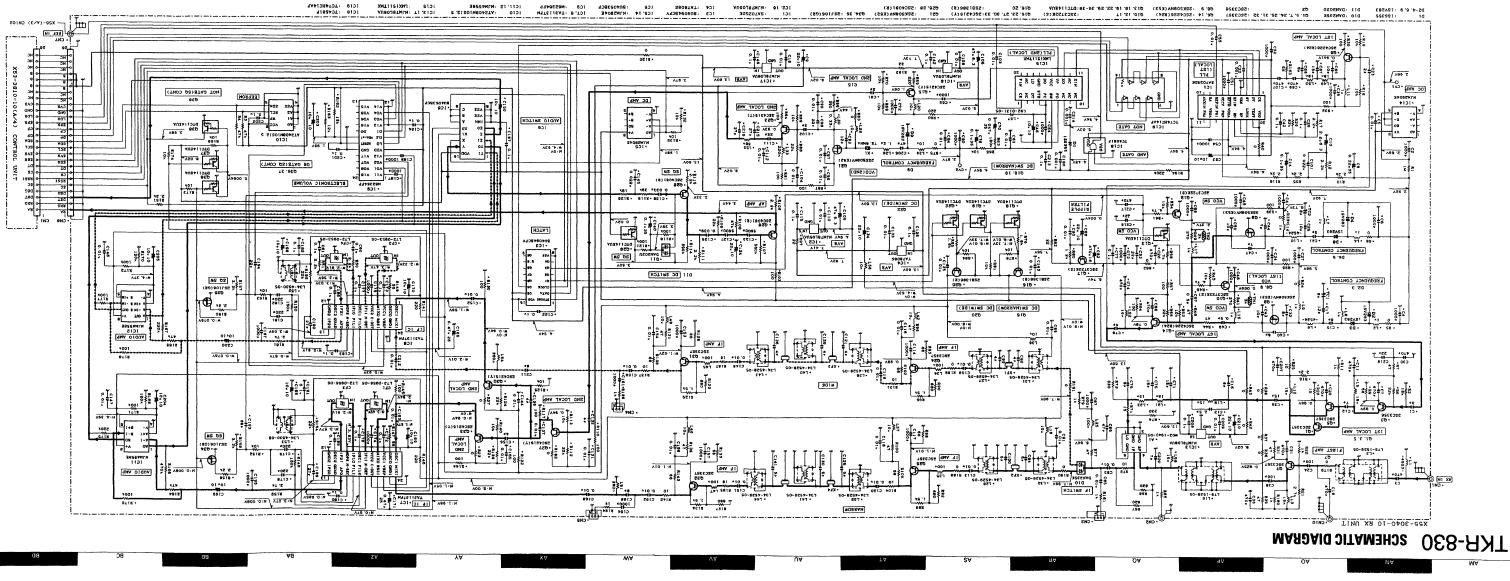
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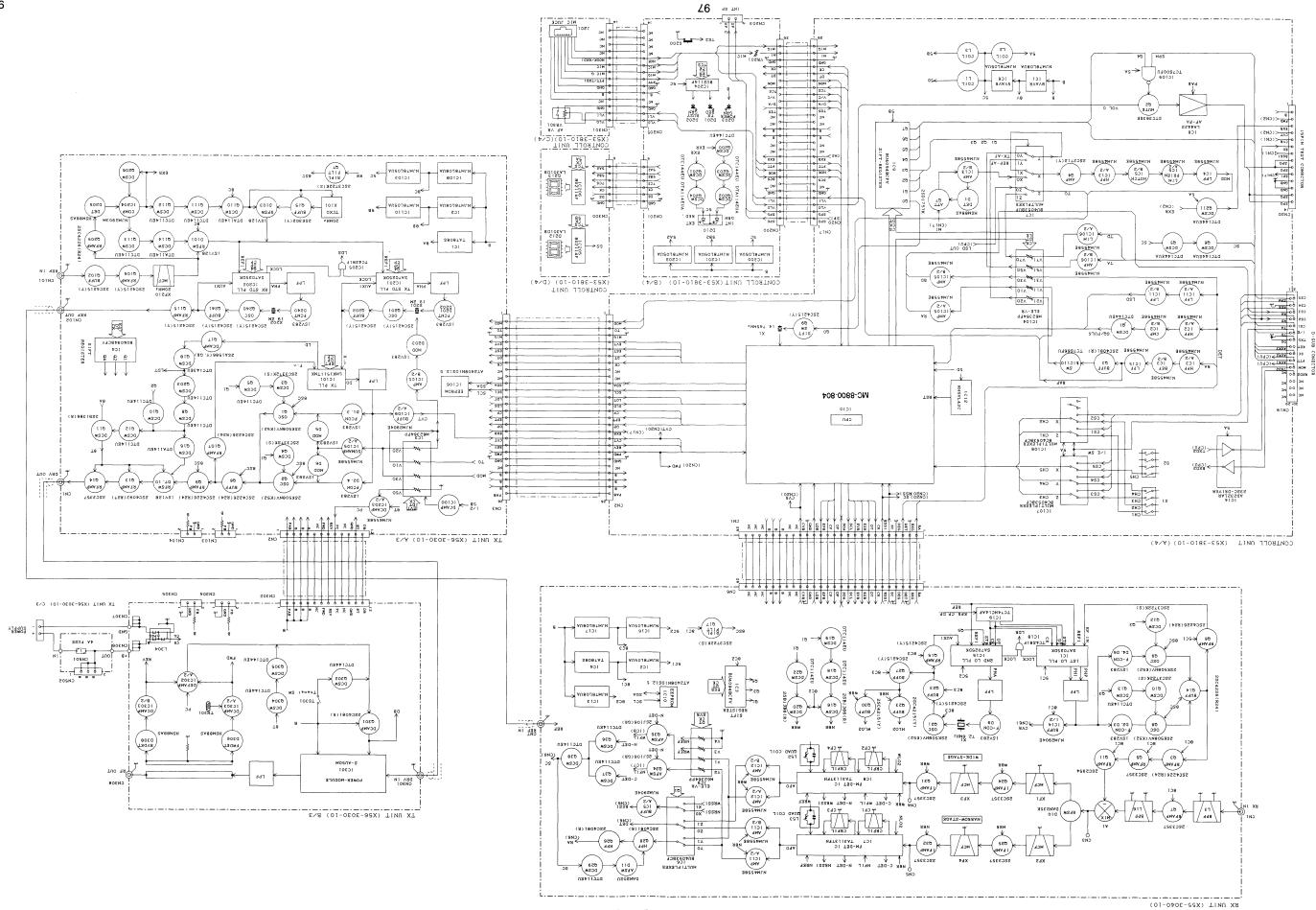




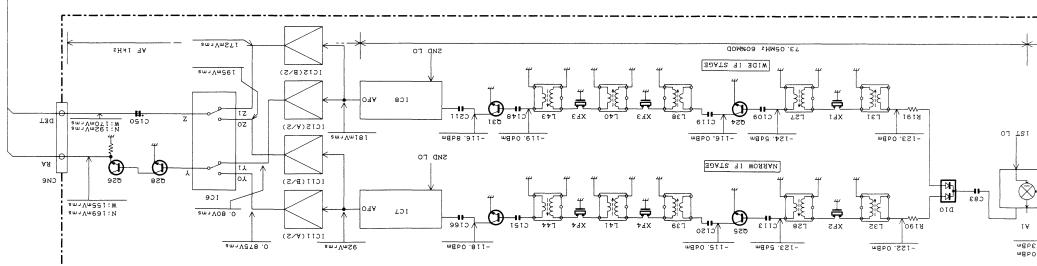


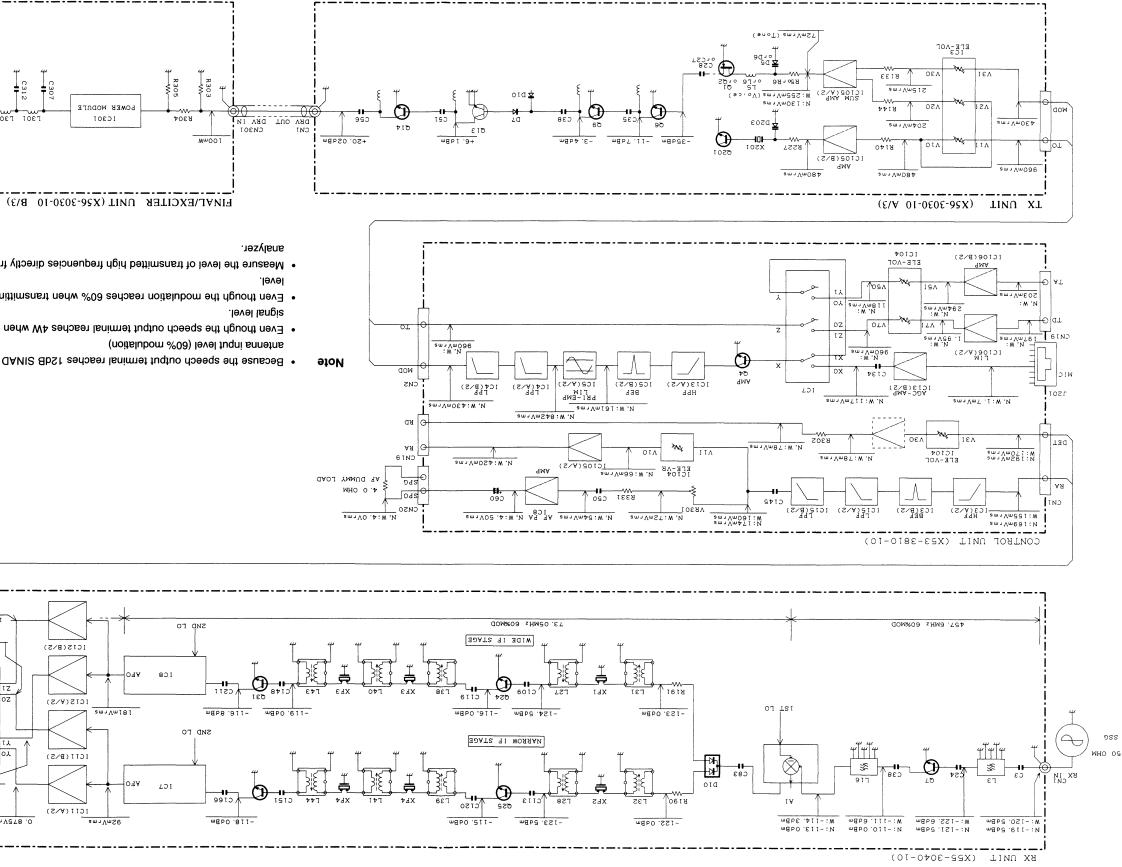


ВLOCK DIAGRAM MARDAG TKR-830



LEVEL DIAGRAM MARDAGO TKR-830





Measure the level of transmitted high trequencies directly from a special quality 500 impedance spec trum

r301 r305 r303

WHO OS RF DUMMY LOAD

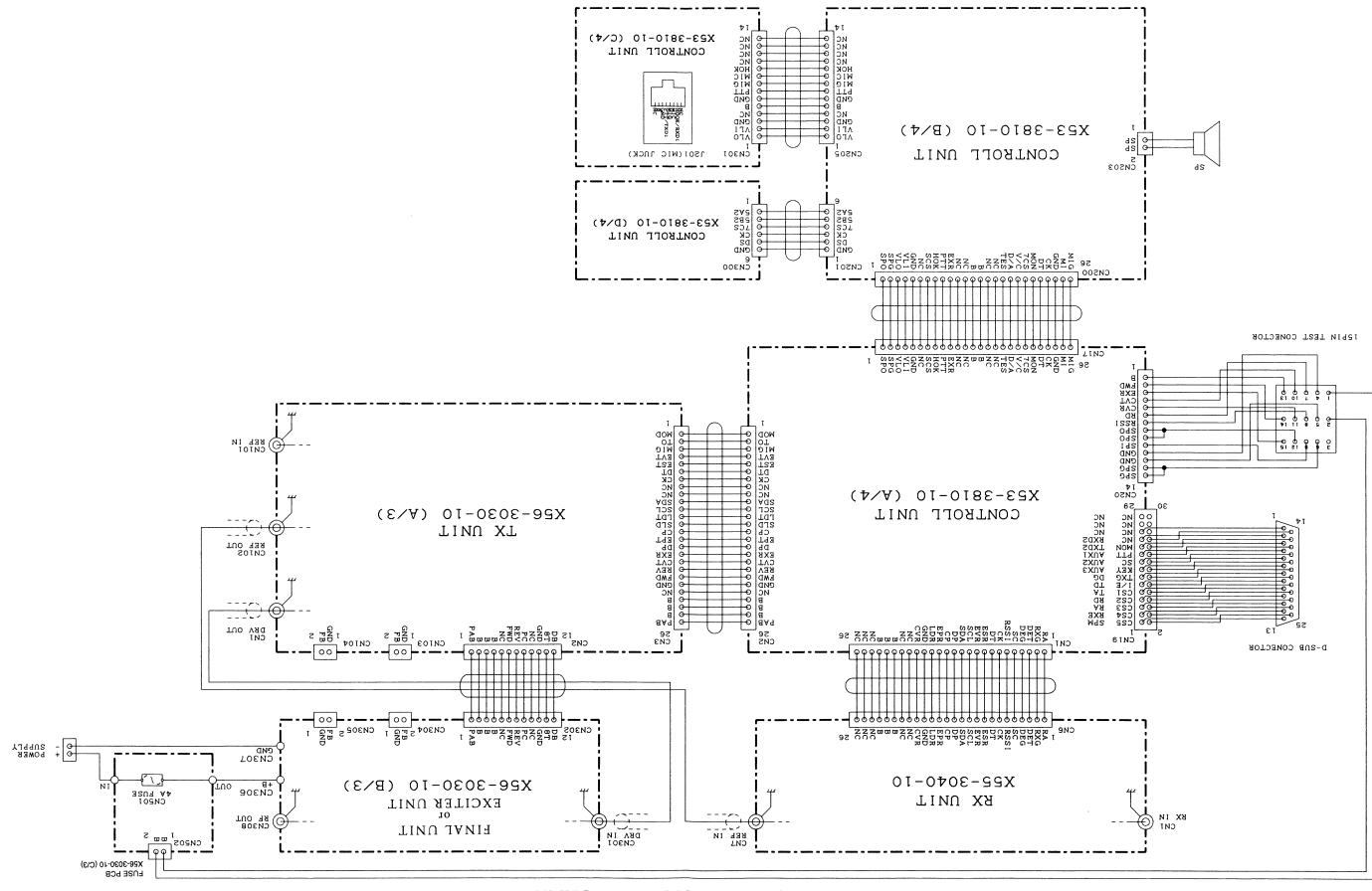
RF OUT

BOENS

4. 92W

- Even though the modulation reaches 60% when transmitting low frequencies, you need a 1kHz MIC input
- Even though the speech output terminal reaches 4W when receiving low frequencies, you need a 1kHz AF
- Because the speech output terminal reaches 12dB SINAD when receiving high trequencies, you need an

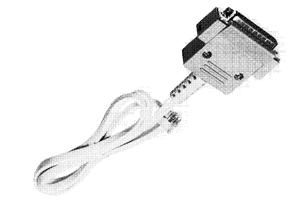


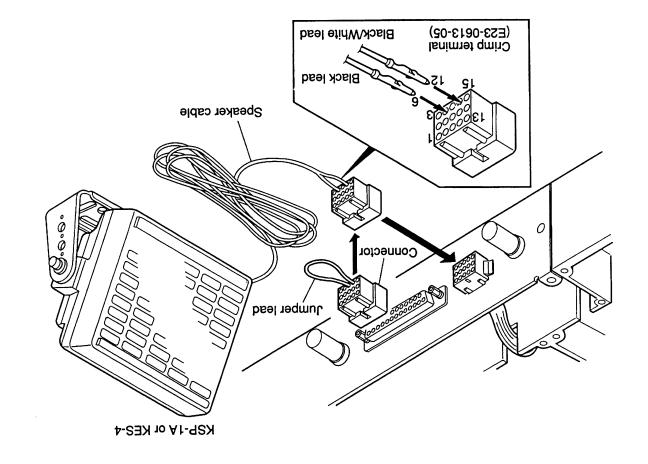


KPG-46 (PROGRAMMING INTERFACE CABLE) TKR-830

KSP-1A/KES-4 (EXTERNAL SPEAKER) TKR-830

External view KbG-49





(St bns 9 and 12) lead and insert the connector into the speaker jack. 3. When not using the external speaker, replace the jumper

		SPECIFICATIONS
KSP-1A	KES-4	Specifications
mm 021	mm 02t	Speaker size
MOL	20M	Maximum input power
smdo 4	smdo 4	Impedance
165 to 80001zH0008	zH 0005 여 00 F	Frequency response
(5" × 5" × 127 × 65mm) (5" × 5" × 127 × 65mm)	$mm33 \times 721 \times 721$	$(D \times H \times W)$ snoisnemid
	$(2_{\rm I} \times 2_{\rm I} \times 5^{-3})$	projection not inclrded
ь(sdlčð.f)g0č7	(sdlS7.f)g087	Meight

Mhen using an external speaker :

- 1. Make sure the unit's power is turned OFF.
- 2. When using the external speaker, remove the jumper lead
- from the connector, and attach the speaker cable.

SPECIFICATIONS

GENERAL

Frequency range	RX : 450,000 to 480,000 MHz, Band spread 5MHz
	TX : 450,000 to 480,000 MHz
Input volta	13.8V DC negative ground
Temperature range	-30°C to +60°C (-22°F to +140°F)
Frequency stability	±0.00015%
Antenna impedance	50Ω
Channel spacing	Wide : 25 kHz, Narrow : 12.5 kHz
	(PLL channel step 5 kHz, 6.25 kHz)
Channels quantity	1 (32 Preset)
Duty cycle	100%
Dimensions (not including protrusions)	19.00" (482.6mm) W $ imes$ 1.73" (44mm) H $ imes$ 10.41" (265mm) D

RECEIVER

Sensitivity (EIA 12dB SINAD)	0.32 μV
Selectivity	Wide : -90dB, Narrow : -82dB
Channel Frequency Spread	5 MHz
Spurious and image rejection	-100 dB
Intermodulation	Wide : -85dB, Narrow : -80dB

TRANSMITTER

RF power output	5W
Channel Frequency Spread	30MHz
Type of Emiss	11K0F3E, 16K0F3E
Audio distortion	Less than 2%
Spurious and emission	Harmonics : -50dB
	Short distance : -75dB
FM Noise	Wide : -55dB, Narrow : -50dB

KENWOOD CORPORATION

14-6, Dogenzaka 1-chome, Shibuya-ku, Tokyo 150-8501, Japan KENWOOD SERVICE CORPORATION

P.O. BOX 22745, 2201 East Dominguez Street, Long Beach, CA 90801-5745, U.S.A.

KENWOOD ELECTRONICS LATIN AMERICA S.A. P.O. BOX 55-2791 Piso 6 Plaza Chase Cl, 47 y Aquilino de la Guardio Panama,

Republic of Panama KENWOOD ELECTRONICS CANADA INC. 6070 Kestrel Road, Mississauga, Ontario, Canada L5T 1S8 KENWOOD ELECTRONICS DEUTSCHLAND GMBH Rembrücker Str. 15, 63150 Heusenstamm, Germany KENWOOD ELECTRONICS BELGIUM N.V. Mechelsesteenweg 418 B-1930 Zaventem, Belgium KENWOOD ELECTRONICS FRANCE S.A. 13, Boulevard Ney, 75018 Paris, France KENWOOD ELECTRONICS U.K. LIMITED

KENWOOD House, Dwight Road, Watford, Herst., WD1 8EB United Kingdom

KENWOOD ELECTRONICS EUROPE B.V. Amsterdamseweg 37, 1422 AC Uithoorn, The Netherlands KENWOOD ELECTRONICS ITALIA S.p.A. Via G. Sirtori, 7/9 20129 Milano, Italy KENWOOD IBERICA S.A. Bolivia, 239-08020 Barcelona, Spain

KENWOOD ELECTRONICS AUSTRALIA PTY. LTD. (A.C.N. 001 499 074) P.O. Box 504, 8 Figtree Drive, Australia Centre, Homebush, N.S.W. 2140, Australia

KENWOOD ELECTRONICS (HONG KONG) LTD. Unit 3712-3724, Level 37, Tower one Metroplaza, 223 Hing Fong Road, Kwai Fong, N.T., Hong Kong

KENWOOD ELECTRONICS TECHNOLOGIES(S) PTE LTD. Sales Marketing Division 1 Ang Mo Kio Street 63, Singapore 569110